

# STEP-UP, SUPER-SMALL PACKAGE, 600 kHz, PWM CONTROL or PWM/PFM SWITCHABLE SWITCHING REGULATOR CONTROLLER

## S-8355/56/57/58 Series

The S-8355/56/57/58 Series is a CMOS step-up switching regulator controller which mainly consists of a reference voltage source, an oscillation circuit, an error amplifier, a phase compensation circuit, a PWM control circuit (S-8355/57 Series) and a PWM/PFM switching control circuit (S-8356/58 Series).

With an external low-ON-resistance Nch Power MOS, this product is ideal for applications requiring high efficiency and a high output current. The S-8355/57 Series realizes low ripple, high efficiency, and excellent transient characteristics due to its PWM control circuit whose duty ratio can be varied linearly from 0 to 83% (from 0 to 78% for 250 kHz, 300 kHz, and 600 kHz models), an excellently designed error amplifier and a phase compensation circuits.

S-8356/58 Series features a PWM/PFM switching controller that can switch the operation to a PFM controller with a duty ratio is 15% under a light load to prevent a decline in the efficiency due to the IC operating current.

### ■ Features

- Low voltage operation : Startup at 0.9 V min. ( $I_{OUT} = 1$  mA) guaranteed
- Low current consumption : During operation 25.9  $\mu$ A (3.3 V, 100 kHz, typ.)  
During shutdown 0.5  $\mu$ A (max.)
- Duty ratio : Built-in PWM/PFM switching control circuit (S-8356/58 Series)  
15 to 83% (100 kHz models)  
15 to 78% (250 kHz, 300 kHz, and 600 kHz models)
- External parts : Coil, diode, capacitor, and transistor
- Output voltage : Selectable in 0.1 V steps between 1.5 and 6.5 V (for  $V_{DD} / V_{OUT}$  separate types)  
Selectable in 0.1 V steps between 2.0 and 6.5 V (for other than  $V_{DD} / V_{OUT}$  separate types)
- Output voltage accuracy :  $\pm 2.4\%$
- Oscillation frequency : 100 kHz, 250 kHz, 300 kHz, 600 kHz selectable
- Soft start function : 6 ms (100 kHz, typ.)
- Shutdown function

### ■ Applications

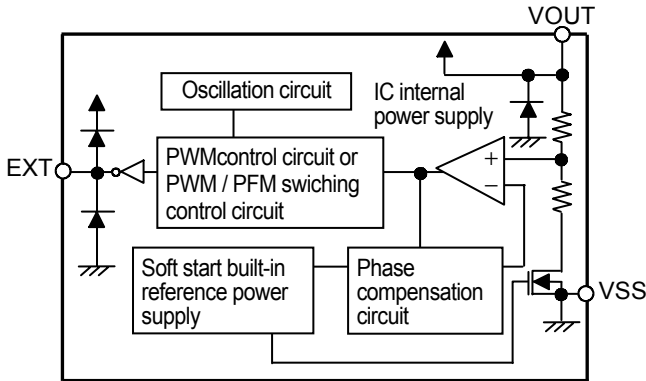
- Power supplies for portable equipment such as digital cameras, electronic notebooks, and PDAs
- Power supplies for audio equipment such as portable CD / MD players
- Constant voltage power supplies for cameras, VCRs, and communications devices
- Power supplies for microcomputers

### ■ Packages

Package Name	Drawing Code		
	Package	Tape	Reel
SOT-23-3	MP003-A	MP003-A	MP003-A
SOT-23-5	MP005-A	MP005-A	MP005-A
SOT-89-3	UP003-A	UP003-A	UP003-A
6-Pin SNB(B)	BD006-A	BD006-A	BD006-A

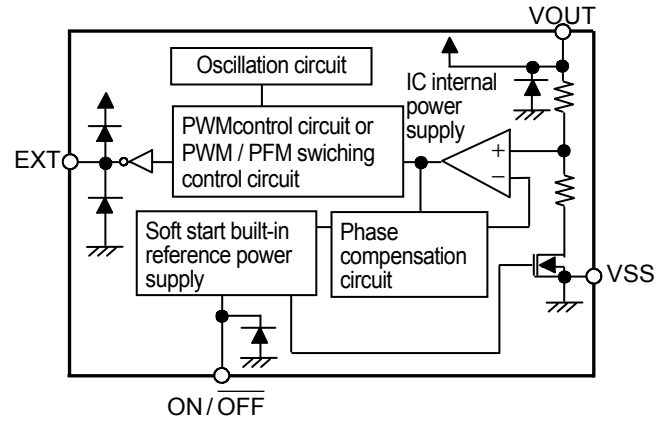
■ **Block Diagrams**

(1) **S-8357/58 Series B, H and F Types**  
 (Without Shutdown Function)



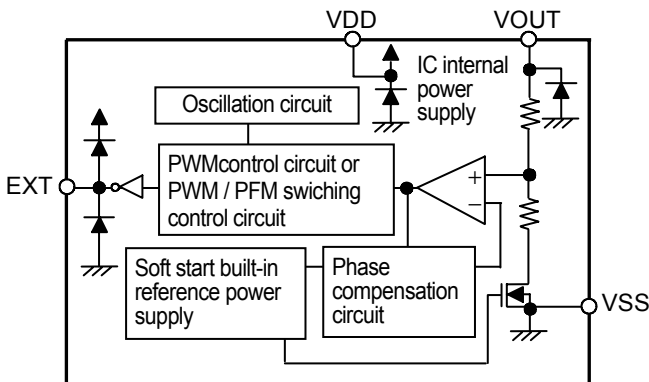
**Figure 1**

(2) **S-8357/58 Series B, H, F and N Types**  
 (With Shutdown Function)



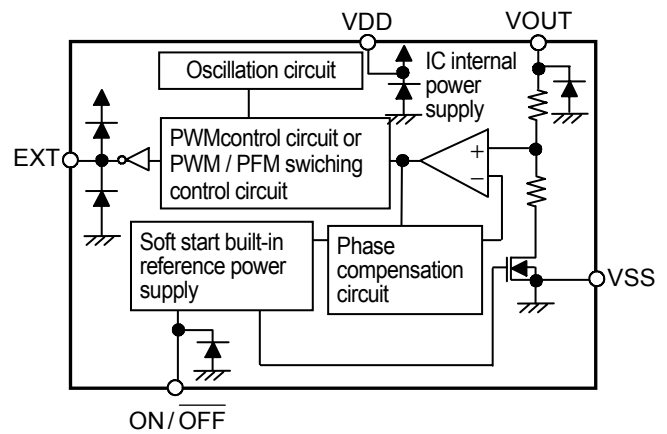
**Figure 2**

(3) **S-8357/58 Series E, J, G and P Types**  
 ( $V_{DD}$  /  $V_{OUT}$  Separate Type)



**Figure 3**

(4) **S-8355/56 Series K, L, M and Q Types**  
 (With Shutdown Function,  $V_{DD}$  /  $V_{OUT}$  Separate Type)



**Figure 4**

## ■ Product Name Structure

The control system, product types, output voltage, and packages for the S-8355/56/57/58 Series can be selected at the user's request. Please refer to the "3. Product Name" for the definition of the product name and "4. Product Name List" for the full product names.

### 1. Function List

#### (1) PWM Control Products

Table 1

Product Name	Switching Frequency kHz	Shutdown Function	V <sub>DD</sub> / V <sub>OUT</sub> Separate Type	Package	Application
S-8355KxxMC	100	Yes	Yes	SOT-23-5	Applications requiring variable output voltage and a shutdown function
S-8355LxxMC, S-8355LxxBD	250	Yes	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage, a shutdown function, and a thin coil
S-8355MxxMC, S-8355MxxBD	300	Yes	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage, a shutdown function, and a thin coil
S-8355QxxMC, S-8355QxxBD	600	Yes	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage, a shutdown function, and a thin coil
S-8357BxxMC	100	Yes	–	SOT-23-5	Applications requiring a shutdown function
S-8357BxxMA	100	–	–	SOT-23-3	Applications not requiring a shutdown function
S-8357BxxUA	100	–	–	SOT-89-3	Applications not requiring a shutdown function
S-8357ExxMC	100	–	Yes	SOT-23-5	Applications in which output voltage is adjusted by external resistor
S-8357FxxMC, S-8357FxxBD	300	Yes	–	SOT-23-5, 6-Pin SNB(B)	Applications requiring a shutdown function and a thin coil
S-8357GxxMC, S-8357GxxBD	300	–	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage and a thin coil
S-8357HxxMC, S-8357HxxBD	250	Yes	–	SOT-23-5, 6-Pin SNB(B)	Applications requiring a shutdown function and a thin coil
S-8357JxxMC, S-8357JxxBD	250	–	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage with an external resistor and a thin coil
S-8357NxxMC, S-8357NxxBD	600	Yes	–	SOT-23-5, 6-Pin SNB(B)	Applications requiring a shutdown function and a thin coil
S-8357PxxMC, S-8357PxxBD	600	–	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage with an external resistor and a thin coil

(2) PWM / PFM Switching Control Products

Table 2

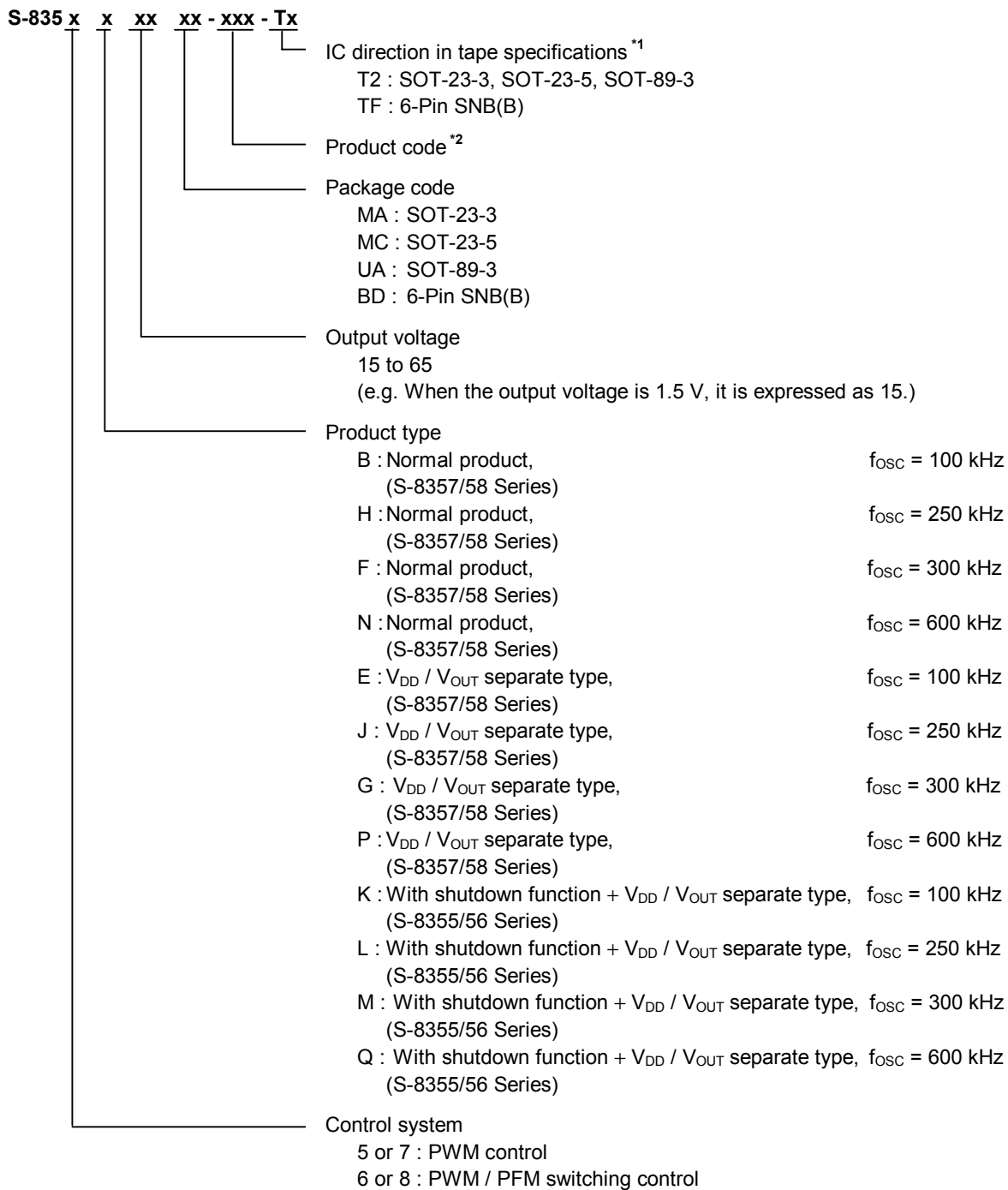
Product Name	Switching Frequency kHz	Shutdown Function	V <sub>DD</sub> / V <sub>OUT</sub> Separate Type	Package	Application
S-8356KxxMC	100	Yes	Yes	SOT-23-5	Applications requiring variable output voltage and a shutdown function
S-8356LxxMC, S-8356KxxBD	250	Yes	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage, a shutdown function, and a thin coil
S-8356MxxMC, S-8356MxxBD	300	Yes	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage, a shutdown function, and a thin coil
S-8356QxxMC, S-8356QxxBD	600	Yes	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage, a shutdown function, and a thin coil
S-8358BxxMC	100	Yes	–	SOT-23-5	Applications requiring a shutdown function
S-8358BxxMA	100	–	–	SOT-23-3	Applications not requiring a shutdown function
S-8358BxxUA	100	–	–	SOT-89-3	Applications not requiring a shutdown function
S-8358ExxMC	100	–	Yes	SOT-23-5	Applications in which output voltage is adjusted by external resistor
S-8358FxxMC, S-8358FxxBD	300	Yes	–	SOT-23-5, 6-Pin SNB(B)	Applications requiring a shutdown function and a thin coil
S-8358GxxMC, S-8358GxxBD	300	–	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage and a thin coil
S-8358HxxMC, S-8358HxxBD	250	Yes	–	SOT-23-5, 6-Pin SNB(B)	Applications requiring a shutdown function and a thin coil
S-8358JxxMC, S-8358JxxBD	250	–	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage with an external resistor and a thin coil
S-8358NxxMC, S-8358NxxBD	600	Yes	–	SOT-23-5, 6-Pin SNB(B)	Applications requiring a shutdown function and a thin coil
S-8358PxxMC, S-8358PxxBD	600	–	Yes	SOT-23-5, 6-Pin SNB(B)	Applications requiring variable output voltage with an external resistor and a thin coil

2. Package and Function List by Product Type

Table 3

Series Name	Type	Package Name (Abbreviation)	Shutdown Function Yes / No	V <sub>DD</sub> / V <sub>OUT</sub> Separate Type Yes / No
S-8355 Series, S-8356 Series	K, L, M, Q (Shutdown function + V <sub>DD</sub> / V <sub>OUT</sub> separate type) K = 100 kHz, L = 250 kHz, M = 300 kHz, Q = 600 kHz	MC / BD	Yes	Yes
S-8357 Series	B, H, F (Normal product) B = 100 kHz, H = 250 kHz, F = 300 kHz	MA / UA	No	No
		MC / BD	Yes	
	N (Normal product) N = 600 kHz	MC / BD	Yes	No
	E, J, G, P (V <sub>DD</sub> / V <sub>OUT</sub> separate type) E = 100 kHz, J = 250 kHz, G = 300 kHz, P = 600 kHz	MC / BD	No	Yes
S-8358 Series	B, H, F (Normal product) B = 100 kHz, H = 250 kHz, F = 300 kHz	MA / UA	No	No
		MC / BD	Yes	
	N (Normal product) N = 600 kHz	MC/BD	Yes	No
	E, J, G, P (V <sub>DD</sub> / V <sub>OUT</sub> separate type) E = 100 kHz, J = 250 kHz, G = 300 kHz, P = 600 kHz	MC / BD	No	Yes

3. Product Name



\*1. Refer to the taping specifications.

\*2. Refer to the **Table 4** to **Table 13** in the “**4. Product Name List**”.

**4. Product Name List**

**(1) S-8355 Series**

**Table 4**

Output voltage	S-8355KxxMC Series	S-8355LxxMC Series	S-8355MxxMC Series	S-8355MxxBD Series
1.5 V	–	S-8355L15MC-NCA-T2	–	–
1.8 V	S-8355K18MC-NAD-T2	–	S-8355M18MC-MCD-T2	S-8355M18BD-MCD-TF
2.0 V	S-8355K20MC-NAF-T2	S-8355L20MC-NCF-T2	S-8355M20MC-MCF-T2	–
3.1 V	S-8355K31MC-NAQ-T2	–	S-8355M31MC-MCQ-T2	–
3.2 V	–	–	S-8355M32MC-MCR-T2	–
3.3 V	S-8355K33MC-NAS-T2	–	–	–
3.4 V	–	–	S-8355M34MC-MCT-T2	S-8355M34BD-MCT-TF
5.0 V	S-8355K50MC-NBJ-T2	–	S-8355M50MC-MDJ-T2	–
5.5 V	–	–	S-8355M55MC-MDO-T2	–

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**Table 5**

Output voltage	S-8355QxxMC Series	S-8355QxxBD Series
1.5 V	S-8355Q15MC-OWA-T2	S-8355Q15BD-OWA-TF
2.8 V	–	S-8355Q28BD-OWN-TF
3.1 V	–	S-8355Q31BD-OWQ-TF
3.4 V	–	S-8355Q34BD-OWT-TF
5.0 V	S-8355Q50MC-OXJ-T2	S-8355Q50BD-OXJ-TF

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**(2) S-8356 Series**

Output voltage	S-8356KxxMC Series	S-8356MxxMC Series	S-8356MxxBD Series
1.5 V	–	S-8356M15MC-MEA-T2	–
1.8 V	S-8356K18MC-NED-T2	S-8356M18MC-MED-T2	S-8356M18BD-MED-TF
3.0 V	–	S-8356M30MC-MEP-T2	–
3.3 V	S-8356K33MC-NES-T2	–	–
5.0 V	S-8356K50MC-NFJ-T2	S-8356M50MC-MFJ-T2	S-8356M50BD-MFJ-TF

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**Table 7**

Output voltage	S-8356QxxMC Series	S-8356QxxBD Series
1.8 V	S-8356Q18MC-OYD-T2	–
3.3 V	S-8356Q33MC-OYS-T2	–
3.7 V	–	S-8356Q37BD-OYW-TF
5.0 V	S-8356Q50MC-OVJ-T2	S-8356Q50BD-OVJ-TF

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**(3) S-8357 Series**

**Table 8**

Output voltage	S-8357BxxMC Series	S-8357BxxMA Series	S-8357BxxUA Series	S-8357ExxMC Series
1.5 V	–	–	–	S-8357E15MC-NKA-T2
2.0 V	–	–	–	S-8357E20MC-NKF-T2
2.5 V	S-8357B25MC-NIK-T2	–	–	–
2.6 V	S-8357B26MC-NIL-T2	–	–	–
2.7 V	S-8357B27MC-NIM-T2	–	–	–
2.8 V	S-8357B28MC-NIN-T2	–	–	–
3.0 V	S-8357B30MC-NIP-T2	S-8357B30MA-NIP-T2	–	–
3.3 V	S-8357B33MC-NIS-T2	S-8357B33MA-NIS-T2	S-8357B33UA-NIS-T2	–
3.6 V	S-8357B36MC-NIV-T2	–	–	–
4.8 V	S-8357B48MC-NJH-T2	–	S-8357B48UA-NJH-T2	–
5.0 V	S-8357B50MC-NJJ-T2	S-8357B50MA-NJJ-T2	S-8357B50UA-NJJ-T2	S-8357E50MC-NLJ-T2
5.2 V	S-8357B52MC-NJL-T2	–	–	–
5.4 V	S-8357B54MC-NJN-T2	–	–	–
6.0 V	S-8357B60MC-NJT-T2	–	–	–

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**Table 9**

Output voltage	S-8357FxxMC Series	S-8357GxxMC Series	S-8357HxxMC Series	S-8357JxxMC Series
2.5 V	–	–	–	S-8357J25MC-NOK-T2
3.0 V	–	–	S-8357H30MC-NMP-T2	–
3.1 V	–	–	S-8357H31MC-NMQ-T2	–
3.2 V	S-8357F32MC-MGR-T2	–	–	–
3.3 V	S-8357F33MC-MGS-T2	–	–	–
3.5 V	–	–	S-8357H35MC-NMU-T2	–
3.6 V	–	–	S-8357H36MC-NMV-T2	–
5.0 V	S-8357F50MC-MHJ-T2	S-8357G50MC-MJJ-T2	S-8357H50MC-NNJ-T2	S-8357J50MC-NPJ-T2
5.2 V	S-8357F52MC-MHL-T2	–	–	–

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**Table 10**

Output voltage	S-8357JxxBD Series	S-8357NxxMC Series
3.3 V	–	S-8357N33MC-O2S-T2
5.0 V	S-8357J50BD-NPJ-TF	S-8357N50MC-O3J-T2

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**(4) S-8358 Series**

**Table 11**

Output voltage	S-8358BxxMC Series	S-8358BxxMA Series	S-8358BxxUA Series	S-8358ExxMC Series
2.0 V	–	–	–	S-8358E20MC-NSF-T2
2.3 V	S-8358B23MC-NQI-T2	–	–	–
2.5 V	S-8358B25MC-NQK-T2	–	–	–
2.6 V	S-8358B26MC-NQL-T2	–	–	–
2.7 V	S-8358B27MC-NQM-T2	–	–	–
3.0 V	S-8358B30MC-NQP-T2	–	–	–
3.1 V	S-8358B31MC-NQQ-T2	–	–	–
3.2 V	S-8358B32MC-NQR-T2	–	–	–
3.3 V	S-8358B33MC-NQS-T2	–	S-8358B33UA-NQS-T2	–
3.5 V	S-8358B35MC-NQU-T2	–	–	–
3.6 V	S-8358B36MC-NQV-T2	–	–	–
3.8 V	S-8358B38MC-NQX-T2	–	–	–
4.0 V	S-8358B40MC-NQZ-T2	–	–	–
5.0 V	S-8358B50MC-NRJ-T2	S-8358B50MA-NRJ-T2	S-8358B50UA-NRJ-T2	S-8358E50MC-NTJ-T2
6.0 V	S-8358B60MC-NRT-T2	–	–	–

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**Table 12**

Output voltage	S-8358FxxMC Series	S-8358GxxMC Series	S-8358HxxMC Series	S-8358JxxMC Series
2.3 V	–	–	S-8358H23MC-NUI-T2	–
2.6 V	S-8358F26MC-MKL-T2	–	–	–
2.7 V	S-8358F27MC-MKM-T2	–	–	–
3.0 V	–	–	S-8358H30MC-NUP-T2	–
3.3 V	S-8358F33MC-MKS-T2	–	S-8358H33MC-NUS-T2	S-8358J33MC-NWS-T2
5.0 V	S-8358F50MC-MLJ-T2	S-8358G50MC-MNJ-T2	S-8358H50MC-NVJ-T2	S-8358J50MC-NXJ-T2
5.3 V	S-8358F53MC-MLM-T2	–	–	–

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.

**Table 13**

Output voltage	S-8358NxxMC Series
5.3 V	S-8358N53MC-O7M-T2

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above.



■ Pin Configurations

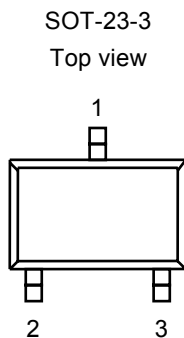


Figure 5

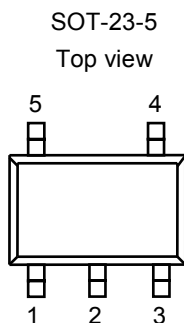


Figure 6

Table 14 S-8357/58 Series B, H and F Types  
(Without shutdown function,  $V_{DD}$  /  $V_{OUT}$  non-separate type)

Pin No.	Symbol	Pin Description
1	VOUT	Output voltage pin and IC power supply pin
2	VSS	GND pin
3	EXT	External transistor connection pin

Table 15 S-8355/56 Series K, L, M and Q Types  
(With shutdown function,  $V_{DD}$  /  $V_{OUT}$  separate type)

Pin No.	Symbol	Pin Description
1	VOUT	Output voltage
2	VDD	IC power supply pin
3	ON/ $\overline{\text{OFF}}$	Shutdown pin "H": Normal operation (Step-up operating) "L": Step-up stopped (Entire circuit stopped)
4	VSS	GND pin
5	EXT	External transistor connection pin

Table 16 S-8357/58 Series B, H, F and N Types  
(With shutdown function,  $V_{DD}$  /  $V_{OUT}$  non-separate type)

Pin No.	Symbol	Pin Description
1	ON/ $\overline{\text{OFF}}$	Shutdown pin "H": Normal operation (Step-up operating) "L": Step-up stopped (Entire circuit stopped)
2	VOUT	Output voltage pin and IC power supply pin
3	NC*1	No connection
4	VSS	GND pin
5	EXT	External transistor connection pin

\*1. The NC pin indicates electrically open.

Table 17 S-8357/58 Series E, J, G and P Types  
(Without shutdown function,  $V_{DD}$  /  $V_{OUT}$  separate type)

Pin No.	Symbol	Pin Description
1	VOUT	Output voltage pin
2	VDD	IC power supply pin
3	NC*1	No connection
4	VSS	GND pin
5	EXT	External transistor connection pin

\*1. The NC pin indicates electrically open.

SOT-89-3  
 Top view

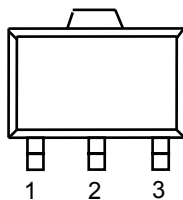
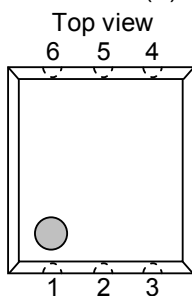
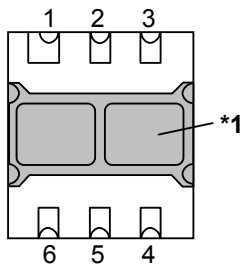


Figure 7

6-Pin SNB(B)



Bottom view



\*1. Connect the heatsink of back side at shadowed area to the board, and set electric potential open or VDD.  
 However, do not use it as the function of electrode.

Figure 8

**Table 18 S-8357/58 Series B, H and F Types**  
 (Without shutdown function,  $V_{DD}$  /  $V_{OUT}$  non-separate type)

Pin No.	Symbol	Pin Description
1	VSS	GND pin
2	VOUT	Output voltage pin and IC power supply pin
3	EXT	External transistor connection pin

**Table 19 S-8355/56 Series K, L, M and Q Types**  
 (With shutdown function,  $V_{DD}$  /  $V_{OUT}$  separate type)

Pin No.	Symbol	Pin Description
1	ON/ $\overline{\text{OFF}}$	Shutdown pin "H": Normal operation (Step-up operating) "L": Step-up stopped (Entire circuit stopped)
2	VOUT	Output voltage pin
3	VDD	IC power supply pin
4	EXT	External transistor connection pin
5	NC*1	No connection
6	VSS	GND pin

\*1. The NC pin indicates electrically open.

**Table 20 S-8357/58 Series B, H, F and N Types**  
 (With shutdown function,  $V_{DD}$  /  $V_{OUT}$  non-separate type)

Pin No.	Symbol	Pin Description
1	NC*1	No connection
2	ON/ $\overline{\text{OFF}}$	Shutdown pin "H": Normal operation (Step-up operating) "L": Step-up stopped (Entire circuit stopped)
3	VOUT	Output voltage pin and IC power supply pin
4	EXT	External transistor connection pin
5	NC*1	No connection
6	VSS	GND pin

\*1. The NC pin indicates electrically open.

**Table 21 S-8357/58 Series E, J, G and P Types**  
 (Without shutdown function,  $V_{DD}$  /  $V_{OUT}$  separate type)

Pin No.	Symbol	Pin Description
1	NC*1	No connection
2	VOUT	Output voltage pin
3	VDD	IC power supply pin
4	EXT	External transistor connection pin
5	NC*1	No connection
6	VSS	GND pin

\*1. The NC pin indicates electrically open.

■ Absolute Maximum Ratings

Table 22

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute maximum rating	Unit
VOUT pin voltage	V <sub>OUT</sub>	V <sub>SS</sub> - 0.3 to V <sub>SS</sub> + 12	V
ON/OFF pin voltage *1	V <sub>ON/OFF</sub>	V <sub>SS</sub> - 0.3 to V <sub>SS</sub> + 12	V
VDD pin voltage *2	V <sub>DD</sub>	V <sub>SS</sub> - 0.3 to V <sub>SS</sub> + 12	V
EXT pin voltage	B, H, F, N type	V <sub>SS</sub> - 0.3 to V <sub>DD</sub> + 0.3	V
	Others	V <sub>SS</sub> - 0.3 to V <sub>OUT</sub> + 0.3	V
EXT pin current	I <sub>EXT</sub>	±80	mA
Power dissipation	SOT-23-3	P <sub>D</sub>	150
	SOT-23-5		250
	SOT-89-3		500
	6-Pin SNB(B)		90
Operating ambient temperature	Topr	- 40 to + 85	°C
Storage temperature	Tstg	- 40 to + 125	°C

\*1. With shutdown function

\*2. For V<sub>DD</sub> / V<sub>OUT</sub> separate type

**Caution** The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

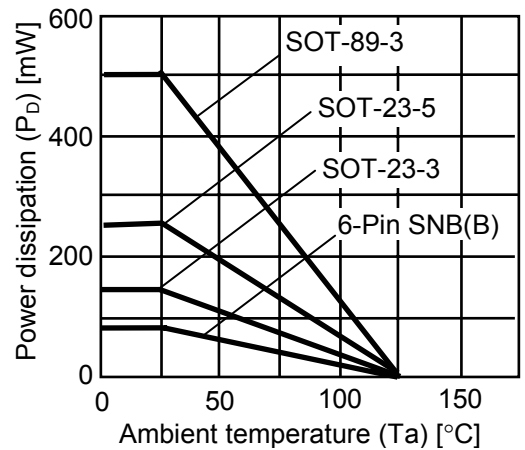


Figure 9 Power Dissipation of The Packages (Before Mounting)

■ **Electrical Characteristics**

(1) 100 kHz Product (B, E and K Types)

**Table 23 (1 / 2)**

(Ta = 25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Measurement circuit	
Output voltage	$V_{OUT}$	–	$V_{OUT(S)} \times 0.976$	$V_{OUT(S)}$	$V_{OUT(S)} \times 1.024$	V	2	
Input voltage	$V_{IN}$	–	–	–	10	V	2	
Operation start voltage	$V_{ST1}$	$I_{OUT} = 1 \text{ mA}$	–	–	0.9	V	2	
Oscillation start voltage	$V_{ST2}$	No external parts, Voltage applied to $V_{OUT}$	–	–	0.8	V	1	
Operation holding voltage	$V_{HLD}$	$I_{OUT} = 1 \text{ mA}$ , Judged by decreasing $V_{IN}$ voltage gradually	0.7	–	–	V	2	
Current consumption 1	$I_{SS1}$	$V_{OUT} = V_{OUT(S)} \times 0.95$	S-835xx15 to 19	–	14.0	23.4	$\mu\text{A}$	1
			S-835xx20 to 29	–	19.7	32.9	$\mu\text{A}$	1
			S-835xx30 to 39	–	25.9	43.2	$\mu\text{A}$	1
			S-835xx40 to 49	–	32.6	54.4	$\mu\text{A}$	1
			S-835xx50 to 59	–	39.8	66.4	$\mu\text{A}$	1
			S-835xx60 to 65	–	47.3	78.9	$\mu\text{A}$	1
Current consumption 2	$I_{SS2}$	$V_{OUT} = V_{OUT(S)} + 0.5 \text{ V}$	S-835xx15 to 19	–	5.6	11.1	$\mu\text{A}$	1
			S-835xx20 to 29	–	5.8	11.5	$\mu\text{A}$	1
			S-835xx30 to 39	–	5.9	11.8	$\mu\text{A}$	1
			S-835xx40 to 49	–	6.1	12.1	$\mu\text{A}$	1
			S-835xx50 to 59	–	6.3	12.5	$\mu\text{A}$	1
			S-835xx60 to 65	–	6.4	12.8	$\mu\text{A}$	1
Current consumption during shutdown (With shutdown function)	$I_{SSS}$	$V_{ON/OFF} = 0 \text{ V}$	–	–	0.5	$\mu\text{A}$	1	
EXT pin output current	$I_{EXTH}$	$V_{EXT} = V_{OUT} - 0.4 \text{ V}$	S-835xx15 to 19	–4.5	–8.9	–	mA	1
			S-835xx20 to 24	–6.2	–12.3	–	mA	1
			S-835xx25 to 29	–7.8	–15.7	–	mA	1
			S-835xx30 to 39	–10.3	–20.7	–	mA	1
			S-835xx40 to 49	–13.3	–26.7	–	mA	1
			S-835xx50 to 59	–16.1	–32.3	–	mA	1
			S-835xx60 to 65	–18.9	–37.7	–	mA	1
	$I_{EXTL}$	$V_{EXT} = 0.4 \text{ V}$	S-835xx15 to 19	9.5	19.0	–	mA	1
			S-835xx20 to 24	12.6	25.2	–	mA	1
			S-835xx25 to 29	15.5	31.0	–	mA	1
			S-835xx30 to 39	19.2	38.5	–	mA	1
			S-835xx40 to 49	23.8	47.6	–	mA	1
			S-835xx50 to 59	27.4	54.8	–	mA	1
			S-835xx60 to 65	30.3	60.6	–	mA	1
Line regulation	$\Delta V_{OUT1}$	$V_{IN} = V_{OUT(S)} \times 0.4 \text{ to } \times 0.6$	–	30	60	mV	2	
Load regulation	$\Delta V_{OUT2}$	$I_{OUT} = 10 \mu\text{A to } V_{OUT(S)} / 50 \times 1.25$	–	30	60	mV	2	
Output voltage temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT}}$	Ta = –40 to +85°C	–	±50	–	ppm / °C	2	
Oscillation frequency	$f_{OSC}$	$V_{OUT} = V_{OUT(S)} \times 0.95$	85	100	115	kHz	1	
Maximum duty ratio	MaxDuty	$V_{OUT} = V_{OUT(S)} \times 0.95$	75	83	90	%	1	
PWM / PFM switching duty ratio (For S-8356/58 Series)	PFMDuty	$V_{IN} = V_{OUT(S)} - 0.1 \text{ V}$ , No-load	10	15	24	%	1	
ON / OFF pin input voltage (With shutdown function)	$V_{SH}$	Measured oscillation at EXT pin	0.75	–	–	V	1	
	$V_{SL1}$	Judged oscillation stop at EXT pin	At $V_{OUT} \geq 1.5 \text{ V}$	–	–	0.3	V	1
			At $V_{OUT} < 1.5 \text{ V}$	–	–	0.2	V	1

**Table 23 (2 / 2)**

(Ta = 25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Measurement circuit
ON/OFF pin input current (For with shutdown function)	I <sub>SH</sub>	V <sub>ON/OFF</sub> = V <sub>OUT(S)</sub> × 0.95	-0.1	-	0.1	μA	1
	I <sub>SL</sub>	V <sub>ON/OFF</sub> = 0 V	-0.1	-	0.1	μA	1
Soft start time	t <sub>SS</sub>	-	3.0	6.0	12.0	ms	2
Efficiency	EFFI	-	-	85	-	%	2

**External parts**

- Coil: CDRH6D28-470 of Sumida Corporation
- Diode: RB461F (Schottky type) of Rohm Co., Ltd.
- Capacitor: F93 (16 V, 47 μF tantalum type) of Nichicon Corporation
- Transistor: CPH3210 of Sanyo Electric Co., Ltd.
- Base resistor (R<sub>b</sub>): 1.0 kΩ
- Base capacitor (C<sub>b</sub>): 2200 pF (ceramic type)

V<sub>IN</sub> = V<sub>OUT(S)</sub> × 0.6 applied, I<sub>OUT</sub> = V<sub>OUT(S)</sub> / 50 Ω

With shutdown function : ON/OFF pin is connected to V<sub>OUT</sub>

For V<sub>DD</sub> / V<sub>OUT</sub> separate type : V<sub>DD</sub> pin is connected to V<sub>OUT</sub> pin

**Remark 1.** V<sub>OUT(S)</sub> specified above is the set output voltage value, and V<sub>OUT</sub> is the typical value of the actual output voltage.

**2.** V<sub>DD</sub> / V<sub>OUT</sub> separate type

A step-up operation is performed from V<sub>DD</sub> = 0.8 V. However, 1.8 V ≤ V<sub>DD</sub> ≤ 10 V is recommended stabilizing the output voltage and oscillation frequency. (V<sub>DD</sub> ≥ 1.8 V must be applied for products with a set value of less than 1.9 V.)

(2) 250 kHz Product (H, J and L Types)

Table 24

(Ta = 25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Measurement circuit	
Output voltage	$V_{OUT}$	–	$V_{OUT(S)} \times 0.976$	$V_{OUT(S)}$	$V_{OUT(S)} \times 1.024$	V	2	
Input voltage	$V_{IN}$	–	–	–	10	V	2	
Operation start voltage	$V_{ST1}$	$I_{OUT} = 1 \text{ mA}$	–	–	0.9	V	2	
Oscillation start voltage	$V_{ST2}$	No external parts, Voltage applied to $V_{OUT}$	–	–	0.8	V	1	
Operation holding voltage	$V_{HLD}$	$I_{OUT} = 1 \text{ mA}$ , Judged by decreasing $V_{IN}$ voltage gradually	0.7	–	–	V	2	
Current consumption 1	$I_{SS1}$	$V_{OUT} = V_{OUT(S)} \times 0.95$	S-835xx15 to 19	–	28.9	48.2	$\mu\text{A}$	1
			S-835xx20 to 29	–	42.7	71.1	$\mu\text{A}$	1
			S-835xx30 to 39	–	58.0	96.7	$\mu\text{A}$	1
			S-835xx40 to 49	–	74.5	124.1	$\mu\text{A}$	1
			S-835xx50 to 59	–	92.0	153.4	$\mu\text{A}$	1
			S-835xx60 to 65	–	110.5	184.2	$\mu\text{A}$	1
Current consumption 2	$I_{SS2}$	$V_{OUT} = V_{OUT(S)} + 0.5 \text{ V}$	S-835xx15 to 19	–	8.7	17.3	$\mu\text{A}$	1
			S-835xx20 to 29	–	8.8	17.6	$\mu\text{A}$	1
			S-835xx30 to 39	–	9.0	18.0	$\mu\text{A}$	1
			S-835xx40 to 49	–	9.2	18.3	$\mu\text{A}$	1
			S-835xx50 to 59	–	9.3	18.6	$\mu\text{A}$	1
			S-835xx60 to 65	–	9.5	19.0	$\mu\text{A}$	1
Current consumption during shutdown (With shutdown function)	$I_{SSS}$	$V_{ON/OFF} = 0 \text{ V}$	–	–	0.5	$\mu\text{A}$	1	
EXT pin output current	$I_{EXTH}$	$V_{EXT} = V_{OUT} - 0.4 \text{ V}$	S-835xx15 to 19	–4.5	–8.9	–	mA	1
			S-835xx20 to 24	–6.2	–12.3	–	mA	1
			S-835xx25 to 29	–7.8	–15.7	–	mA	1
			S-835xx30 to 39	–10.3	–20.7	–	mA	1
			S-835xx40 to 49	–13.3	–26.7	–	mA	1
			S-835xx50 to 59	–16.1	–32.3	–	mA	1
			S-835xx60 to 65	–18.9	–37.7	–	mA	1
			$I_{EXTL}$	$V_{EXT} = 0.4 \text{ V}$	S-835xx15 to 19	9.5	19.0	–
	S-835xx20 to 24	12.6	25.2	–	mA	1		
	S-835xx25 to 29	15.5	31.0	–	mA	1		
	S-835xx30 to 39	19.2	38.5	–	mA	1		
	S-835xx40 to 49	23.8	47.6	–	mA	1		
	S-835xx50 to 59	27.4	54.8	–	mA	1		
	S-835xx60 to 65	30.3	60.6	–	mA	1		
Line regulation	$\Delta V_{OUT1}$	$V_{IN} = V_{OUT(S)} \times 0.4$ to $\times 0.6$	–	30	60	mV	2	
Load regulation	$\Delta V_{OUT2}$	$I_{OUT} = 10 \mu\text{A}$ to $V_{OUT(S)} / 50 \times 1.25$	–	30	60	mV	2	
Output voltage temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT}}$	$T_a = -40$ to $+85^\circ\text{C}$	–	$\pm 50$	–	ppm / °C	2	
Oscillation frequency	$f_{OSC}$	$V_{OUT} = V_{OUT(S)} \times 0.95$	212.5	250	287.5	kHz	1	
Maximum duty ratio	MaxDuty	$V_{OUT} = V_{OUT(S)} \times 0.95$	70	78	85	%	1	
PWM / PFM switching duty ratio (For S-8356/58 Series)	PFMDuty	$V_{IN} = V_{OUT(S)} - 0.1 \text{ V}$ , No-load	10	15	24	%	1	
ON / OFF pin input voltage (With shutdown function)	$V_{SH}$	Measured oscillation at EXT pin	0.75	–	–	V	1	
	$V_{SL1}$	Judged oscillation stop at EXT pin	At $V_{OUT} \geq 1.5 \text{ V}$	–	–	0.3	V	1
	$V_{SL2}$		At $V_{OUT} < 1.5 \text{ V}$	–	–	0.2	V	1
ON / OFF pin input current (With shutdown function)	$I_{SH}$	$V_{ON/OFF} = V_{OUT(S)} \times 0.95$	–0.1	–	0.1	$\mu\text{A}$	1	
	$I_{SL}$	$V_{ON/OFF} = 0 \text{ V}$	–0.1	–	0.1	$\mu\text{A}$	1	
Soft start time	$t_{SS}$	–	1.5	3.0	6.0	ms	2	
Efficiency	EFFI	–	–	85	–	%	2	

External parts

Coil:	CDRH6D28-220 of Sumida Corporation
Diode:	RB461F (Schottky type) of Rohm Co., Ltd.
Capacitor:	F93 (16 V, 47 $\mu$ F tantalum type) of Nichicon Corporation
Transistor:	CPH3210 of Sanyo Electric Co., Ltd.
Base resistor ( $R_b$ ):	1.0 k $\Omega$
Base capacitor ( $C_b$ ):	2200 pF (ceramic type)

$V_{IN} = V_{OUT(S)} \times 0.6$  applied,  $I_{OUT} = V_{OUT(S)} / 50 \Omega$

With shutdown function : ON/OFF pin is connected to  $V_{OUT}$

For  $V_{DD}$  /  $V_{OUT}$  separate type :  $V_{DD}$  pin is connected to  $V_{OUT}$  pin

- Remark**
1.  $V_{OUT(S)}$  specified above is the set output voltage value, and  $V_{OUT}$  is the typical value of the actual output voltage.
  2.  $V_{DD}$  /  $V_{OUT}$  separate type  
A step-up operation is performed from  $V_{DD} = 0.8$  V. However,  $1.8 \text{ V} \leq V_{DD} \leq 10 \text{ V}$  is recommended stabilizing the output voltage and oscillation frequency. ( $V_{DD} \geq 1.8$  V must be applied for products with a set value of less than 1.9 V.)

(3) 300 kHz Product (F, G and M Types)

Table 25

(Ta = 25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Measurement circuit	
Output voltage	$V_{OUT}$	–	$V_{OUT(S)} \times 0.976$	$V_{OUT(S)}$	$V_{OUT(S)} \times 1.024$	V	2	
Input voltage	$V_{IN}$	–	–	–	10	V	2	
Operation start voltage	$V_{ST1}$	$I_{OUT} = 1 \text{ mA}$	–	–	0.9	V	2	
Oscillation start voltage	$V_{ST2}$	No external parts, Voltage applied to $V_{OUT}$	–	–	0.8	V	1	
Operation holding voltage	$V_{HLD}$	$I_{OUT} = 1 \text{ mA}$ , Judged by decreasing $V_{IN}$ voltage gradually	0.7	–	–	V	2	
Current consumption 1	$I_{SS1}$	$V_{OUT} = V_{OUT(S)} \times 0.95$	S-835xx15 to 19	–	33.8	56.4	$\mu\text{A}$	1
			S-835xx20 to 29	–	50.3	83.9	$\mu\text{A}$	1
			S-835xx30 to 39	–	68.6	114.4	$\mu\text{A}$	1
			S-835xx40 to 49	–	88.4	147.4	$\mu\text{A}$	1
			S-835xx50 to 59	–	109.4	182.4	$\mu\text{A}$	1
			S-835xx60 to 65	–	131.6	219.3	$\mu\text{A}$	1
Current consumption 2	$I_{SS2}$	$V_{OUT} = V_{OUT(S)} + 0.5 \text{ V}$	S-835xx15 to 19	–	9.7	19.4	$\mu\text{A}$	1
			S-835xx20 to 29	–	9.9	19.7	$\mu\text{A}$	1
			S-835xx30 to 39	–	10.0	20.0	$\mu\text{A}$	1
			S-835xx40 to 49	–	10.2	20.4	$\mu\text{A}$	1
			S-835xx50 to 59	–	10.4	20.7	$\mu\text{A}$	1
			S-835xx60 to 65	–	10.5	21.0	$\mu\text{A}$	1
Current consumption during shutdown (With shutdown function)	$I_{SSS}$	$V_{ON/OFF} = 0 \text{ V}$	–	–	0.5	$\mu\text{A}$	1	
EXT pin output current	$I_{EXTH}$	$V_{EXT} = V_{OUT} - 0.4 \text{ V}$	S-835xx15 to 19	–4.5	–8.9	–	mA	1
			S-835xx20 to 24	–6.2	–12.3	–	mA	1
			S-835xx25 to 29	–7.8	–15.7	–	mA	1
			S-835xx30 to 39	–10.3	–20.7	–	mA	1
			S-835xx40 to 49	–13.3	–26.7	–	mA	1
			S-835xx50 to 59	–16.1	–32.3	–	mA	1
			S-835xx60 to 65	–18.9	–37.7	–	mA	1
			$I_{EXTL}$	$V_{EXT} = 0.4 \text{ V}$	S-835xx15 to 19	9.5	19.0	–
	S-835xx20 to 24	12.6			25.2	–	mA	1
	S-835xx25 to 29	15.5			31.0	–	mA	1
	S-835xx30 to 39	19.2			38.5	–	mA	1
	S-835xx40 to 49	23.8			47.6	–	mA	1
	S-835xx50 to 59	27.4			54.8	–	mA	1
	S-835xx60 to 65	30.3	60.6	–	mA	1		
Line regulation	$\Delta V_{OUT1}$	$V_{IN} = V_{OUT(S)} \times 0.4$ to $\times 0.6$	–	30	60	mV	2	
Load regulation	$\Delta V_{OUT2}$	$I_{OUT} = 10 \mu\text{A}$ to $V_{OUT(S)} / 50 \times 1.25$	–	30	60	mV	2	
Output voltage temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT}}$	$T_a = -40$ to $+85^\circ\text{C}$	–	$\pm 50$	–	ppm / °C	2	
Oscillation frequency	$f_{OSC}$	$V_{OUT} = V_{OUT(S)} \times 0.95$	255	300	345	kHz	1	
Maximum duty ratio	MaxDuty	$V_{OUT} = V_{OUT(S)} \times 0.95$	70	78	85	%	1	
PWM / PFM switching duty ratio (For S-8356/58 Series)	PFMDuty	$V_{IN} = V_{OUT(S)} - 0.1 \text{ V}$ , No-load	10	15	24	%	1	
ON / OFF pin input voltage (With shutdown function)	$V_{SH}$	Measured oscillation at EXT pin	0.75	–	–	V	1	
	$V_{SL1}$	Judged oscillation stop at EXT pin	At $V_{OUT} \geq 1.5 \text{ V}$	–	–	0.3	V	1
	$V_{SL2}$		At $V_{OUT} < 1.5 \text{ V}$	–	–	0.2	V	1
ON / OFF pin input current (With shutdown function)	$I_{SH}$	$V_{ON/OFF} = V_{OUT(S)} \times 0.95$	–0.1	–	0.1	$\mu\text{A}$	1	
	$I_{SL}$	$V_{ON/OFF} = 0 \text{ V}$	–0.1	–	0.1	$\mu\text{A}$	1	
Soft start time	$t_{SS}$	–	1.5	3.0	6.0	ms	2	
Efficiency	EFFI	–	–	85	–	%	2	



External parts

Coil:	CDRH6D28-220 of Sumida Corporation
Diode:	RB461F (Schottky type) of Rohm Co., Ltd.
Capacitor:	F93 (16 V, 47 $\mu$ F tantalum type) of Nichicon Corporation
Transistor:	CPH3210 of Sanyo Electric Co., Ltd.
Base resistor ( $R_b$ ):	1.0 k $\Omega$
Base capacitor ( $C_b$ ):	2200 pF (ceramic type)

$$V_{IN} = V_{OUT(S)} \times 0.6 \text{ applied, } I_{OUT} = V_{OUT(S)} / 50 \Omega$$

With shutdown function : ON/OFF pin is connected to  $V_{OUT}$

For  $V_{DD}$  /  $V_{OUT}$  separate type :  $V_{DD}$  pin is connected to  $V_{OUT}$  pin

- Remark**
1.  $V_{OUT(S)}$  specified above is the set output voltage value, and  $V_{OUT}$  is the typical value of the actual output voltage.
  2.  $V_{DD}$  /  $V_{OUT}$  separate type  
A step-up operation is performed from  $V_{DD} = 0.8$  V. However,  $1.8 \text{ V} \leq V_{DD} \leq 10 \text{ V}$  is recommended stabilizing the output voltage and oscillation frequency. ( $V_{DD} \geq 1.8$  V must be applied for products with a set value of less than 1.9 V.)

(4) 600 kHz Product (N Type)

Table 26

(Ta = 25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Measurement circuit	
Output voltage	V <sub>OUT</sub>	–	V <sub>OUT(S)</sub> × 0.976	V <sub>OUT(S)</sub>	V <sub>OUT(S)</sub> × 1.024	V	2	
Input voltage	V <sub>IN</sub>	–	–	–	10	V	2	
Operation start voltage	V <sub>ST1</sub>	I <sub>OUT</sub> = 1 mA	–	–	0.9	V	2	
Oscillation start voltage	V <sub>ST2</sub>	No external parts, Voltage applied to V <sub>OUT</sub>	–	–	0.8	V	1	
Operation holding voltage	V <sub>HLD</sub>	I <sub>OUT</sub> = 1 mA, Judged by decreasing V <sub>IN</sub> voltage gradually	0.7	–	–	V	2	
Current consumption 1	I <sub>SS1</sub>	V <sub>OUT</sub> = V <sub>OUT(S)</sub> × 0.95	S-835xx15 to 19	–	63.6	105.9	μA	1
			S-835xx20 to 29	–	96.4	160.6	μA	1
			S-835xx30 to 39	–	132.8	221.3	μA	1
			S-835xx40 to 49	–	172.2	286.9	μA	1
			S-835xx50 to 59	–	214.0	356.7	μA	1
Current consumption 2	I <sub>SS2</sub>	V <sub>OUT</sub> = V <sub>OUT(S)</sub> + 0.5 V	S-835xx15 to 19	–	15.9	31.8	μA	1
			S-835xx20 to 29	–	16.1	32.1	μA	1
			S-835xx30 to 39	–	16.2	32.4	μA	1
			S-835xx40 to 49	–	16.4	32.8	μA	1
			S-835xx50 to 59	–	16.6	33.1	μA	1
Current consumption during shutdown	I <sub>SSS</sub>	V <sub>ON/OFF</sub> = 0 V	S-835xx60 to 65	–	16.7	33.3	μA	1
				–	–	0.5	μA	1
EXT pin output current	I <sub>EXTH</sub>	V <sub>EXT</sub> = V <sub>OUT</sub> – 0.4 V	S-835xx15 to 19	–4.5	–8.9	–	mA	1
			S-835xx20 to 24	–6.2	–12.3	–	mA	1
			S-835xx25 to 29	–7.8	–15.7	–	mA	1
			S-835xx30 to 39	–10.3	–20.7	–	mA	1
			S-835xx40 to 49	–13.3	–26.7	–	mA	1
			S-835xx50 to 59	–16.1	–32.3	–	mA	1
			S-835xx60 to 65	–18.9	–37.7	–	mA	1
	I <sub>EXTL</sub>	V <sub>EXT</sub> = 0.4 V	S-835xx15 to 19	9.5	19.0	–	mA	1
			S-835xx20 to 24	12.6	25.2	–	mA	1
			S-835xx25 to 29	15.5	31.0	–	mA	1
			S-835xx30 to 39	19.2	38.5	–	mA	1
			S-835xx40 to 49	23.8	47.6	–	mA	1
			S-835xx50 to 59	27.4	54.8	–	mA	1
			S-835xx60 to 65	30.3	60.6	–	mA	1
Line regulation	ΔV <sub>OUT1</sub>	V <sub>IN</sub> = V <sub>OUT(S)</sub> × 0.4 to × 0.6	–	30	60	mV	2	
Load regulation	ΔV <sub>OUT2</sub>	I <sub>OUT</sub> = 10 μA to V <sub>OUT(S)</sub> / 50 × 1.25	–	30	60	mV	2	
Output voltage temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT}}$	Ta = –40 to +85°C	–	±50	–	ppm / °C	2	
Oscillation frequency	f <sub>OSC</sub>	V <sub>OUT</sub> = V <sub>OUT(S)</sub> × 0.95	510	600	690	kHz	1	
Maximum duty ratio	MaxDuty	V <sub>OUT</sub> = V <sub>OUT(S)</sub> × 0.95	65	78	85	%	1	
PWM / PFM switching duty ratio (For S-8356/58 Series)	PFMDuty	V <sub>IN</sub> = V <sub>OUT(S)</sub> – 0.1 V, No-load	10	15	24	%	1	
ON / OFF pin input voltage	V <sub>SH</sub>	Measured oscillation at EXT pin	0.75	–	–	V	1	
	V <sub>SL1</sub>	Judged oscillation stop at EXT pin	At V <sub>OUT</sub> ≥ 1.5 V	–	–	0.3	V	1
	V <sub>SL2</sub>		At V <sub>OUT</sub> < 1.5 V	–	–	0.2	V	1
ON / OFF pin input current	I <sub>SH</sub>	V <sub>ON/OFF</sub> = V <sub>OUT(S)</sub> × 0.95	–0.1	–	0.1	μA	1	
	I <sub>SL</sub>	V <sub>ON/OFF</sub> = 0 V	–0.1	–	0.1	μA	1	
Soft start time	t <sub>SS</sub>	–	1.5	3.0	6.0	ms	2	
Efficiency	EFFI	–	–	85	–	%	2	

External parts

Coil:	CDRH6D28-100 of Sumida Corporation
Diode:	RB461F (Schottky type) of Rohm Co., Ltd.
Capacitor:	F93 (16 V, 47 $\mu$ F tantalum type) of Nichicon Corporation
Transistor:	CPH3210 of Sanyo Electric Co., Ltd.
Base resistor ( $R_b$ ):	1.0 k $\Omega$
Base capacitor ( $C_b$ ):	2200 pF (ceramic type)

$$V_{IN} = V_{OUT(S)} \times 0.6 \text{ applied, } I_{OUT} = V_{OUT(S)} / 50 \Omega, \text{ ON/OFF} = V_{OUT}$$

**Remark**  $V_{OUT(S)}$  specified above is the set output voltage value, and  $V_{OUT}$  is the typical value of the actual output voltage.

(5) 600 kHz Product (P and Q types)

Table 27

(Ta = 25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Measurement circuit
Output voltage	$V_{OUT}$	–	$V_{OUT(S)} \times 0.976$	$V_{OUT(S)}$	$V_{OUT(S)} \times 1.024$	V	4
Input voltage	$V_{IN}$	–	–	–	10	V	4
Operation start voltage	$V_{ST1}$	$I_{OUT} = 1 \text{ mA}$	–	–	0.9	V	4
Oscillation start voltage	$V_{ST2}$	No external parts, Voltage applied to $V_{DD}$	–	–	0.8	V	3
Operation holding voltage	$V_{HLD}$	$I_{OUT} = 1 \text{ mA}$ , Judged by decreasing $V_{IN}$ voltage gradually	0.7	–	–	V	4
Current consumption 1	$I_{SS1}$	$V_{DD} = 3.3 \text{ V}$	–	132.8	221.3	$\mu\text{A}$	3
Current consumption 2	$I_{SS2}$	$V_{DD} = 3.3 \text{ V}$	–	16.2	32.4	$\mu\text{A}$	3
Current consumption during shutdown (With shutdown function)	$I_{SS3}$	$V_{ON/OFF} = 0 \text{ V}$	–	–	0.5	$\mu\text{A}$	3
EXT pin output current	$I_{EXTH}$	$V_{DD} = 3.3 \text{ V}$	–10.3	–20.7	–	mA	3
	$I_{EXTL}$	$V_{DD} = 3.3 \text{ V}$	19.2	38.5	–	mA	3
Line regulation	$\Delta V_{OUT1}$	$V_{IN} = V_{OUT(S)} \times 0.4 \text{ to } \times 0.6$	–	30	60	mV	4
Load regulation	$\Delta V_{OUT2}$	$I_{OUT} = 10 \mu\text{A to } V_{OUT(S)} / 50 \times 1.25$	–	30	60	mV	4
Output voltage temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT}}$	$T_a = -40 \text{ to } +85^\circ\text{C}$	–	$\pm 50$	–	ppm / °C	4
Oscillation frequency	$f_{OSC}$	$V_{DD} = 3.3 \text{ V}$	510	600	690	kHz	3
Maximum duty ratio	MaxDuty	$V_{DD} = 3.3 \text{ V}$	65	78	85	%	3
PWM / PFM switching duty ratio (For S-8356/58 Series)	PFMDuty	$V_{IN} = V_{OUT(S)} - 0.1 \text{ V}$ , No-load	10	15	24	%	3
ON / OFF pin input voltage (With shutdown function)	$V_{SH}$	Measured oscillation at EXT pin	0.75	–	–	V	3
	$V_{SL1}$	Judged oscillation stop at EXT pin	–	–	0.3	V	3
	$V_{SL2}$	At $V_{OUT} < 1.5 \text{ V}$	–	–	0.2	V	3
ON / OFF pin input current (With shutdown function)	$I_{SH}$	$V_{ON/OFF} = V_{OUT(S)} \times 0.95$	–0.1	–	0.1	$\mu\text{A}$	3
	$I_{SL}$	$V_{ON/OFF} = 0 \text{ V}$	–0.1	–	0.1	$\mu\text{A}$	3
Soft start time	$t_{SS}$	–	1.5	3.0	6.0	ms	4
Efficiency	EFFI	–	–	85	–	%	4

External parts

Coil: CDRH6D28-100 of Sumida Corporation  
 Diode: RB461F (Schottky type) of Rohm Co., Ltd.  
 Capacitor: F93 (16 V, 47  $\mu\text{F}$  tantalum type) of Nichicon Corporation  
 Transistor: CPH3210 of Sanyo Electric Co., Ltd.  
 Base resistor ( $R_b$ ): 1.0 k $\Omega$   
 Base capacitor ( $C_b$ ): 2200 pF (ceramic type)

$V_{IN} = V_{OUT(S)} \times 0.6$  applied,  $I_{OUT} = V_{OUT(S)} / 50 \Omega$ ,  $V_{ON/OFF} = V_{OUT}$

- Remark**
- $V_{OUT(S)}$  specified above is the set output voltage value, and  $V_{OUT}$  is the typical value of the actual output voltage.
  - $V_{DD} / V_{OUT}$  separate type  
 A step-up operation is performed from  $V_{DD} = 0.8 \text{ V}$ . However,  $1.8 \text{ V} \leq V_{DD} \leq 10 \text{ V}$  is recommended stabilizing the output voltage and oscillation frequency. ( $V_{DD} \geq 1.8 \text{ V}$  must be applied for products with a set value of less than 1.9 V.)

■ Measurement Circuits

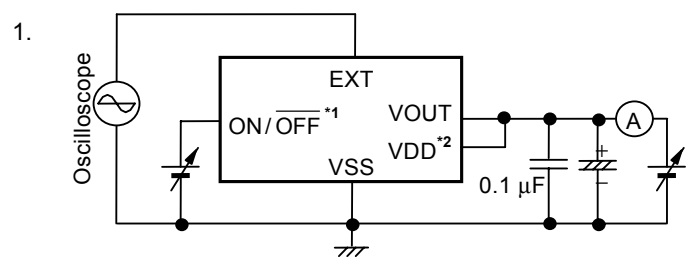


Figure 10

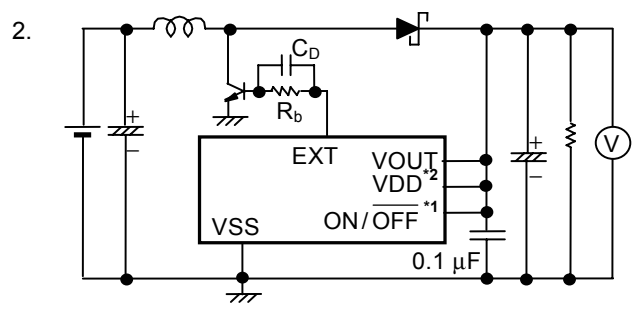


Figure 11

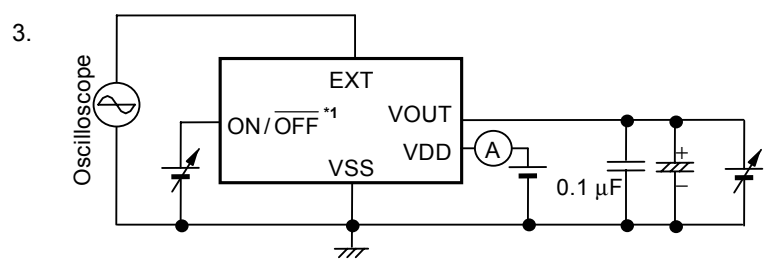


Figure 12

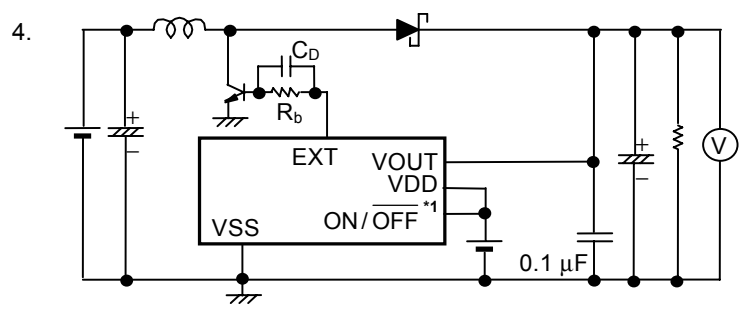


Figure 13

\*1. With shutdown function  
 \*2. For V<sub>DD</sub> / V<sub>OUT</sub> separate type

## ■ Operation

### 1. Switching Control Types

#### 1.1 PWM Control (S-8355/57 Series)

The S-8355/57 Series is a DC-DC converter using a pulse width modulation method (PWM) and features a low current consumption.

In conventional PFM DC-DC converters, pulses are skipped when the output load current is low, causing a fluctuation in the ripple frequency of the output voltage, resulting in an increase in the ripple voltage. The switching frequency does not change, although the pulse width changes from 0 to 83% (78% for F, G, H, J, L, M, N, P and Q types) corresponding to each load current. The ripple voltage generated from switching can thus be removed easily through a filter because the switching frequency is constant.

#### 1.2 PWM/PFM Switching Control (S-8356/58 Series)

S-8356/58 Series is a DC-DC converter that automatically switches between a pulse width modulation method (PWM) and a pulse frequency modulation method (PFM), depending on the load current, and features low current consumption.

The S-8356/58 Series operates under PWM control with the pulse width duty changing from 15 to 83% (78% for F, G, H, J, L, M, N, P and Q types) in a high output load current area.

The S-8356/58 Series operates under PFM control with the pulse width duty fixed at 15%, and pulses are skipped according to the load current. The oscillation circuit thus oscillates intermittently so that the resultant lower self current consumption prevents a reduction in the efficiency at a low load current. The switching point from PWM control to PFM control depends on the external devices (coil, diode, etc.), input voltage and output voltage. This series are an especially highly efficient DC-DC converter at an output current around 100  $\mu$ A.

### 2. Soft Start Function

For this IC, the built-in soft start circuit controls the rush current and overshoot of the output voltage when powering on or when the  $\overline{\text{ON/OFF}}$  pin is switched to the "H" level.

**3. ON/OFF Pin (Shutdown Pin) (SOT-23-5 Package Products of S-8355/56/57/58 Series B, H, F, K, L, M, N and Q Types, and 6-Pin SNB(B) Package Products)**

ON/OFF pin stops or starts step-up operation.

Setting the ON/OFF pin to the “L” level stops operation of all the internal circuits and reduces the current consumption significantly.

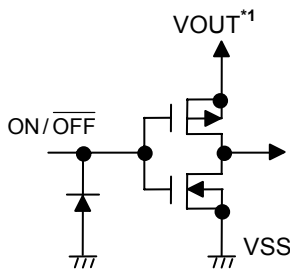
DO NOT use the ON/OFF pin in a floating state because it has the structure shown in **Figure 14** and is not pulled up or pulled down internally. DO NOT apply a voltage of between 0.3 V and 0.75 V to the ON/OFF pin because applying such a voltage increases the current consumption. If the ON/OFF pin is not used, connect it to the VOUT pin.

The ON/OFF pin does not have hysteresis.

**Table 28**

ON/OFF pin	CR oscillation circuit	Output voltage
“H”	Operation	Fixed
“L”	Stop	$\cong V_{IN}^{*1}$

\*1. Voltage obtained by subtracting the voltage drop due to the DC resistance of the inductor and the diode forward voltage from  $V_{IN}$ .

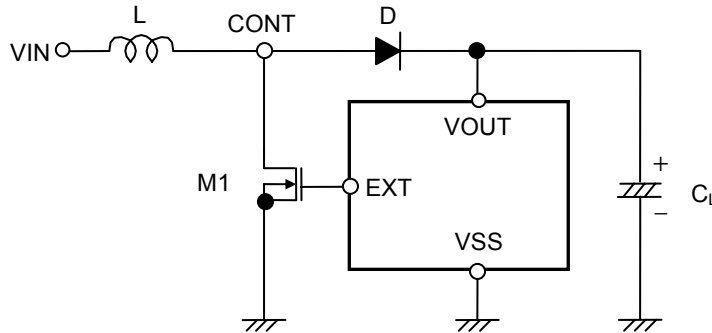


\*1. VDD for K, L, M and Q types.

**Figure 14 ON/OFF Pin Structure**

**4. Operation**

The following are the basic equations [(1) through (7)] of the step-up switching regulator. (Refer to **Figure 15**.)



**Figure 15 Step-Up Switching Regulator Circuit for Basic Equation**

Voltage at CONT pin at the moment M1 is turned ON ( $V_A$ ) \*1 :

$$V_A = V_S \text{ *2} \dots\dots\dots (1)$$

- \*1. Current flowing through L ( $I_L$ ) is zero.
- \*2. Non-saturated voltage of M1.

The change in  $I_L$  over time :

$$\frac{dI_L}{dt} = \frac{V_L}{L} = \frac{V_{IN} - V_S}{L} \dots\dots\dots (2)$$

Integration of equation (2) ( $I_L$ ) :

$$I_L = \left( \frac{V_{IN} - V_S}{L} \right) \cdot t \dots\dots\dots (3)$$

$I_L$  flows while M1 is ON ( $t_{ON}$ ). The time of  $t_{ON}$  is determined by the oscillation frequency of OSC.

The peak current ( $I_{PK}$ ) after  $t_{ON}$  :

$$I_{PK} = \left( \frac{V_{IN} - V_S}{L} \right) \cdot t_{ON} \dots\dots\dots (4)$$

The energy stored in L is represented by  $1/2 \cdot L \cdot (I_{PK})^2$ .

When M1 is turned OFF ( $t_{OFF}$ ), the energy stored in L is emitted through a diode to the output capacitor.

Then, the reverse voltage ( $V_L$ ) is generated :

$$V_L = (V_{OUT} + V_D \text{ *1}) - V_{IN} \dots\dots\dots (5)$$

- \*1. Diode forward voltage

The voltage at CONT pin rises only by  $V_{OUT} + V_D$ .

The change in the current ( $I_L$ ) flowing through the diode into  $V_{OUT}$  during  $t_{OFF}$  :

$$\frac{dI_L}{dt} = \frac{V_L}{L} = \frac{V_{OUT} + V_D - V_{IN}}{L} \dots\dots\dots (6)$$



Integration of the equation (6) is as follows :

$$I_L = I_{PK} - \left( \frac{V_{OUT} + V_D - V_{IN}}{L} \right) \cdot t \dots\dots\dots (7)$$

During  $t_{ON}$ , the energy is stored in L and is not transmitted to  $V_{OUT}$ . When receiving the output current ( $I_{OUT}$ ) from  $V_{OUT}$ , the energy of the capacitor ( $C_L$ ) is consumed. As a result, the pin voltage of  $C_L$  is reduced, and goes to the lowest level after M1 is turned ON ( $t_{ON}$ ). When M1 is turned OFF, the energy stored in L is transmitted through the diode to  $C_L$ , and the voltage of  $C_L$  rises rapidly.  $V_{OUT}$  is a time function, and therefore indicates the maximum value (ripple voltage ( $V_{P-P}$ )) when the current flowing through into  $V_{OUT}$  and load current ( $I_{OUT}$ ) match.

Next, the ripple voltage is determined as follows.

$I_{OUT}$  vs.  $t_1$  (time) from when M1 is turned OFF (after  $t_{ON}$ ) to when  $V_{OUT}$  reaches the maximum level :

$$I_{OUT} = I_{PK} - \left( \frac{V_{OUT} + V_D - V_{IN}}{L} \right) \cdot t_1 \dots\dots\dots (8)$$

$$\therefore t_1 = (I_{PK} - I_{OUT}) \cdot \left( \frac{L}{V_{OUT} + V_D - V_{IN}} \right) \dots\dots\dots (9)$$

When M1 is turned OFF ( $t_{OFF}$ ),  $I_L = 0$  (when the energy of the inductor is completely transmitted). Based on equation (7) :

$$\left( \frac{L}{V_{OUT} + V_D - V_{IN}} \right) = \frac{t_{OFF}}{I_{PK}} \dots\dots\dots (10)$$

When substituting equation (10) for equation (9) :

$$t_1 = t_{OFF} - \left( \frac{I_{OUT}}{I_{PK}} \right) \cdot t_{OFF} \dots\dots\dots (11)$$

Electric charge  $\Delta Q_1$  which is charged in  $C_L$  during  $t_1$  :

$$\Delta Q_1 = \int_0^{t_1} I_L dt = I_{PK} \cdot \int_0^{t_1} dt - \frac{V_{OUT} + V_D - V_{IN}}{L} \cdot \int_0^{t_1} t dt = I_{PK} \cdot t_1 - \frac{V_{OUT} + V_D - V_{IN}}{L} \cdot \frac{1}{2} t_1^2 \dots\dots\dots (12)$$

When substituting equation (12) for equation (9) :

$$\Delta Q_1 = I_{PK} - \frac{1}{2} (I_{PK} - I_{OUT}) \cdot t_1 = \frac{I_{PK} + I_{OUT}}{2} \cdot t_1 \dots\dots\dots (13)$$

A rise in voltage ( $V_{P-P}$ ) due to  $\Delta Q_1$  :

$$V_{P-P} = \frac{\Delta Q_1}{C_L} = \frac{1}{C_L} \cdot \left( \frac{I_{PK} + I_{OUT}}{2} \right) \cdot t_1 \dots\dots\dots (14)$$

When taking into consideration  $I_{OUT}$  to be consumed during  $t_1$  and the Equivalent Series Resistance ( $R_{ESR}$ ) of  $C_L$  :

$$V_{P-P} = \frac{\Delta Q_1}{C_L} = \frac{1}{C_L} \cdot \left( \frac{I_{PK} + I_{OUT}}{2} \right) \cdot t_1 + \left( \frac{I_{PK} + I_{OUT}}{2} \right) \cdot R_{ESR} - \frac{I_{OUT} \cdot t_1}{C_L} \dots\dots\dots (15)$$

When substituting equation (11) for equation (15) :

$$V_{P-P} = \frac{(I_{PK} - I_{OUT})^2}{2I_{PK}} \cdot \frac{t_{OFF}}{C_L} + \left( \frac{I_{PK} + I_{OUT}}{2} \right) \cdot R_{ESR} \dots\dots\dots (16)$$

Therefore to reduce the ripple voltage, it is important that the capacitor connected to the output pin has a large capacity and a small  $R_{ESR}$ .

■ **External Parts Selection**

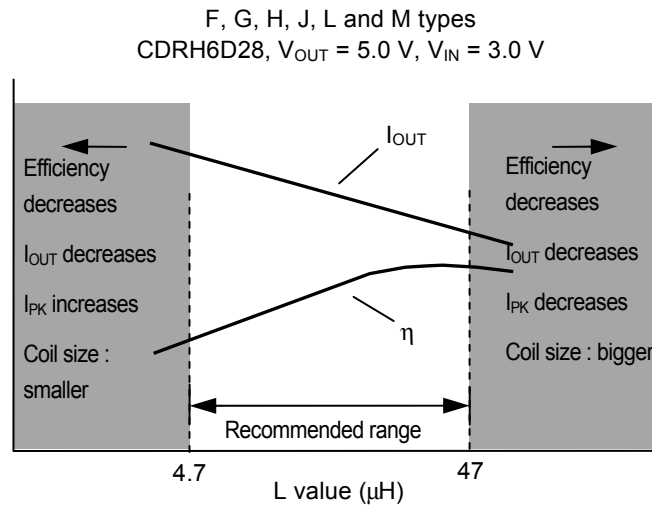
The relationship between the major characteristics of the step-up circuit and the characteristics parameters of the external parts are shown in **Figure 16**.

For larger output current ?	For higher efficiency ?		For smaller ripple voltage ?
	Operation efficiency	Stand-by efficiency	
Smaller inductance	Larger inductance		
Smaller direct current resistance of inductor			
Larger output capacitance			Larger output capacitance
With MOS FET, smaller ON resistance	With MOS FET, smaller input capacitance		
With bipolar transistor, smaller external resistance $R_b$	With bipolar transistor, larger external resistance $R_b$		

**Figure 16 Relationship between Major Characteristics of Step-up Circuit and External Parts**

**1. Inductor**

The inductance value (L value) has a strong influence on the maximum output current ( $I_{OUT}$ ) and efficiency ( $\eta$ ). **Figure 17** shows the relationship between the  $I_{OUT}$  and  $\eta$  dependency on L of S-8355/56/57/58.



**Figure 17 L Value vs.  $I_{OUT}$  Characteristics, L Value vs.  $\eta$  Characteristics**

The peak current ( $I_{PK}$ ) increases by decreasing L value and the stability of the circuit improves and  $I_{OUT}$  increases. If L value is decreased, the efficiency falls causing a decline in the current drive capacity for the switching transistor, and  $I_{OUT}$  decreases.

The loss of  $I_{PK}$  by the switching transistor decreases by increasing L value and the efficiency becomes maximum at a certain L value. Further increasing L value decreases the efficiency due to the loss of the direct current resistance of the coil.  $I_{OUT}$  also decreases.

A higher oscillation frequency allows selection of a lower L value, making the coil smaller.

The recommended inductances are a 22 to 100  $\mu\text{H}$  for B, E, and K types, a 4.7 to 47  $\mu\text{H}$  for F, G, H, J, L, and M types, 3.0 to 22  $\mu\text{H}$  for N, P and Q types.

Be careful of the allowable inductor current when choosing an inductor. Exceeding the allowable current of the inductor causes magnetic saturation, much lower efficiency and destruction of the IC chip due to a large current.

Choose an inductor so that  $I_{PK}$  does not exceed the allowable current.  $I_{PK}$  in discontinuous mode is calculated by the following equation:

$$I_{PK} = \sqrt{\frac{2I_{OUT}(V_{OUT} + V_D - V_{IN})}{f_{OSC} \cdot L}} \text{ (A)} \dots\dots\dots (17)$$

$f_{osc}$  = oscillation frequency,  $V_D \cong 0.4\text{ V}$ .

**2. Diode**

Use an external diode that meets the following requirements :

- Low forward voltage :  $V_F < 0.3\text{ V}$
- High switching speed : 500 ns max.
- Reverse voltage :  $V_{OUT} + V_F$  or more
- Current rate :  $I_{PK}$  or more

### 3. Capacitor ( $C_{IN}$ , $C_L$ )

A capacitor on the input side ( $C_{IN}$ ) improves the efficiency by reducing the power impedance and stabilizing the input current. Select a  $C_{IN}$  value according to the impedance of the power supply used.

A capacitor on the output side ( $C_L$ ) is used for smoothing the output voltage. For step-up types, the output voltage flows intermittently to the load current, so step-up types need a larger capacitance than step-down types. Therefore, select an appropriate capacitor in accordance with the ripple voltage, which increases in case of a higher output voltage or a higher load current. The capacitor value should be 10  $\mu$ F or more.

Select an appropriate capacitor the equivalent series resistance ( $R_{ESR}$ ) for stable output voltage. The stable voltage range in this IC depends on the  $R_{ESR}$ . Although the inductance value (L value) is also a factor, an  $R_{ESR}$  of 30 to 500 m $\Omega$  maximizes the characteristics. However, the best  $R_{ESR}$  value may depend on the L value, the capacitance, the wiring, and the applications (output load). Therefore, fully evaluate the  $R_{ESR}$  under the actual operating conditions to determine the best value.

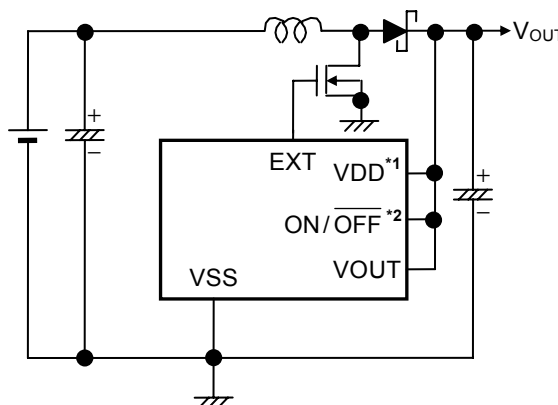
Refer to the “3. Example of Ceramic Capacitor Application” (Figure 27) in the “Application Circuit” for the circuit example using a ceramic capacitor and the external resistance of the capacitor ( $R_{ESR}$ ).

### 4. External Transistor

An enhancement (N-channel) MOS FET type or A bipolar (NPN) type can be used as the external transistor.

#### 4.1 Enhancement (N-channel) MOS FET Type

Figure 18 is a circuit example using a MOS FET transistor (N-channel).



\*1. For  $V_{DD}$  /  $V_{OUT}$  separate type.

\*2. With shutdown function.

**Figure 18 Circuit Example Using MOS FET (N-channel) Type**

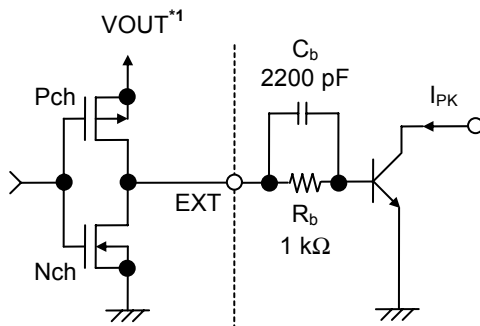
An N-channel power MOS FET should be used for the MOS FET. Because the gate voltage and current of the external power MOS FET are supplied from the stepped-up output voltage ( $V_{OUT}$ ), the MOS FET is driven more effectively.

A large current may flow during startup, depending on the MOS FET selection. So perform sufficient evaluation using the actual devices. Also recommend to use a MOS FET with an input capacitance of 700 pF or less.

Since the ON-resistance of the MOS FET might depend on the difference between the output voltage ( $V_{OUT}$ ) and the threshold voltage of the MOS FET, and affect the output current as well as the efficiency, the threshold voltage should be low. When the output voltage is low, the circuit operates only when the MOS FET has a threshold voltage lower than the output voltage.

#### 4.2 Bipolar (NPN) Type

A circuit example using the CPH3210 ( $h_{FE} = 200$  to  $560$ ) from Sanyo Electric Co., Ltd. As a bipolar transistor (NPN) is shown in **Figure 20 to 25** in the “■ Standard Circuits”. The  $h_{FE}$  value and  $R_b$  value of the bipolar transistor determine the driving capacity to increase the output current using a bipolar transistor. A peripheral circuit example of the transistor is shown in **Figure 19**.



\*1.  $V_{DD}$  for E, G, J, K, L, M, P and Q types.

**Figure 19 External Transistor Peripheral Circuit**

The recommended  $R_b$  value is around  $1\text{ k}\Omega$ . Actually, calculate the necessary base current ( $I_b$ ) from the bipolar transistor ( $h_{FE}$ ) using  $I_b = \frac{I_{PK}}{h_{FE}}$ , and select the smaller  $R_b$  value than  $R_b = \frac{V_{OUT} - 0.7}{I_b} - \frac{0.4}{|I_{EXTH}|}$  \*1.

A small  $R_b$  value can increase the output current, but the efficiency decreases. Since a current may flow on the pulse and the voltage may drop due to wiring resistance or other factors in the actual circuit, therefore the optimum  $R_b$  value should be determined by experiment.

Connecting the speed-up capacitor ( $C_b$ ) in parallel with the  $R_b$  resistance as shown in **Figure 19**, decreases switching loss and improves the efficiency.

The  $C_b$  value is calculated according to  $C_b \leq \frac{1}{2\pi \cdot R_b \cdot f_{osc} \cdot 0.7}$ .

Select a  $C_b$  value after performing sufficient evaluation since the optimum  $C_b$  value differs depending upon the characteristics of the bipolar transistor.

\*1. For E, G, J, K, L, M, P and Q type,  $R_b = \frac{V_{DD} - 0.7}{I_b} - \frac{0.4}{|I_{EXTH}|}$ .

**5. V<sub>DD</sub> / V<sub>OUT</sub> Separate Type (For E, G, J, K, L, M, P and Q Types)**

The E, G, J, K, L, M, P and Q types provides separate internal circuit power supply (V<sub>DD</sub> pin) and output voltage setting pin (V<sub>OUT</sub> pin) in the IC, making it ideal for the following applications.

- (1) When changing the output voltage with external resistance.
- (2) When outputting a high voltage such as +15 V or +20 V.

Choose the products in the **Table 29** according to the applications (1) or (2) above.

**Table 29**

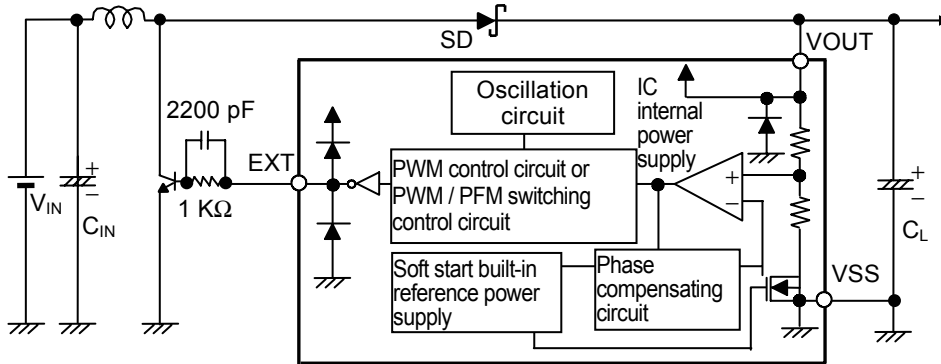
Output Voltage (V <sub>CC</sub> )	1.8 V ≤ V <sub>CC</sub> < 5 V	5 V ≤ V <sub>CC</sub>	Reference Circuit
S-835xx18	Yes	Yes	Application circuit 1 (Figure 26)
S-835xx50	–	Yes	Application circuit 1 (Figure 26)
Connection to VDD pin	V <sub>IN</sub> or V <sub>CC</sub>	V <sub>IN</sub>	–

- Cautions**
1. This IC starts a step-up operation at V<sub>DD</sub> = 0.8 V, but set 1.8 ≤ V<sub>DD</sub> ≤ 10 V to stabilize the output voltage and frequency of the oscillator. (Input a voltage of 1.8 V or more at the VDD pin for all products with a setting less than 1.9 V.) An input voltage of 1.8 V or more at the VDD pin allows connection of the VDD pin to either the input voltage V<sub>IN</sub> pin or output V<sub>OUT</sub> pin.
  2. Choose external resistors R<sub>A</sub> and R<sub>B</sub> so as to not affect the output voltage, considering that there is impedance between the V<sub>OUT</sub> pin and VSS pin in the IC chip. The internal resistance between the V<sub>OUT</sub> pin and VSS pin is as follows :
    - (1) S-835xx18 : 2.1 to 14.8 MΩ
    - (2) S-835xx20 : 1.4 to 14.8 MΩ
    - (3) S-835xx30 : 1.4 to 14.2 MΩ
    - (4) S-835xx50 : 1.4 to 12.1 MΩ
  3. Attach a capacitor (C<sub>C</sub>) in parallel to the R<sub>A</sub> resistance when an unstable event such as oscillation of the output voltage occurs. Calculate C<sub>C</sub> using the following equation :

$$C_c [F] = \frac{1}{2 \cdot \pi \cdot R_A \cdot 20 \text{ kHz}}$$

■ Standard Circuits

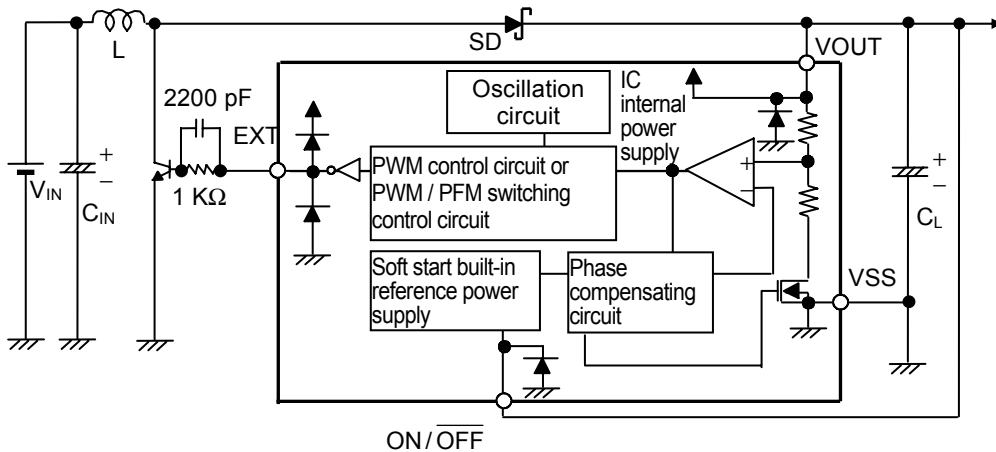
- (1) S-8357BxxMA, S-8357BxxUA, S-8358BxxMA, S-8358BxxUA



Remark The power supply for the IC chip is from the VOUT pin.

Figure 20

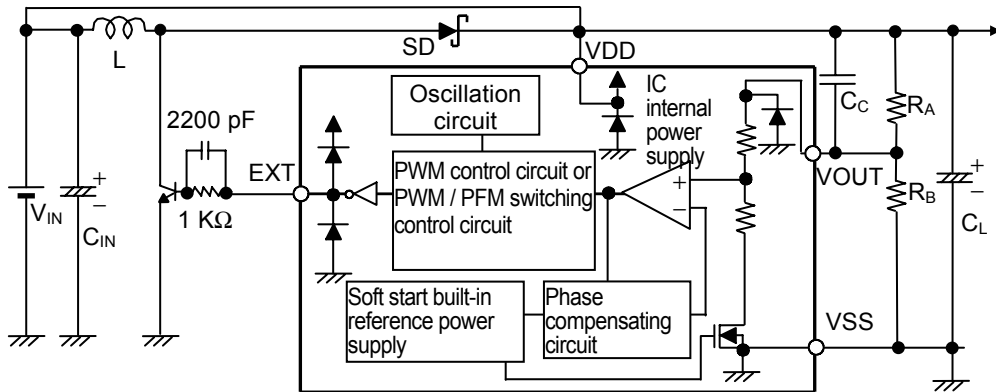
- (2) S-8357BxxMC, S-8357FxxMC / BD, S-8357HxxMC / BD, S-8357NxxMC / BD, S-8358BxxMC, S-8358FxxMC / BD, S-8358HxxMC / BD, S-8358NxxMC / BD



Remark The power supply for the IC chip is from the VOUT pin.

Figure 21

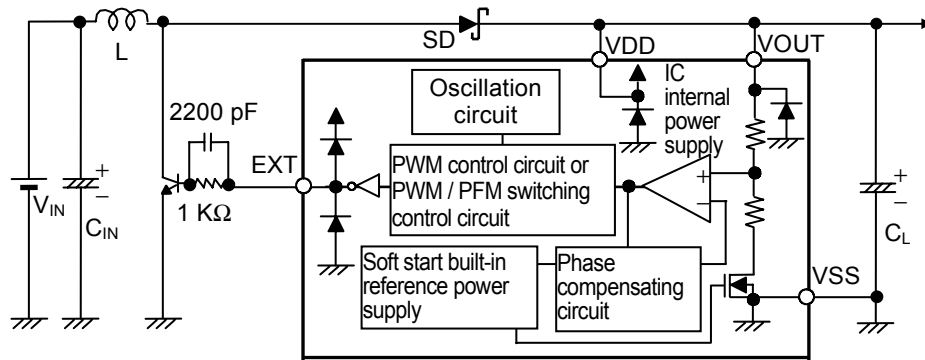
- (3) S-8357ExxMC, S-8357GxxMC / BD, S-8357JxxMC / BD, S-8357PxxMC / BD, S-8358ExxMC, S-8358GxxMC / BD, S-8358JxxMC / BD, S-8358PxxMC / BD



Remark The power supply for the IC chip is from the VOUT pin.

Figure 22

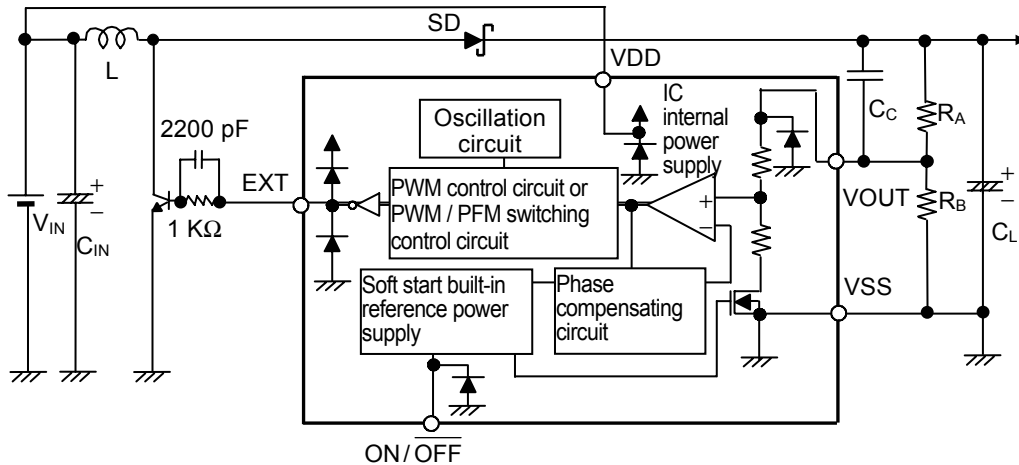
- (4) S-8357ExxMC, S-8357GxxMC / BD, S-8357JxxMC / BD, S-8358ExxMC, S-8358GxxMC / BD, S-8358JxxMC / BD



**Remark** The power supply for the IC chip is from the VOUT pin.

**Figure 23**

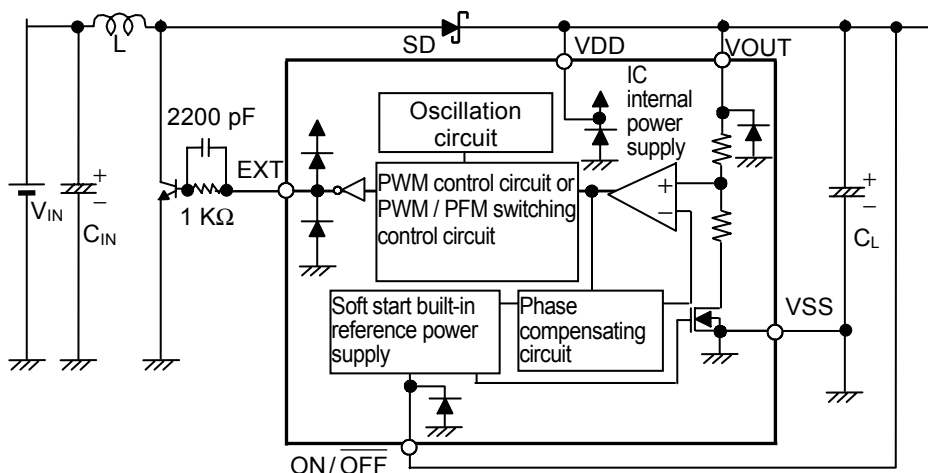
- (5) S-8355KxxMC / BD, S-8355LxxMC / BD, S-8355MxxMC / BD, S-8355QxxMC / BD, S-8356KxxMC / BD, S-8356LxxMC / BD, S-8356MxxMC / BD, S-8356QxxMC / BD



**Remark** The power supply for the IC chip is from the VOUT pin.

**Figure 24**

- (6) S-8355KxxMC / BD, S-8355LxxMC / BD, S-8355MxxMC / BD, S-8356KxxMC / BD, S-8356LxxMC / BD, S-8356MxxMC / BD



**Remark** The power supply for the IC chip is from the VOUT pin.

**Figure 25**

**Caution** The above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.



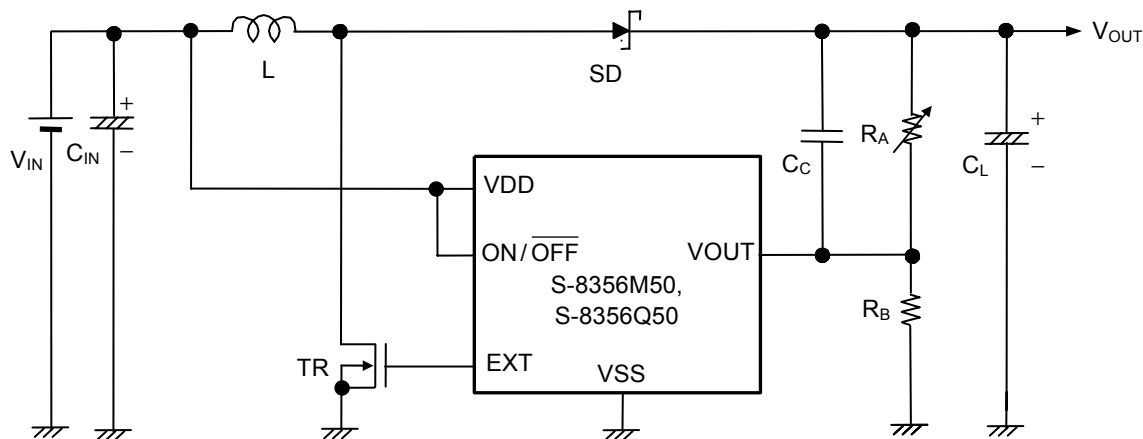
## ■ Precautions

- Mount external capacitors, the diode, and the coil as close as possible to the IC.
- Characteristics ripple voltage and spike noise occur in IC containing switching regulators. Moreover rush current flows at the time of a power supply injection. Because these largely depend on the coil, the capacitor and impedance of power supply used, fully check them using an actually mounted model.
- Make sure that the dissipation of the switching transistor (especially at a high temperature) does not exceed the allowable power dissipation of the package.
- The performance of this IC varies depending on the design of the PCB patterns, peripheral circuits and external parts. Thoroughly test all settings with your device. Also, try to use the recommended external parts. If not, contact an SII sales person.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

■ **Application Circuits**

1. **LCD Power Supply**

The following example is an application power supply circuit (15 V / 20 V output) to drive an LCD panel, and its characteristics.



**Figure 26 Power Supply Circuit Example for LCD**

**Table 30**

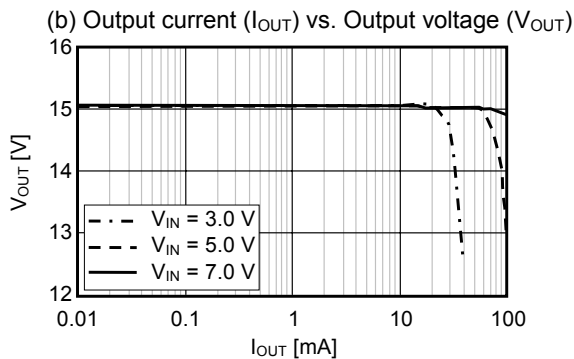
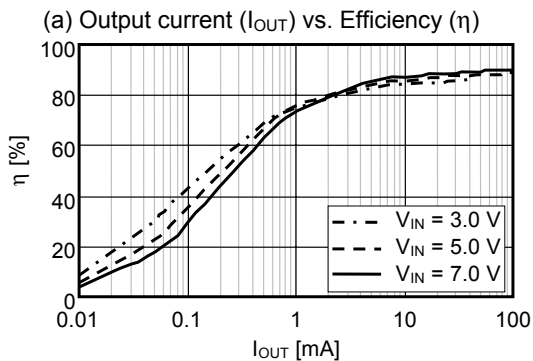
Condition	Output Voltage	IC	L Type Name	TR Type Name	SD Type Name	C <sub>L</sub>	R <sub>a</sub>	R <sub>b</sub>	C <sub>c</sub>
1	15 V	S-8356M50	CDRH5D18-220	MCH3405	MA2Z748	F93 (20 V, 10 μF)	580 kΩ	300 kΩ	15 pF
2	20 V	S-8356M50	CDRH5D18-220	FDN337N	MA729	F93 (25 V, 10 μF)	575 kΩ	200 kΩ	15 pF
3	10 V	S-8356Q50	CDRH5D18-100	MCH3405	MA2Z748	F93 (20 V, 10 μF)	560 kΩ	560 kΩ	15 pF

**Caution** The above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.

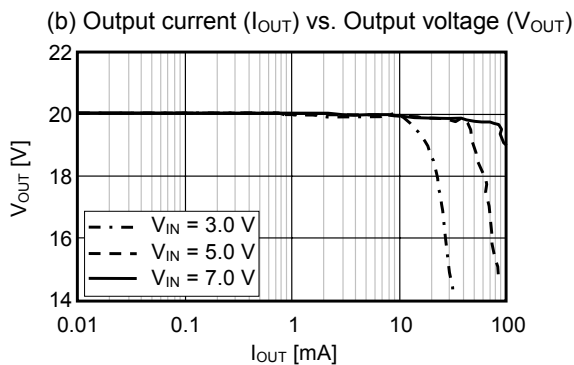
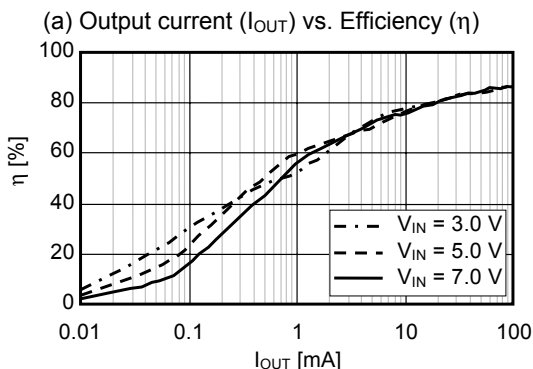
## 2. Output Characteristics of The Power Supply for LCD

The data of the step-up characteristics (a) Output current ( $I_{OUT}$ ) vs. Efficiency ( $\eta$ ) characteristics, (b) Output current ( $I_{OUT}$ ) vs. Output voltage ( $V_{OUT}$ ) characteristics under conditions of 1 to 3 in **Table 30** is shown below.

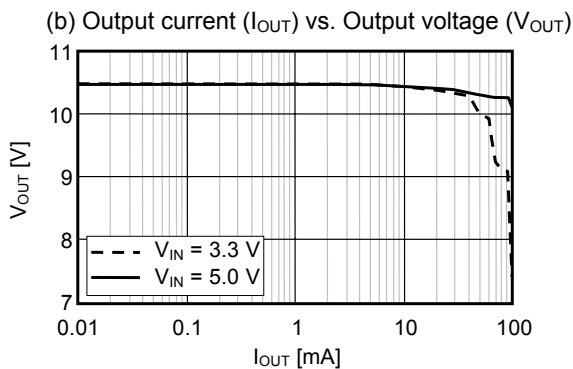
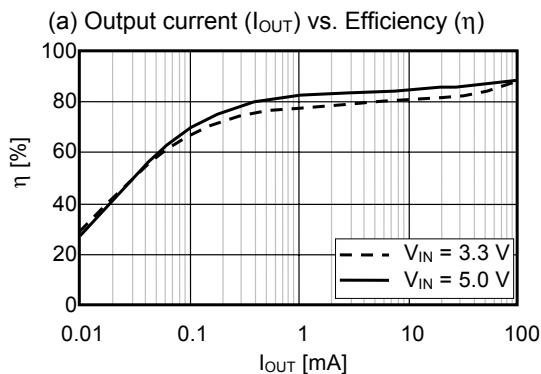
### Condition 1



### Condition 2

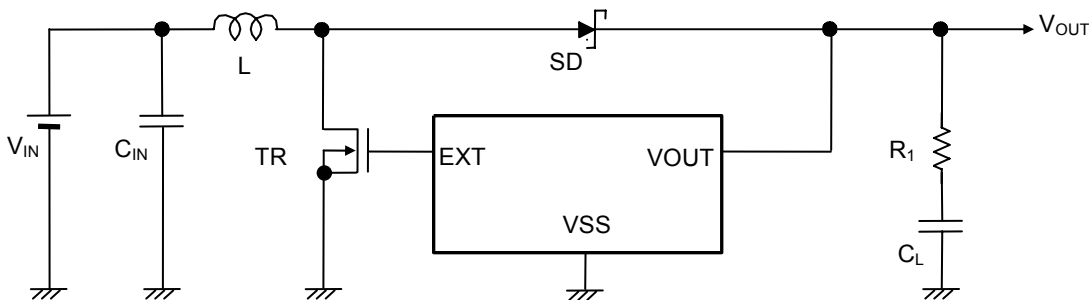


### Condition 3



**3. Using Ceramic Capacitor Example**

When using small  $R_{ESR}$  parts such as ceramic capacitors for the output capacitance, mount a resistor ( $R_1$ ) corresponding to the  $R_{ESR}$  in series with the ceramic capacitor ( $C_L$ ) as shown in **Figure 27**.  $R_1$  differs depending on “L” value, the capacitance, the wiring, and the application (output load). The following example shows a circuit using  $R_1 = 100\text{ m}\Omega$ , output voltage = 3.3 V, output load = 500 mA and its characteristics.



**Figure 27 Using Ceramic Capacitor Circuit Example**

**Table 31**

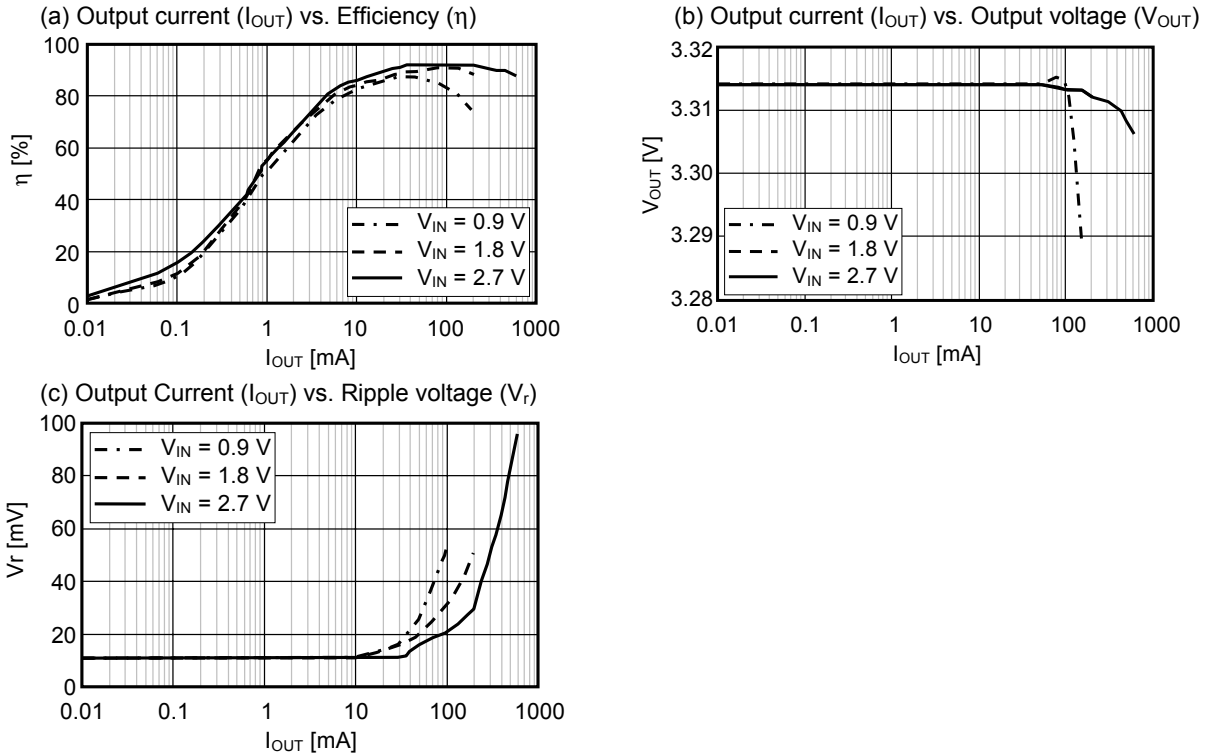
Condition	IC	L Type Name	TR Type Name	SD Type Name	SD Type Name	$R_1$
1	S-8357F33	CDRH6D28-220	FDN335N	M1FH3	10 $\mu\text{F} \times 2$	100 m $\Omega$
2	S-8358B50	CDRH6D28-470	FDN335N	M1FH3	10 $\mu\text{F} \times 2$	100 m $\Omega$
3	S-8357N33	CDRH6D28-100	FDN335N	M1FH3	10 $\mu\text{F} \times 2$	100 m $\Omega$

**Caution** The above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.

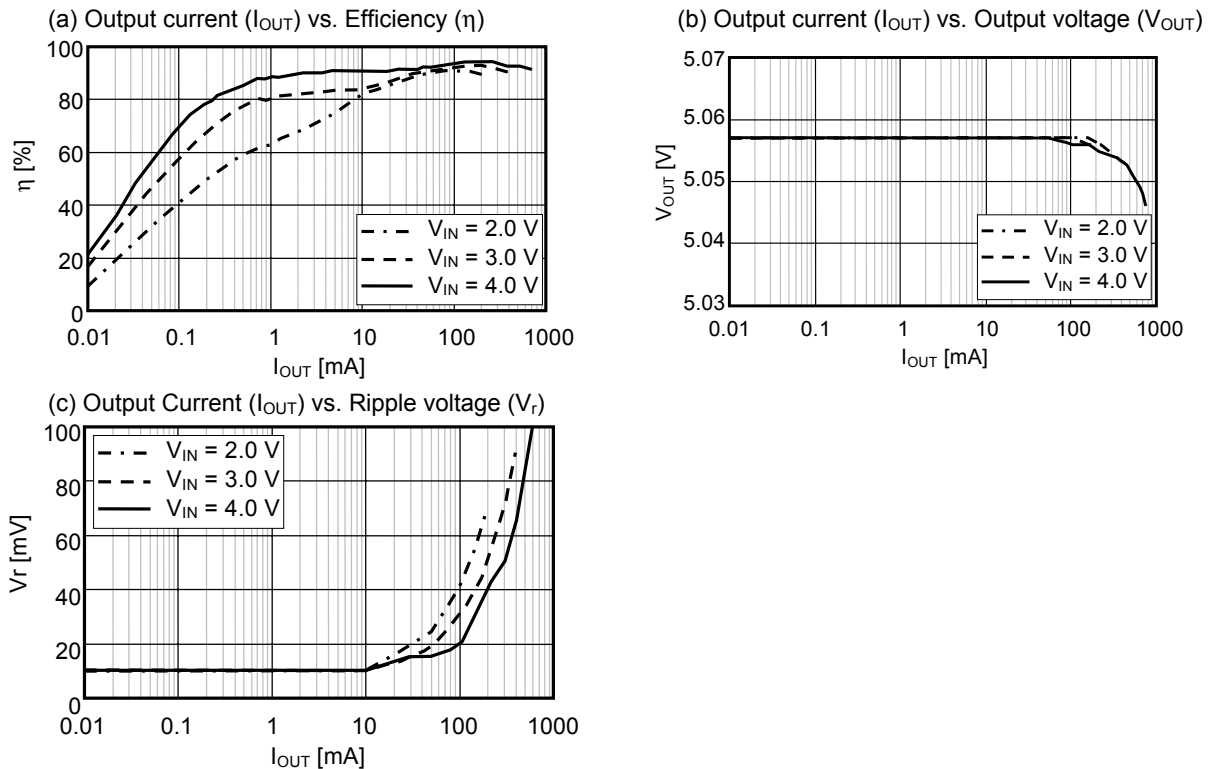
#### 4. Output Characteristics of The Using Ceramic Capacitor Circuit Example

The data of the step-up characteristics (a) Output current ( $I_{OUT}$ ) vs. Efficiency ( $\eta$ ) characteristics, (b) Output current ( $I_{OUT}$ ) vs. Output voltage ( $V_{OUT}$ ) characteristics, (c) Output Current ( $I_{OUT}$ ) vs. Ripple voltage ( $V_r$ ) under conditions of 1 to 3 in Table 31 is shown below.

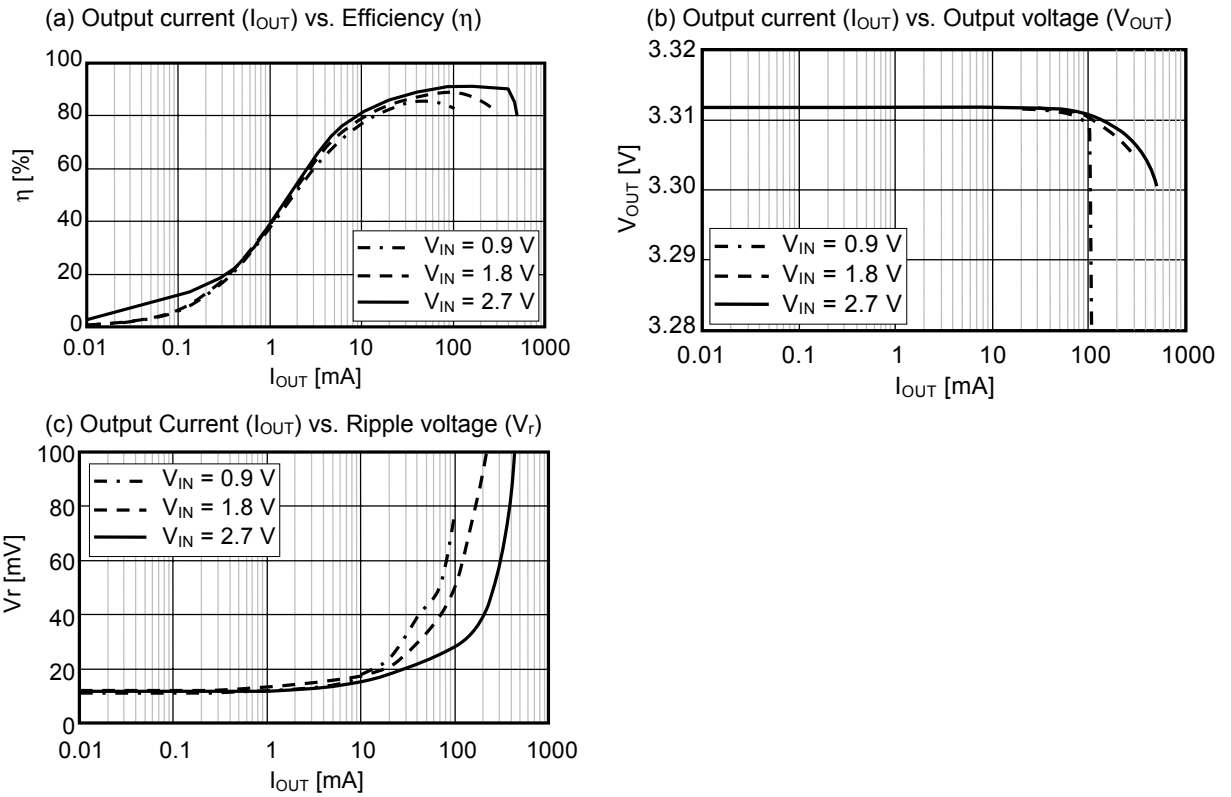
##### Condition 1



##### Condition 2



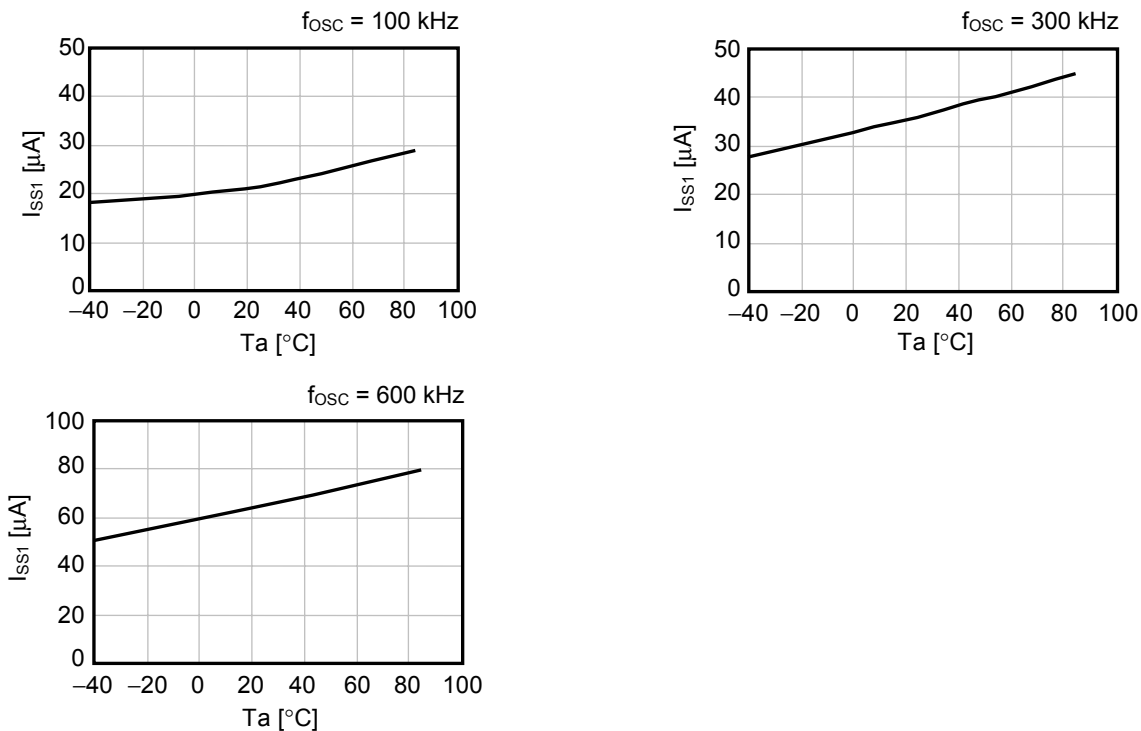
**Condition 3**



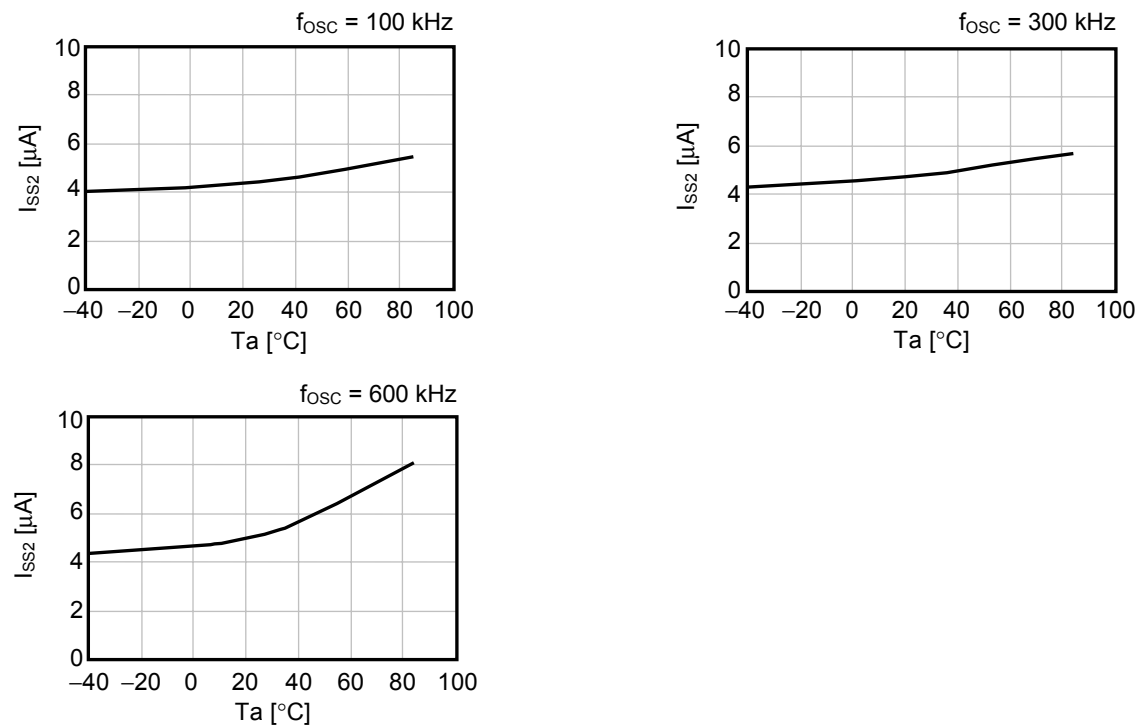
## ■ Characteristics (Typical Data)

### 1. Example of Major Temperature characteristics (Ta = -40 to +85 °C)

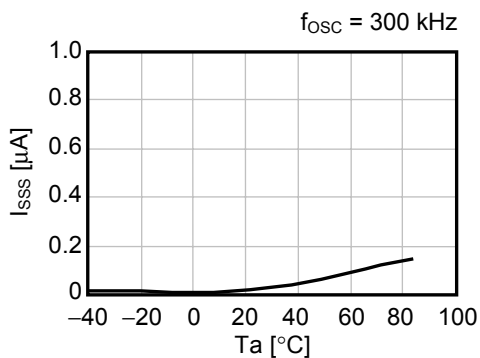
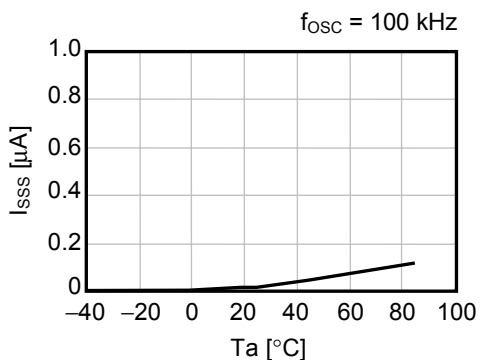
#### (1) Current Consumption 1 (I<sub>SS1</sub>) vs. Temperature (Ta) (V<sub>OUT</sub> = 3.3 V)



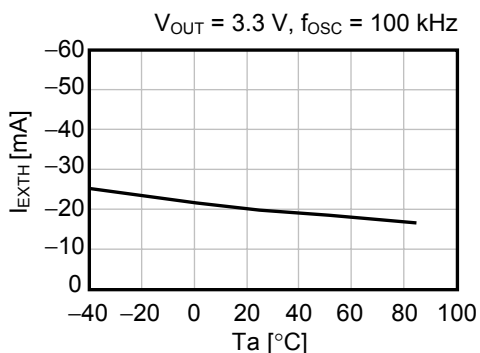
#### (2) Current Consumption 2 (I<sub>SS2</sub>) vs. Temperature (Ta) (V<sub>OUT</sub> = 3.3 V)



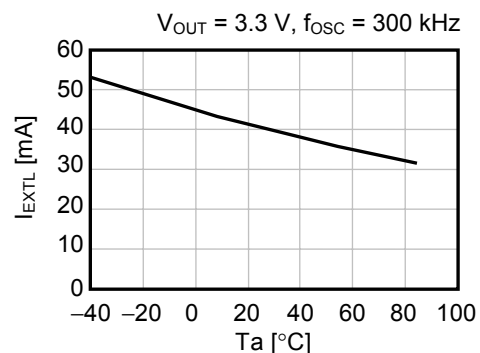
**(3) Current Consumption at Shutdown ( $I_{SS}$ ) vs. Temperature ( $T_a$ )**



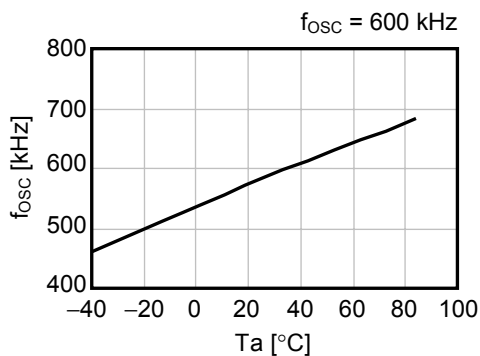
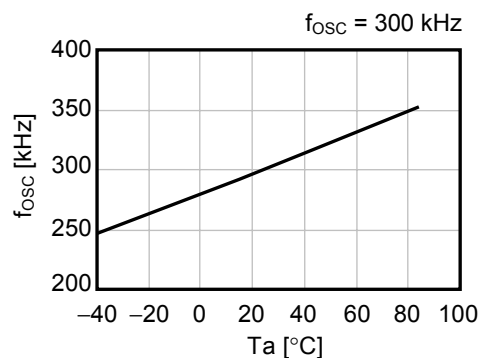
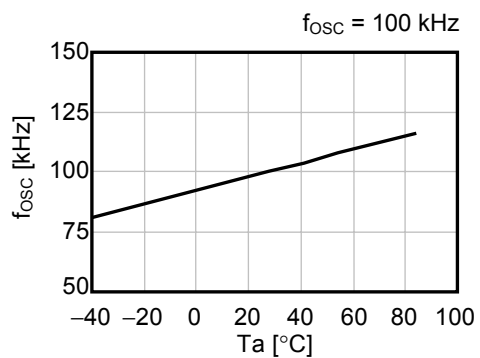
**(4) EXT Pin Output Current "H" ( $I_{EXTH}$ ) vs. Temperature ( $T_a$ )**



**(5) EXT Pin Output Current "L" ( $I_{EXTL}$ ) vs. Temperature ( $T_a$ )**

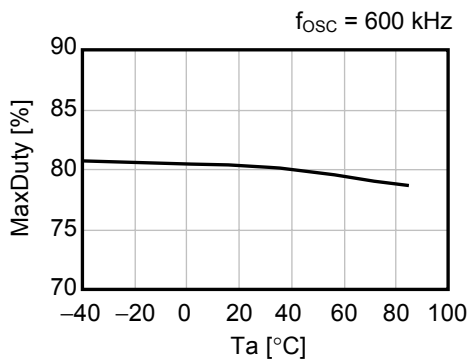
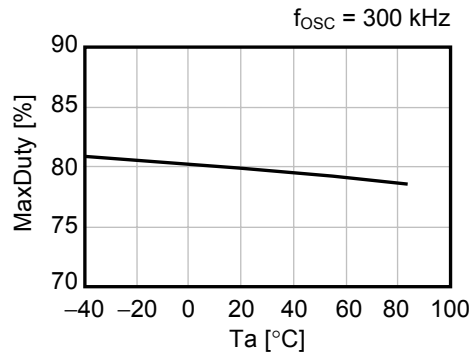
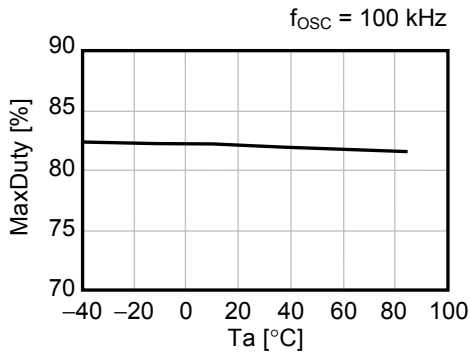


**(6) Oscillation Frequency ( $f_{OSC}$ ) vs. Temperature ( $T_a$ ) ( $V_{OUT} = 3.3 \text{ V}$ )**

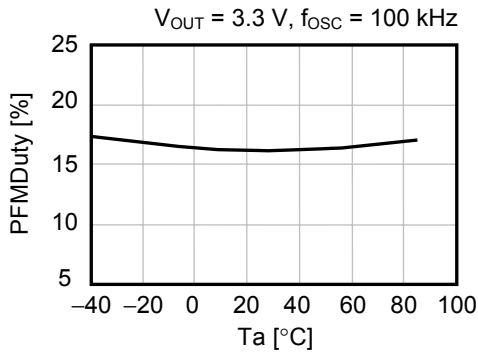




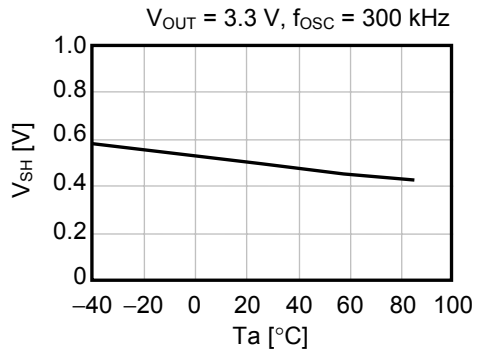
(7) Maximum Duty Ratio (MaxDuty) vs. Temperature (Ta) (V<sub>OUT</sub> = 3.3 V)



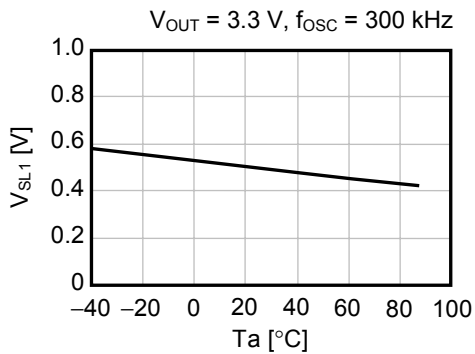
(8) PWM / PFM Switching Duty Ratio (PFMDuty) vs. Temperature (Ta) (S-8356/58 Series)



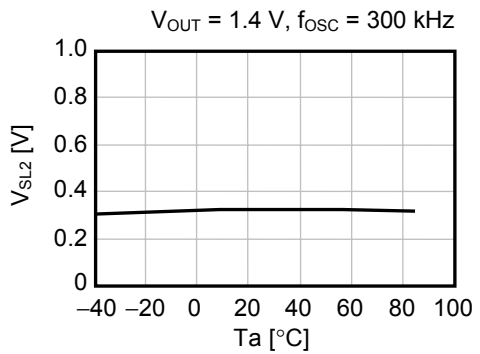
(9) ON/OFF Pin Input Voltage "H" (V<sub>SH</sub>) vs. Temperature (Ta)



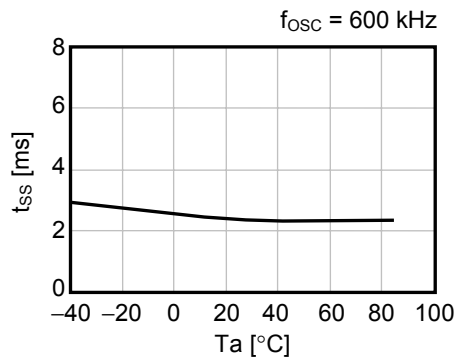
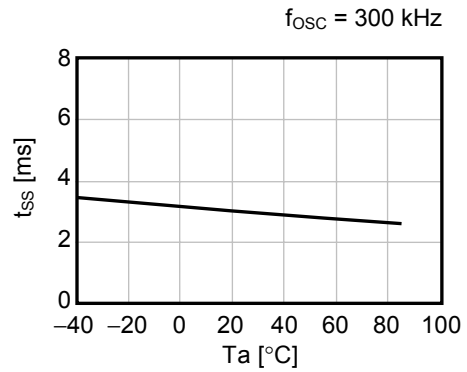
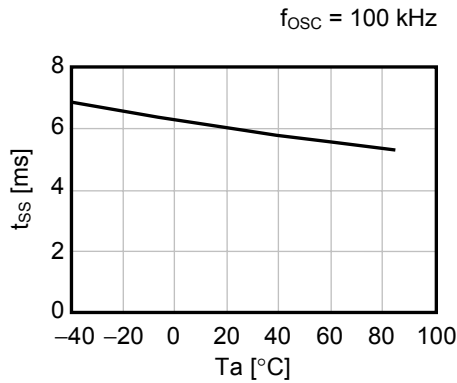
(10) ON/OFF Pin Input Voltage "L" 1 (V<sub>SL1</sub>) vs. Temperature (Ta)



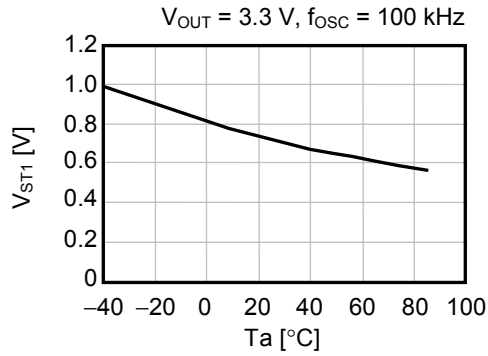
(11) ON/OFF Pin Input Voltage "L" 2 (V<sub>SL2</sub>) vs. Temperature (Ta)



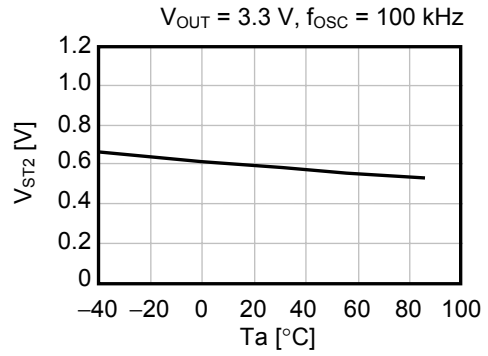
**(12) Soft Start Time ( $t_{SS}$ ) vs. Temperature ( $T_a$ ) ( $V_{OUT} = 3.3\text{ V}$ )**



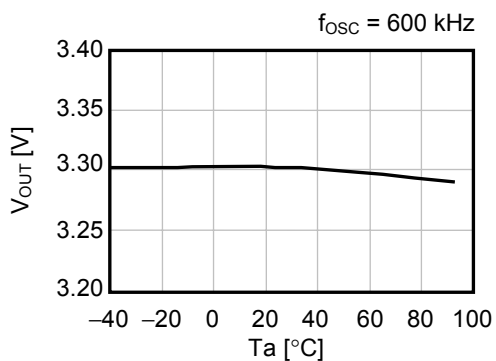
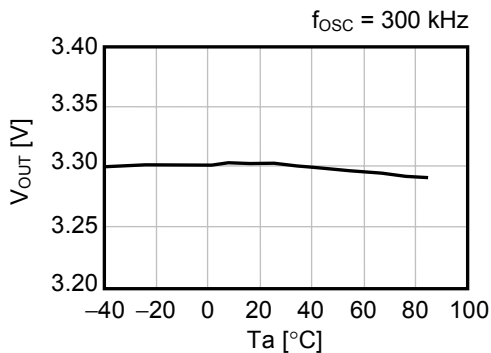
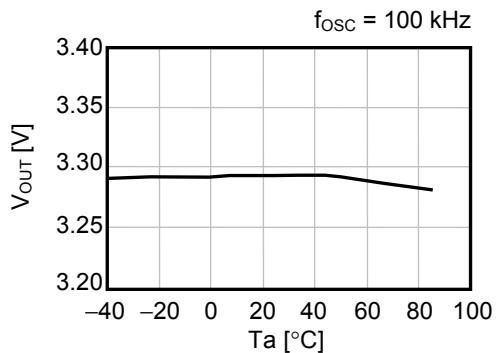
**(13) Operation Start Voltage ( $V_{ST1}$ ) vs. Temperature ( $T_a$ )**



**(14) Oscillation Start Voltage ( $V_{ST2}$ ) vs. Temperature ( $T_a$ )**

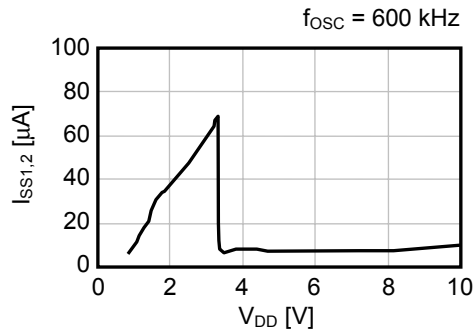
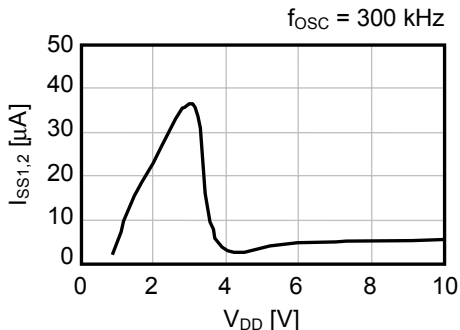


(15) Output Voltage ( $V_{OUT}$ ) vs. Temperature ( $T_a$ ) ( $V_{OUT} = 3.3\text{ V}$ )

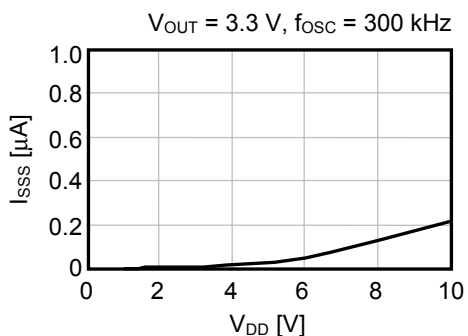


**2. Examples of Major Power Supply Dependence Characteristics (Ta = 25 °C)**

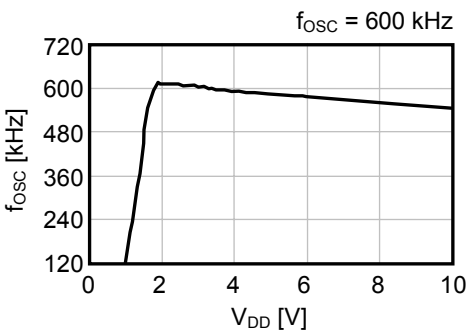
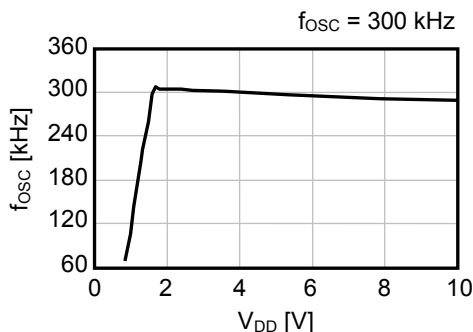
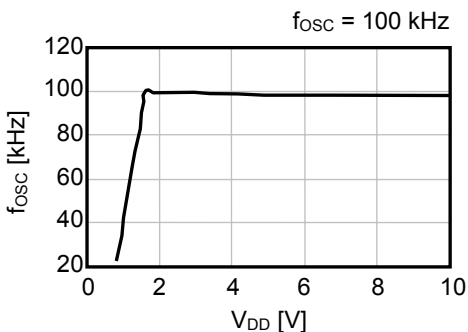
(1) Current Consumption 1 (I<sub>SS1</sub>) vs. Power Supply Voltage (V<sub>DD</sub>), Current Consumption 2 (I<sub>SS2</sub>) vs. Power Supply Voltage (V<sub>DD</sub>)  
 (V<sub>OUT</sub> = 3.3 V)



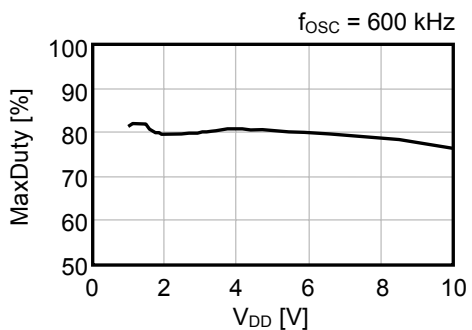
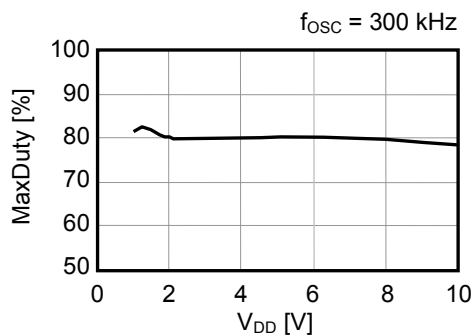
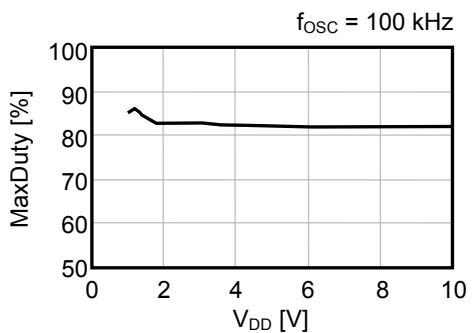
(2) Current Consumption at Shutdown (I<sub>SSS</sub>) vs. Power Supply Voltage (V<sub>DD</sub>)



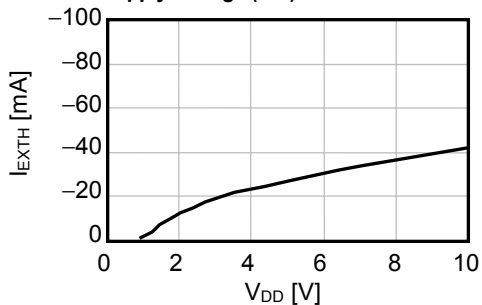
(3) Oscillation Frequency (f<sub>osc</sub>) vs. Power Supply Voltage (V<sub>DD</sub>)



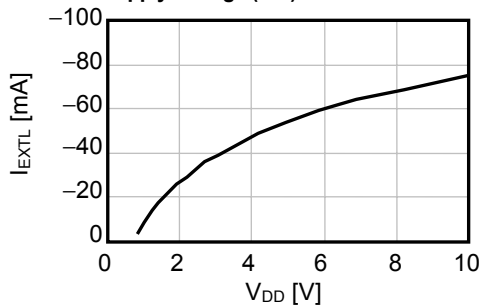
**(4) Maximum Duty Ratio (MaxDuty) vs. Power Supply Voltage ( $V_{DD}$ )**



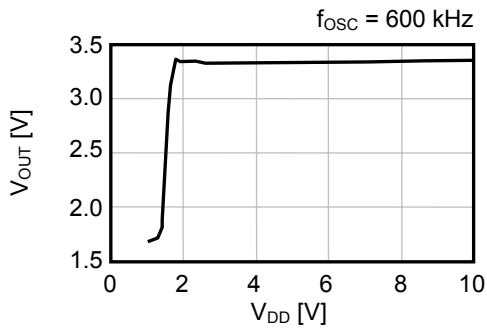
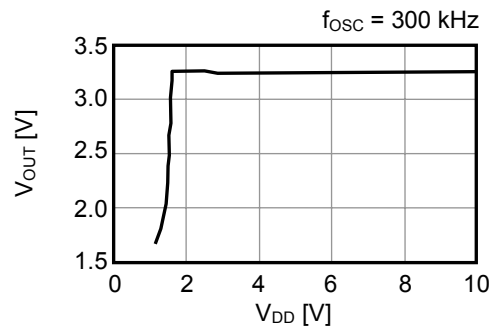
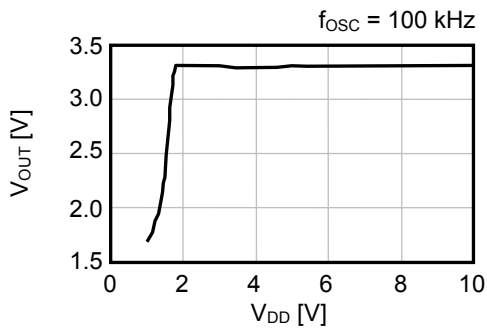
**(5) EXT Pin Output Current "H" ( $I_{EXTH}$ ) vs. Power Supply Voltage ( $V_{DD}$ )**



**(6) EXT Pin Output Current "L" ( $I_{EXTL}$ ) vs. Power Supply Voltage ( $V_{DD}$ )**

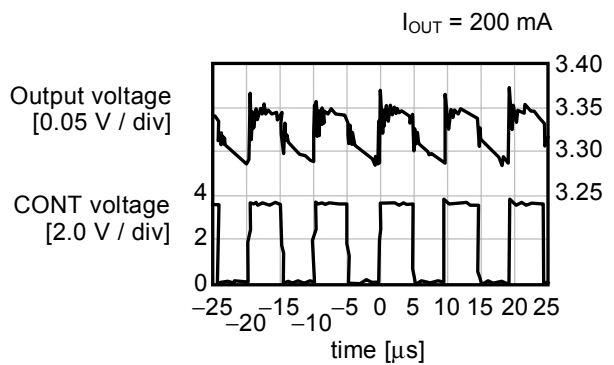
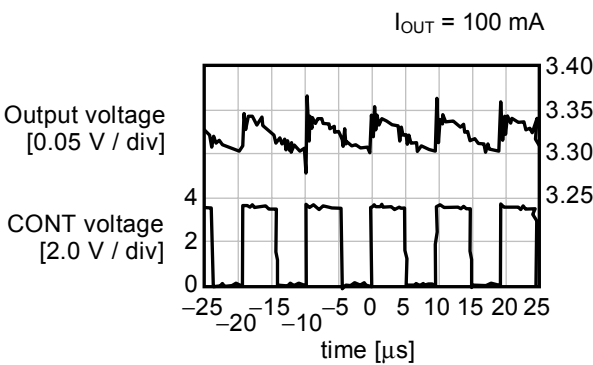
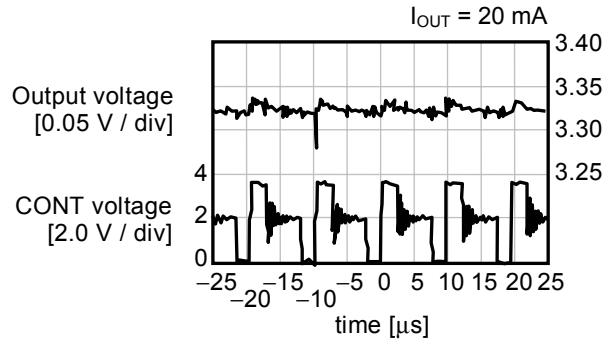
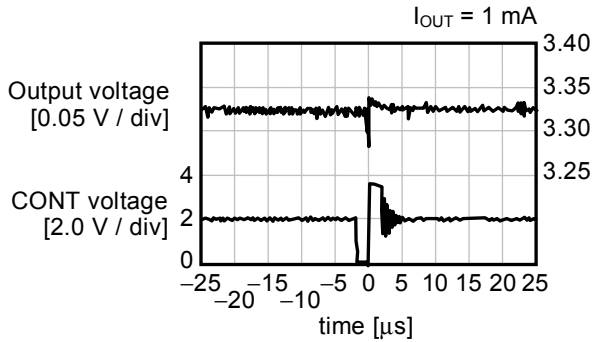


(7) Output Voltage ( $V_{OUT}$ ) vs. Power Supply Voltage ( $V_{DD}$ ) ( $V_{DD}$  Separate Type,  $V_{OUT} = 3.3\text{ V}$ ,  $V_{IN} = 1.98\text{ V}$ ,  $I_{OUT} = 66\text{ mA}$ )

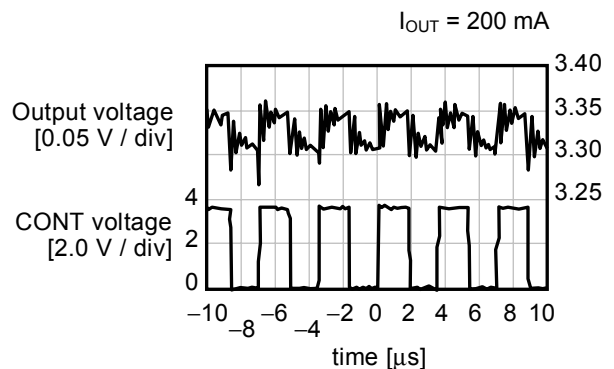
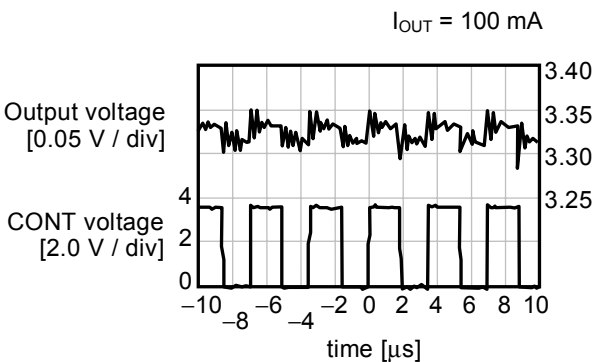
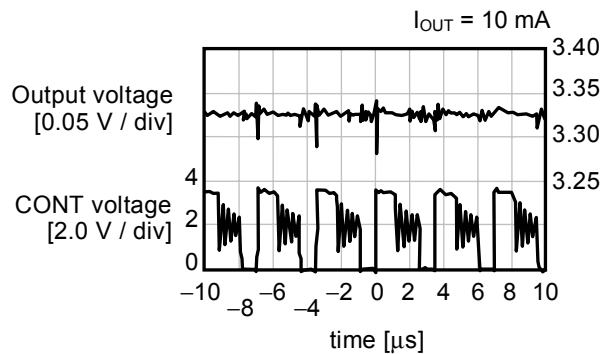
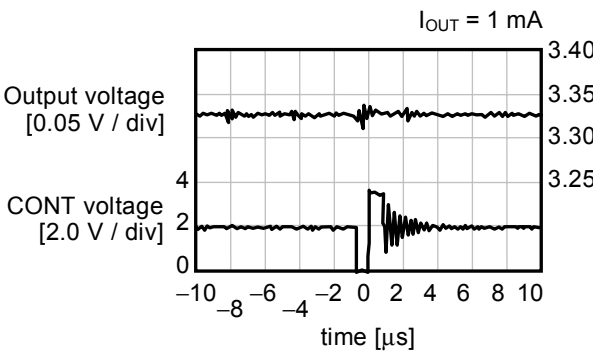


**3. Output Waveforms**

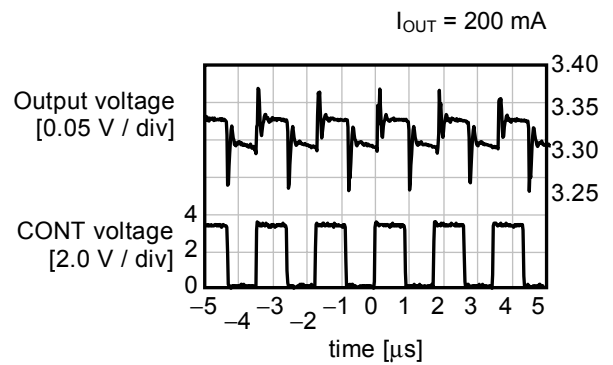
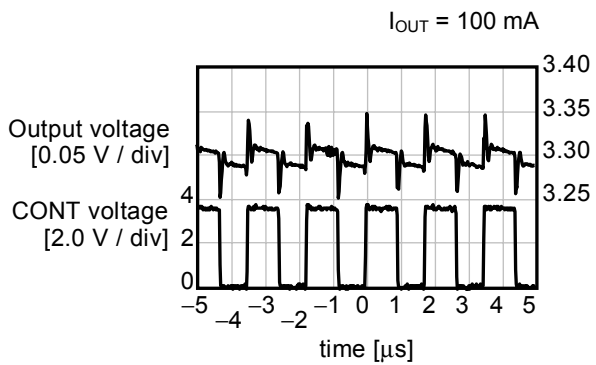
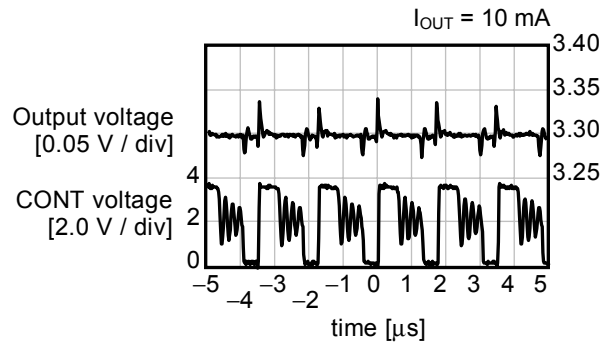
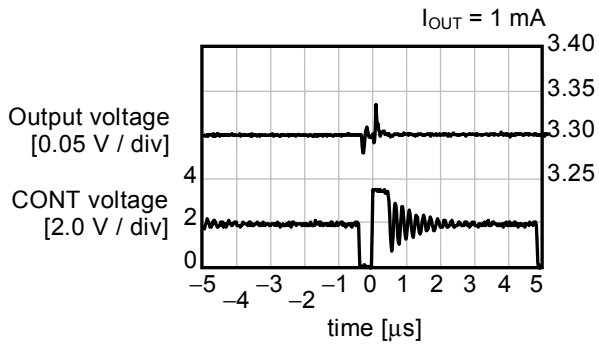
**(1) S-8358B33MC**



**(2) S-8358F33MC**



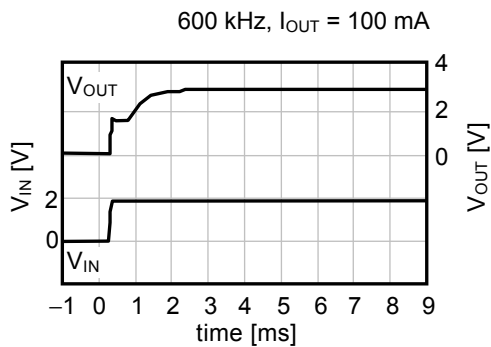
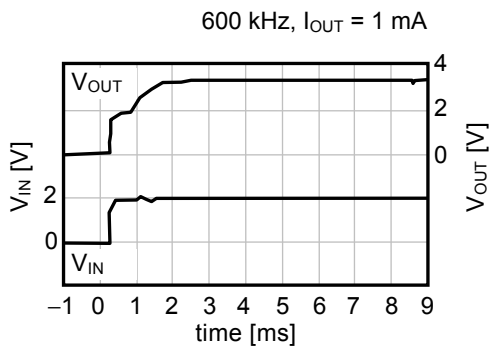
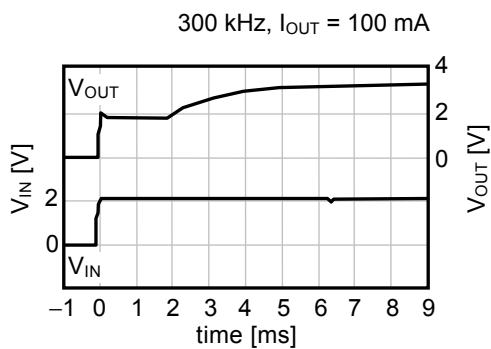
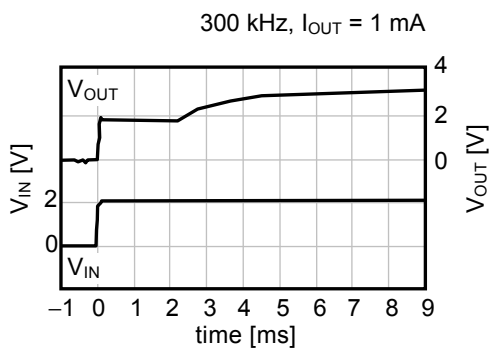
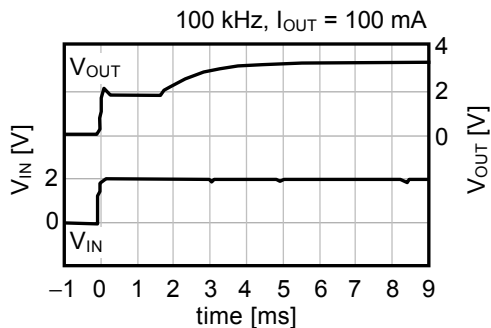
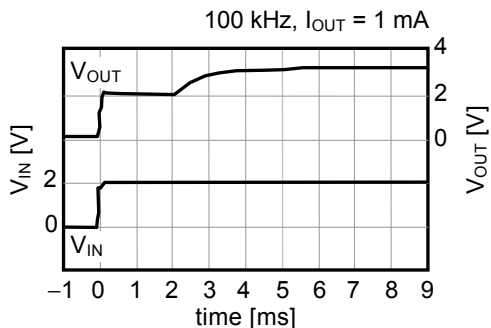
(3) S-8358N33MC



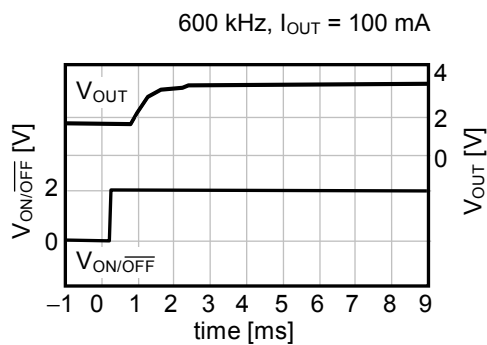
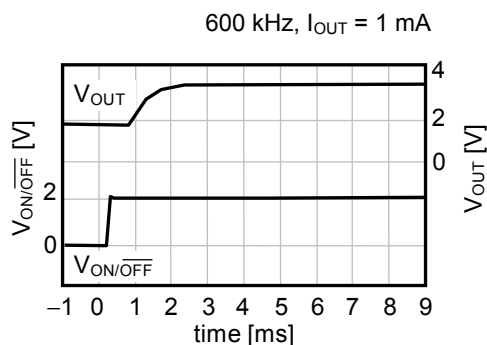
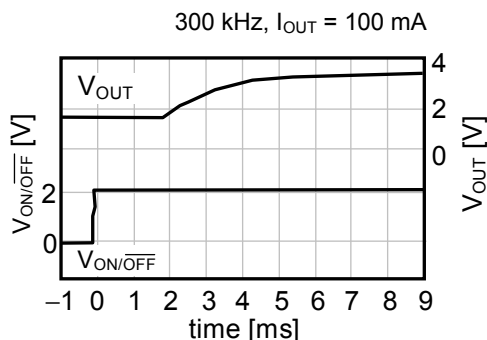
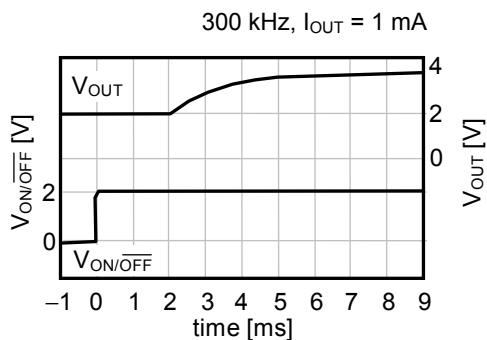
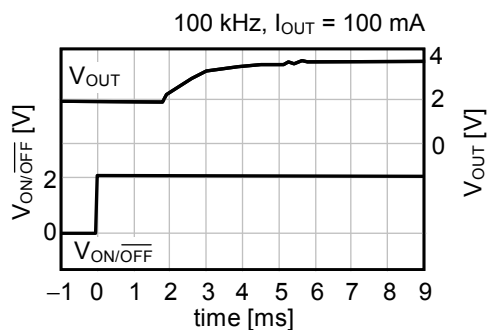
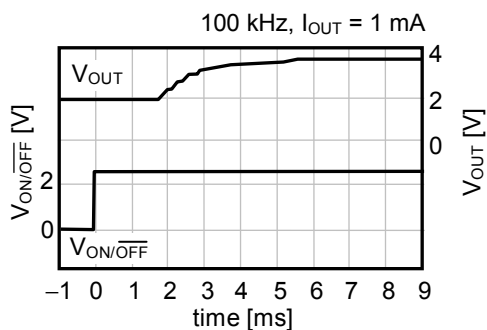


4. Examples of Transient Response Characteristics

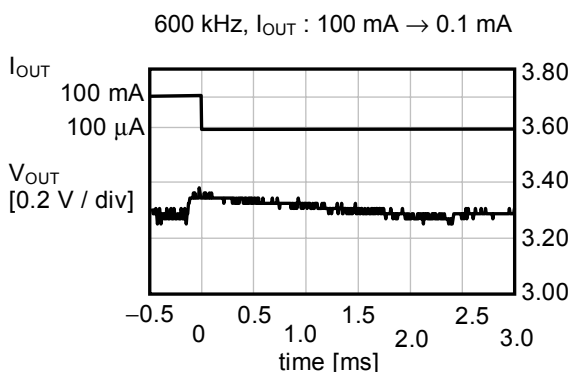
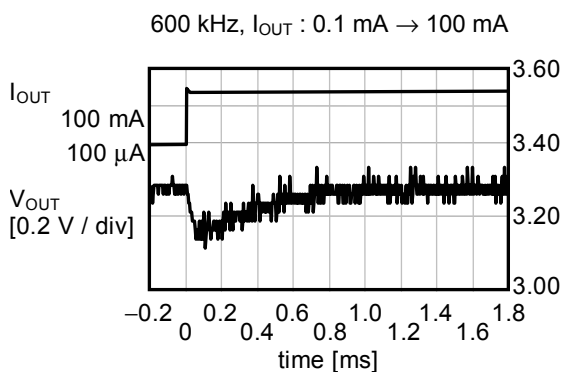
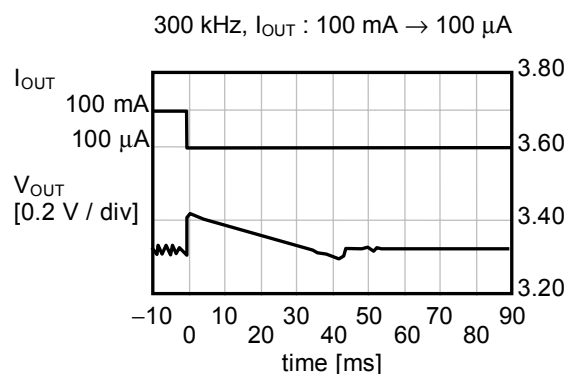
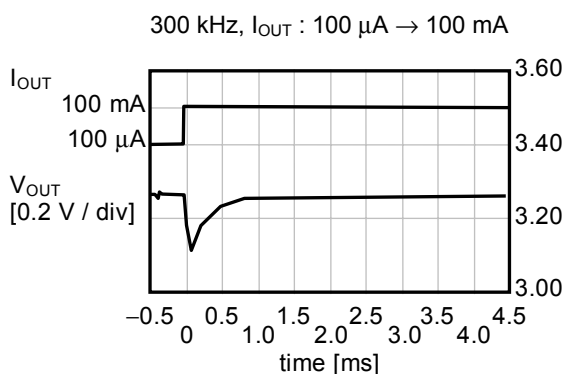
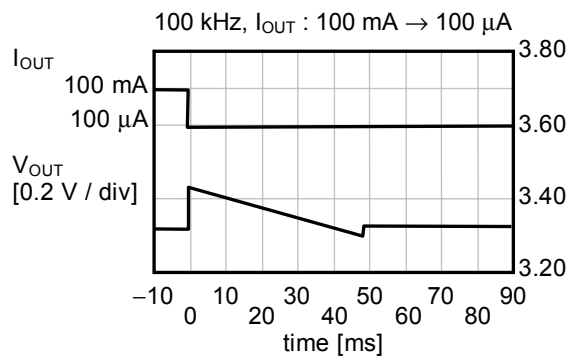
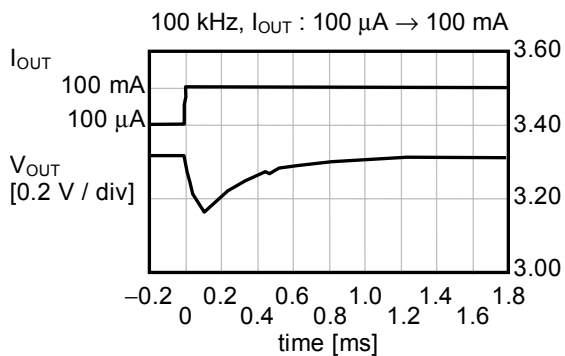
(1) Power-On ( $V_{IN} : 0\text{ V} \rightarrow 2\text{ V}$ )



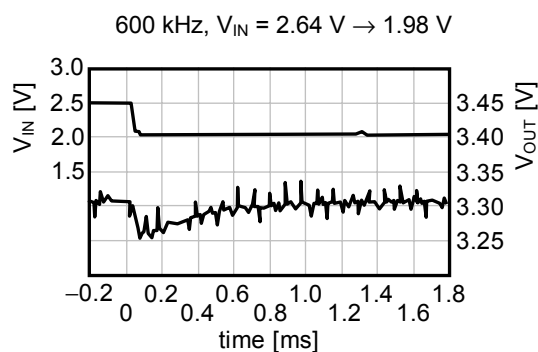
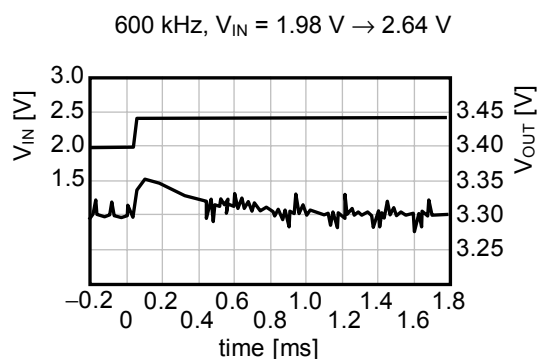
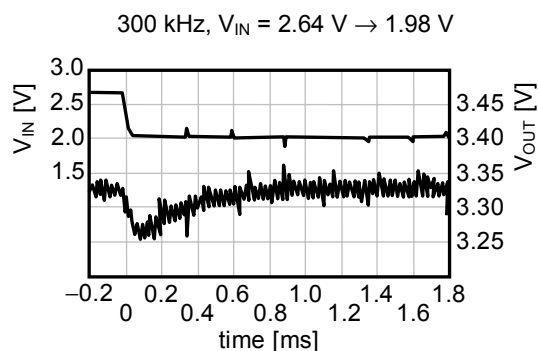
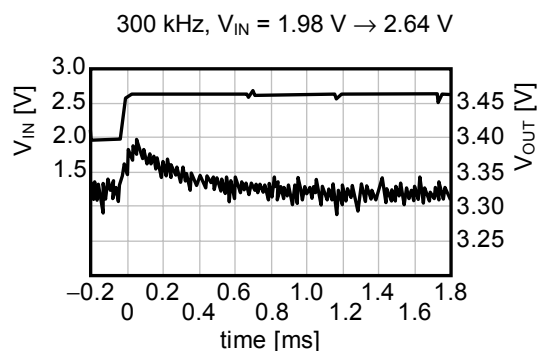
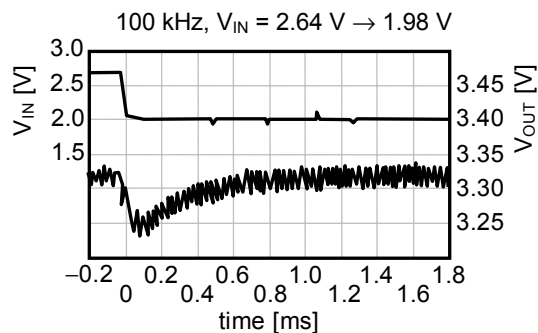
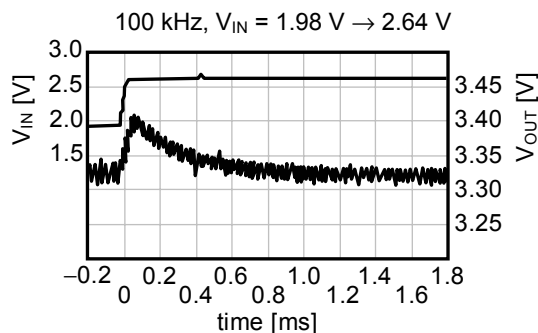
(2) ON/OFF Pin Response ( $V_{ON/OFF} : 0\text{ V} \rightarrow 2.0\text{ V}$ )



**(3) Load Fluctuations**



**(4) Input Voltage Fluctuations ( $I_{OUT} = 100 \text{ mA}$ )**



## ■ Reference Data

Use this reference data to choose the external parts. This reference data makes it possible to choose the recommended external part based on the application and characteristics data.

### 1. External Parts for Reference Data

**Table 32 Efficiency vs. Output Current Characteristics and Output Voltage vs. Output Current Characteristics for External**

Condition	Product Name	Oscillation Frequency	Output Voltage	Control System	Inductor	Transistor	Diode	Output capacitor
1	S-8357F33	300 kHz	3.3 V	PWM	CDRH104R-220	S-90N0312SMA	M1FH3	F93 (16 V, 47 μF) × 2
2	S-8357F50	300 kHz	5.0 V	PWM				
3	S-8356M50	300 kHz	5.0 V	PWM/PFM				
4	S-8357B33	100 kHz	3.3 V	PWM	CDRH104R-470	S-90N0442SUA		
5	S-8358B33	100 kHz	3.3 V	PWM/PFM				
6	S-8357B50	100 kHz	5.0 V	PWM				
7	S-8356M50	300 kHz	5.0 V	PWM/PFM	CDRH8D28-220	S-90N0212SMA		F93 (16 V, 47 μF)
8	S-8357B33	100 kHz	3.3 V	PWM	CDRH8D28-470			
9	S-8358B33	100 kHz	3.3 V	PWM/PFM				
10	S-8357B50	100 kHz	5.0 V	PWM			MA2Z748	F92 (6.3 V, 47 μF)
11	S-8357F33	300 kHz	3.3 V	PWM	CXLP120-220			
12	S-8356M50	300 kHz	5.0 V	PWM/PFM				
13	S-8357N33	600 kHz	3.3 V	PWM	CDRH8D28-100		M1FH3	F93 (16 V, 47 μF)
14	S-8357N50	600 kHz	5.0 V	PWM				
15	S-8356Q33	600 kHz	3.3 V	PWM/PFM				
16	S-8356Q50	600 kHz	5.0 V	PWM/PFM				

The properties of the external parts are shown below.

**Table 33 Properties of External Parts**

Component	Product Name	Manufacturer	Characteristics
Inductor	CDRH104R-220	Sumida Corporation	22 $\mu$ H, DCR <sup>*1</sup> = 73 m $\Omega$ , I <sub>MAX.</sub> <sup>*2</sup> = 2.5 A, Component height = 4.0 mm
	CDRH104R-470		47 $\mu$ H, DCR <sup>*1</sup> = 128 m $\Omega$ , I <sub>MAX.</sub> <sup>*2</sup> = 1.9 A, Component height = 4.0 mm
	CDRH8D28-100		10 $\mu$ H, DCR <sup>*1</sup> = 47 m $\Omega$ , I <sub>MAX.</sub> <sup>*2</sup> = 2.7 A, Component height = 3.0 mm
	CDRH8D28-220		22 $\mu$ H, DCR <sup>*1</sup> = 99 m $\Omega$ , I <sub>MAX.</sub> <sup>*2</sup> = 1.8 A, Component height = 3.0 mm
	CDRH8D28-470		47 $\mu$ H, DCR <sup>*1</sup> = 195 m $\Omega$ , I <sub>MAX.</sub> <sup>*2</sup> = 1.25 A, Component height = 3.0 mm
		CXLP120-220	Sumitomo Special Metals Co., Ltd.
Diode	M1FH3	Shindengen Electric Manufacturing Co., Ltd.	V <sub>F</sub> <sup>*3</sup> = 0.3 V, I <sub>F</sub> <sup>*4</sup> = 1.5 A
	MA2Z748	Matsushita Electric Industrial Co., Ltd.	V <sub>F</sub> <sup>*3</sup> = 0.4 V, I <sub>F</sub> <sup>*4</sup> = 0.3 A
Capacitor (Output Capacitance)	F93	Nichicon Corporation	16 V, 47 $\mu$ F
	F92		6.3 V, 47 $\mu$ F
Transistor (Nch FET)	S-90N0212SMA	Seiko Instruments Inc.	V <sub>DSS</sub> <sup>*5</sup> = 20 V max., V <sub>GSS</sub> <sup>*6</sup> = 12 V max., C <sub>ISS</sub> <sup>*7</sup> = 190 pF, R <sub>DS(ON)</sub> <sup>*8</sup> = 0.16 $\Omega$ max. (V <sub>GS</sub> <sup>*9</sup> = 2.5 V, I <sub>D</sub> <sup>*10</sup> = 0.5 A)
	S-90N0312SMA		V <sub>DSS</sub> <sup>*5</sup> = 20 V max., V <sub>GSS</sub> <sup>*6</sup> = 8 V max., C <sub>ISS</sub> <sup>*7</sup> = 170 pF, R <sub>DS(ON)</sub> <sup>*8</sup> = 0.14 $\Omega$ max. (V <sub>GS</sub> <sup>*9</sup> = 2.5 V, I <sub>D</sub> <sup>*10</sup> = 0.5 A)
	S-90N0442SUA		V <sub>DSS</sub> <sup>*5</sup> = 20 V max., V <sub>GSS</sub> <sup>*6</sup> = 8 V max., C <sub>ISS</sub> <sup>*7</sup> = 390 pF, R <sub>DS(ON)</sub> <sup>*8</sup> = 0.07 $\Omega$ max. (V <sub>GS</sub> <sup>*9</sup> = 2.5 V, I <sub>D</sub> <sup>*10</sup> = 2 A)

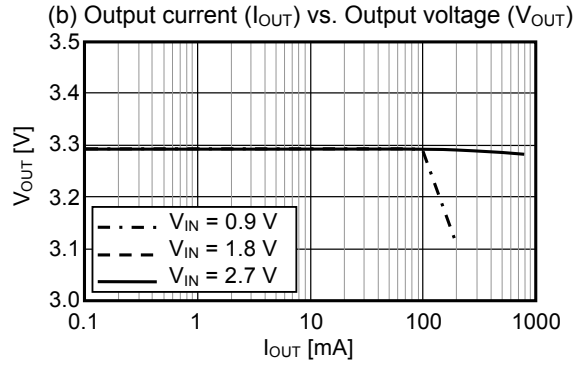
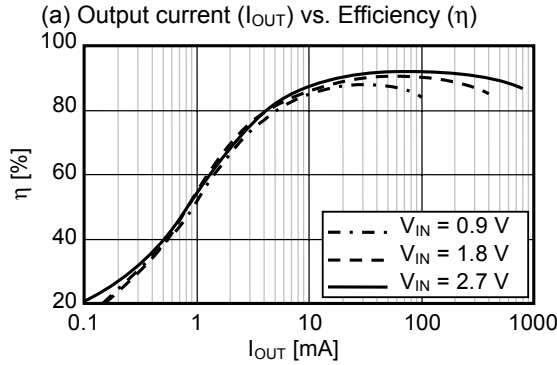
- \*1. Direct current resistance
- \*2. Maximum allowable current
- \*3. Forward voltage
- \*4. Forward current
- \*5. Drain source voltage
- \*6. Gate source voltage
- \*7. Input capacitance
- \*8. Drain source ON-resistance
- \*9. Gate source voltage
- \*10. Drain current

**Caution** The values shown in the characteristics column of Table 33 above are based on the materials provided by each manufacture. However, consider the characteristics of the original materials when using the above products.

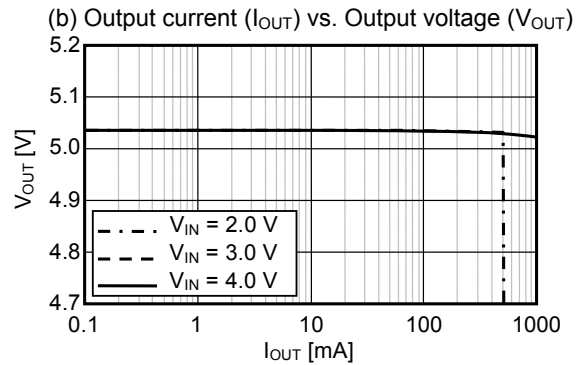
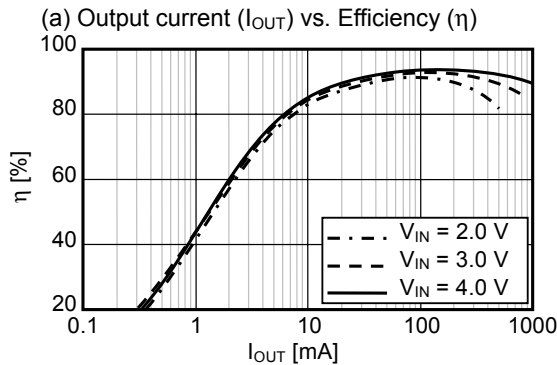
**2. Output Current ( $I_{OUT}$ ) vs. Efficiency ( $\eta$ ) Characteristics, Output Current ( $I_{OUT}$ ) vs. Output Voltage ( $V_{OUT}$ ) Characteristics**

The following shows the actual (a) Output current ( $I_{OUT}$ ) vs. Efficiency ( $\eta$ ) characteristics and (b) Output current ( $I_{OUT}$ ) vs. Output voltage ( $V_{OUT}$ ) characteristics under the conditions of No. 1 to 16 in **Table 32**.

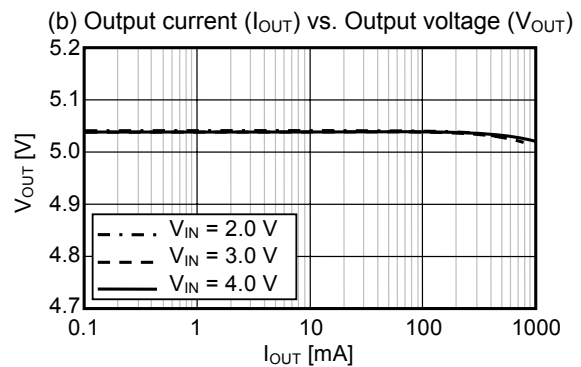
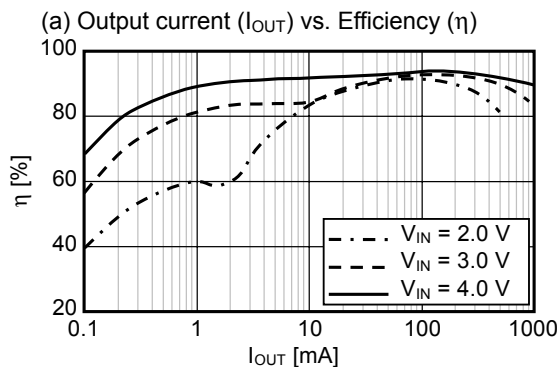
**Condition 1 S-8357F33**



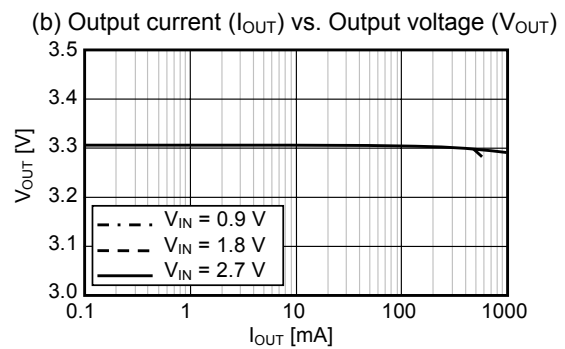
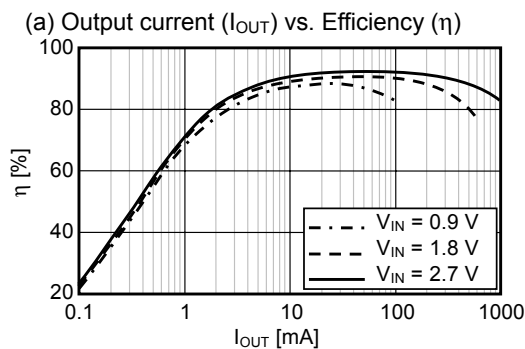
**Condition 2 S-8357F50**



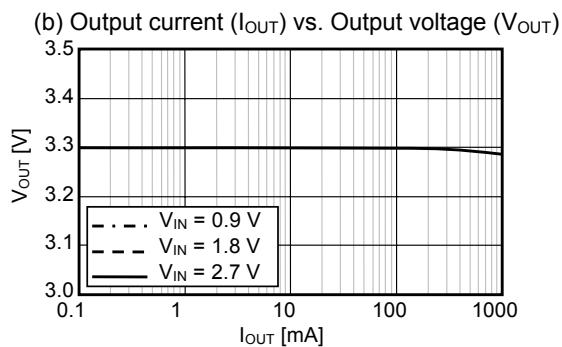
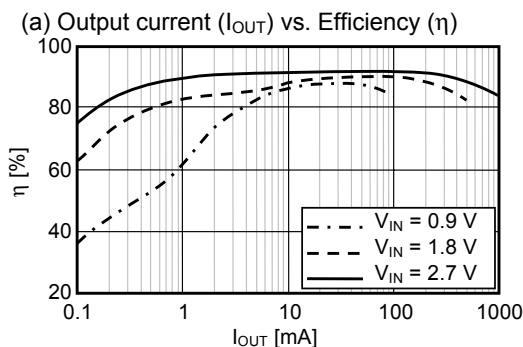
**Condition 3 S-8356M50**



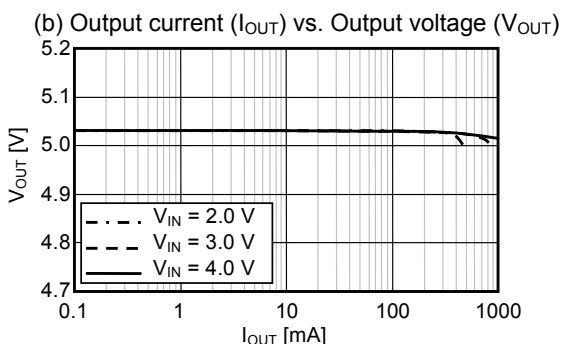
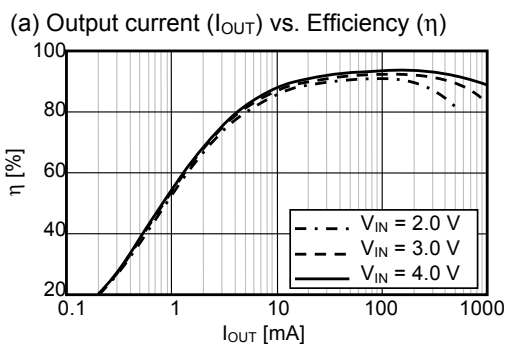
**Condition 4 S-8357B33**



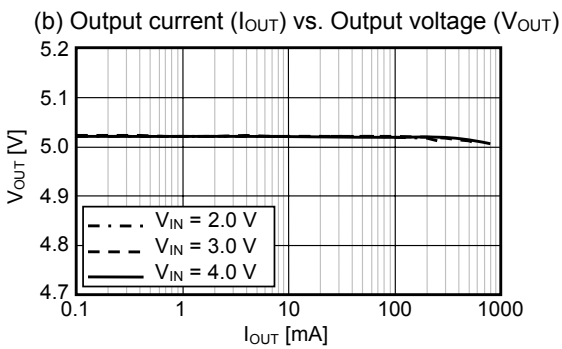
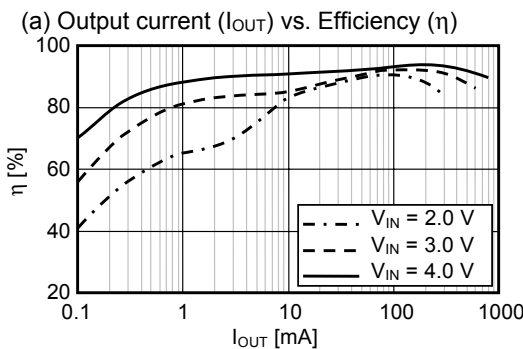
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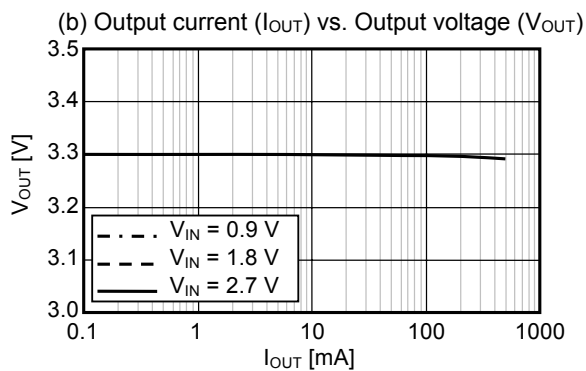
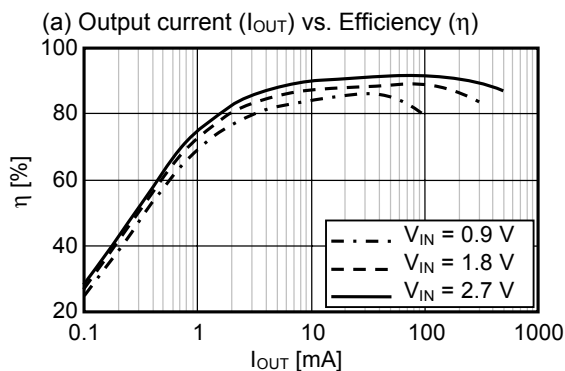
**Condition 6 S-8357B50**



**Condition 7 S-8357M50**

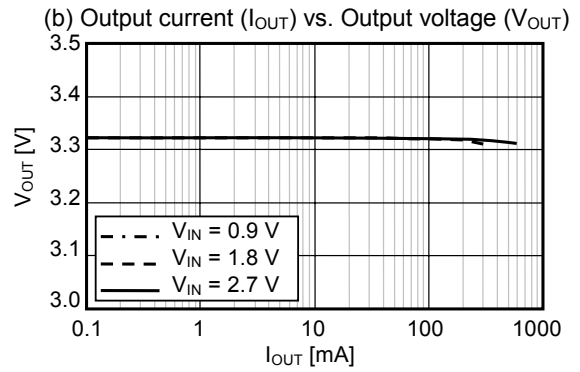
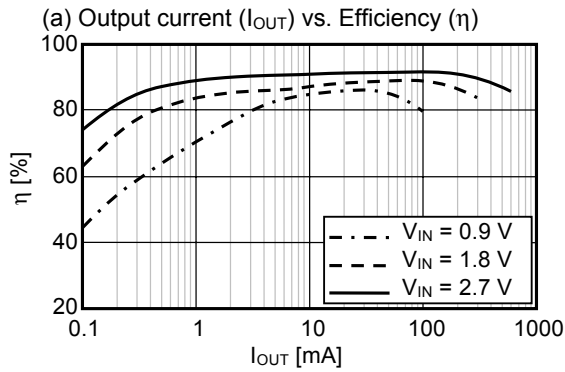


**Condition 8 S-8357B33**

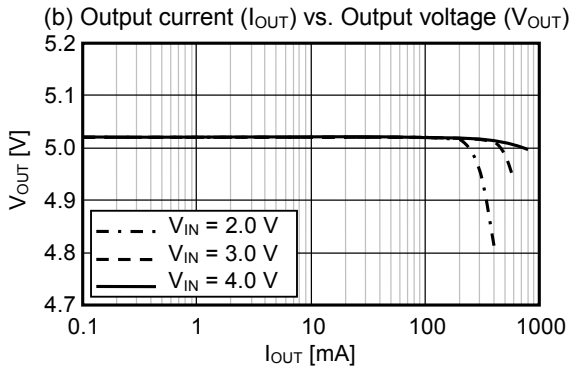
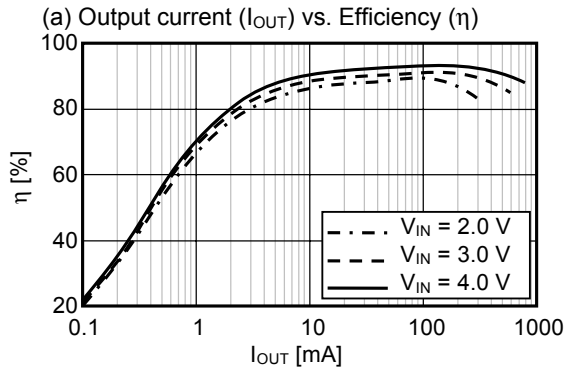




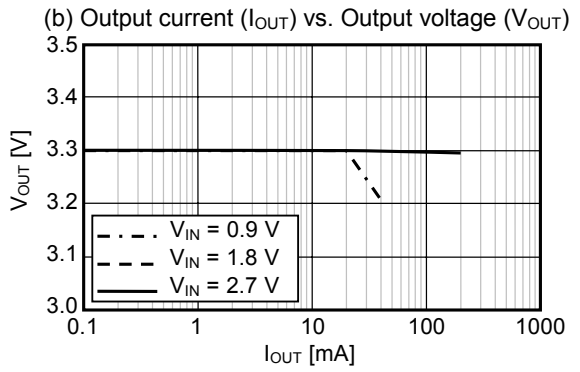
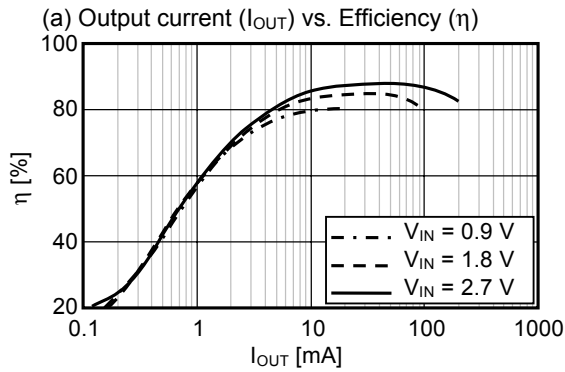
**Condition 9 S-8358B33**



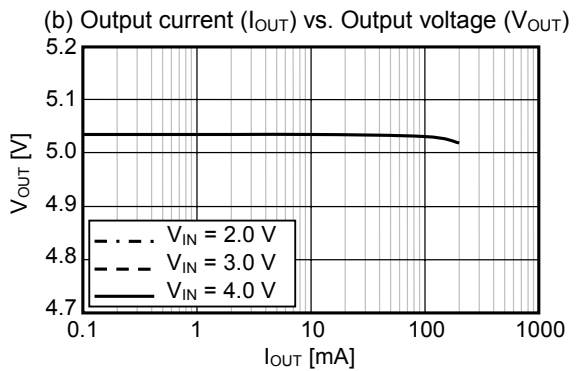
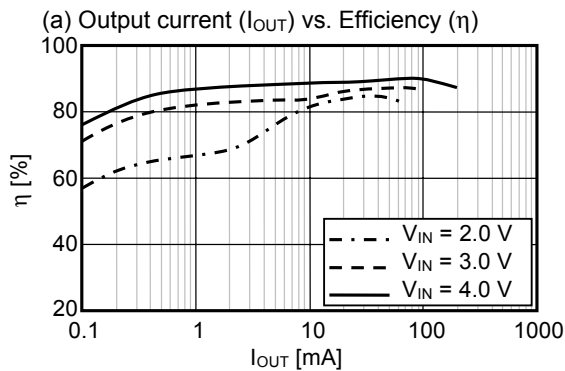
**Condition 10 S-8357B50**



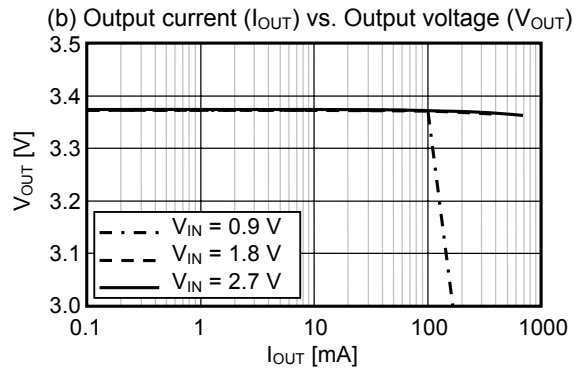
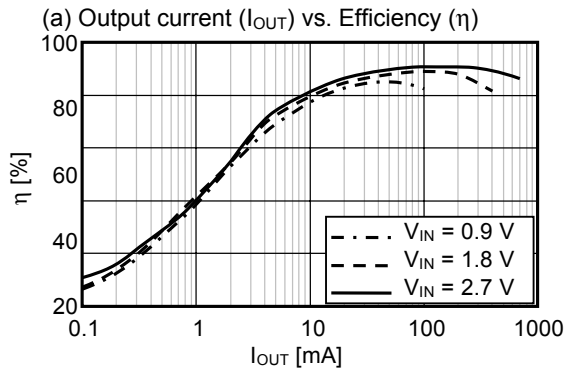
**Condition 11 S-8357F33**



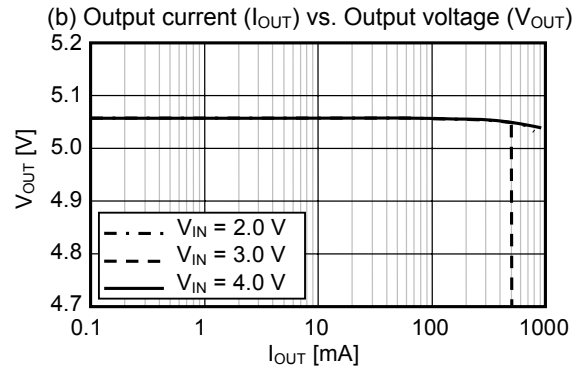
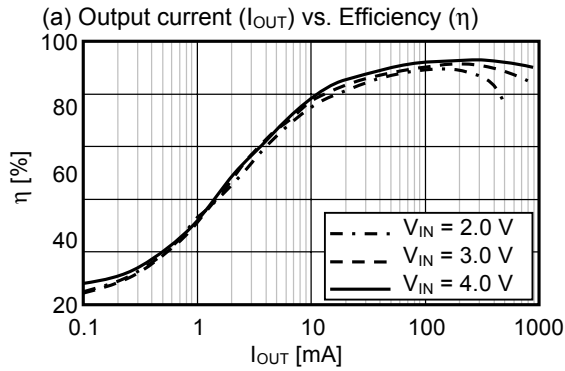
**Condition 12 S-8356M50**



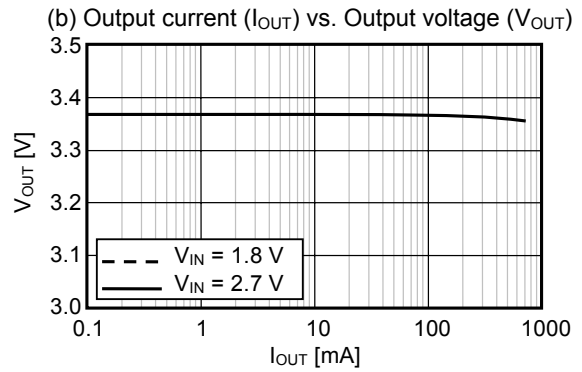
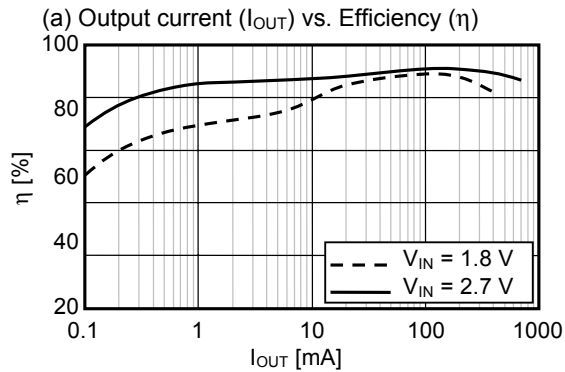
**Condition 13 S-8357N33**



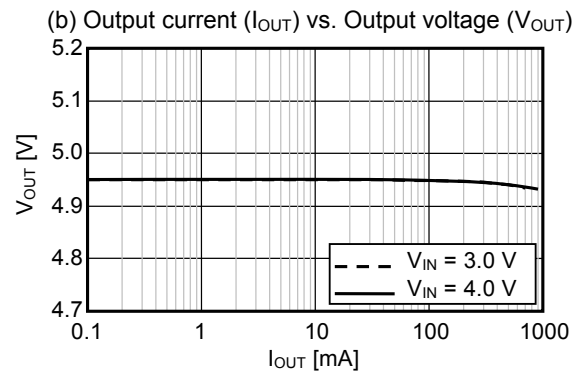
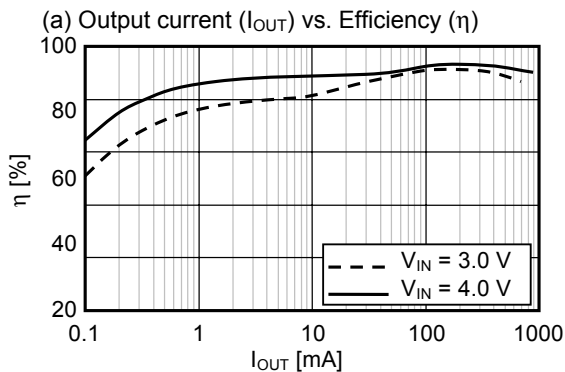
**Condition 14 S-8357N50**



**Condition 15 S-8356Q33**



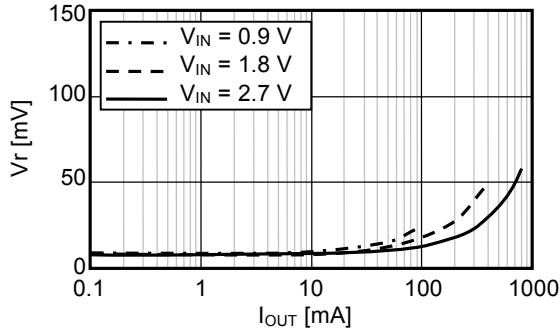
**Condition 16 S-8356Q50**



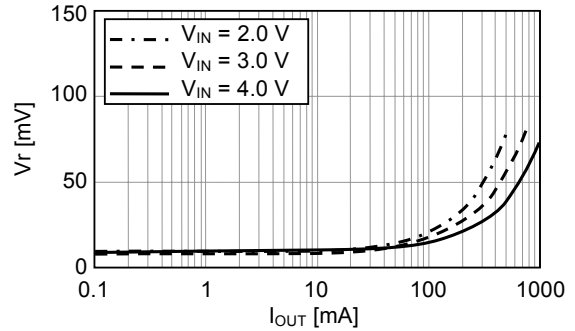
**3. Output Current ( $I_{OUT}$ ) vs. Ripple Voltage ( $V_r$ ) Characteristics**

The following shows the actual Output current ( $I_{OUT}$ ) vs. Ripple voltage ( $V_r$ ) characteristics and (b) Output current ( $I_{OUT}$ ) vs. Output voltage ( $V_{OUT}$ ) characteristics under the conditions of No. 1 to 16 in **Table 32**.

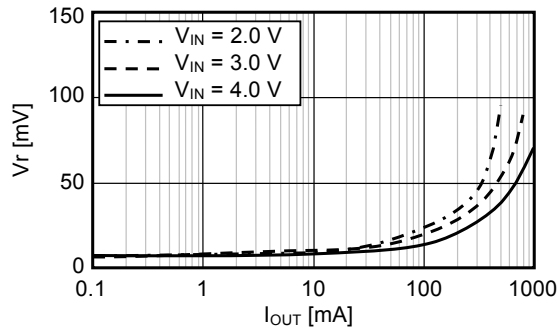
**Condition 1 S-8357F33**



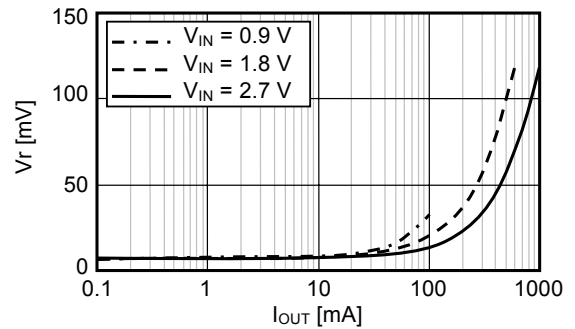
**Condition 2 S-8357F50**



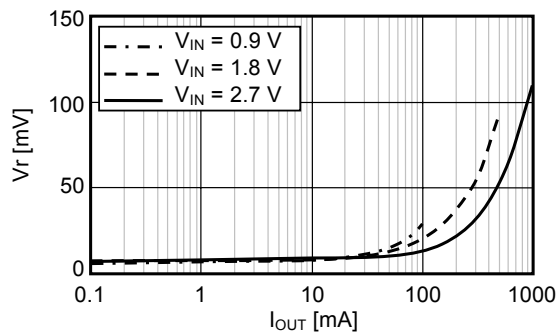
**Condition 3 S-8356M50**



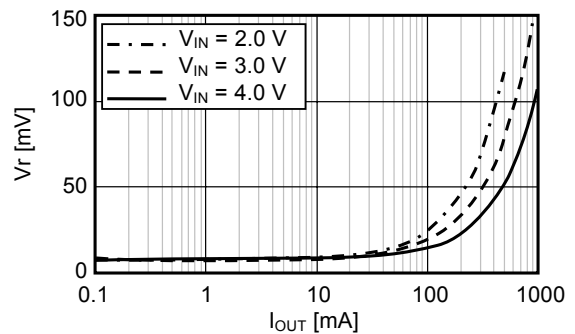
**Condition 4 S-8357B33**



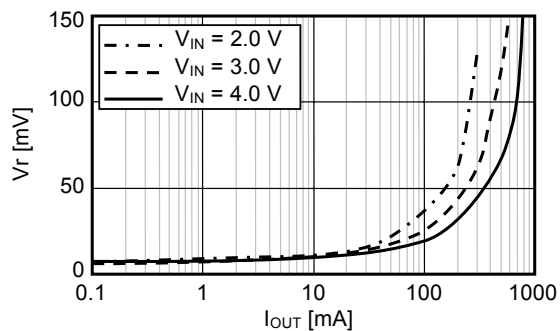
**Condition 5 S-8358B33**



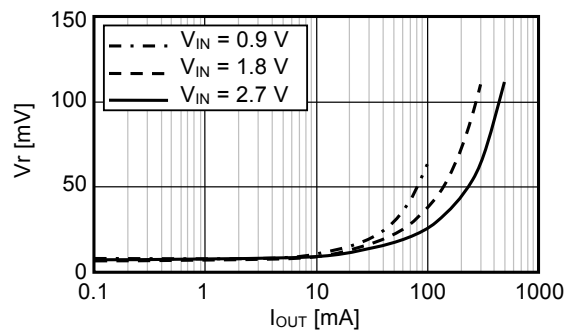
**Condition 6 S-8357B50**



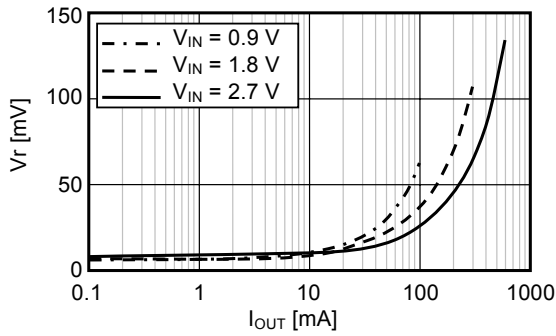
**Condition 7 S-8356M50**



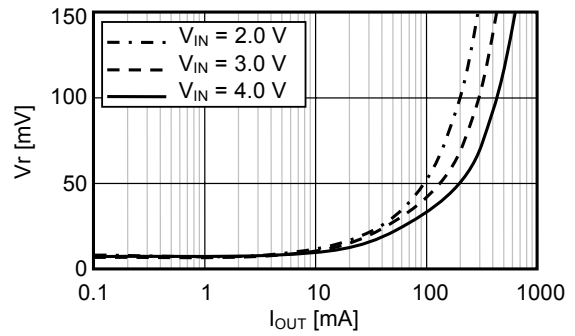
**Condition 8 S-8357B33**



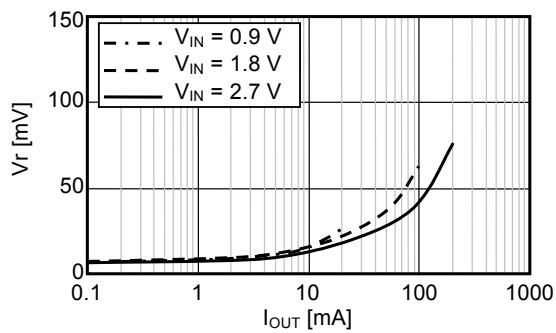
**Condition 9 S-8358B33**



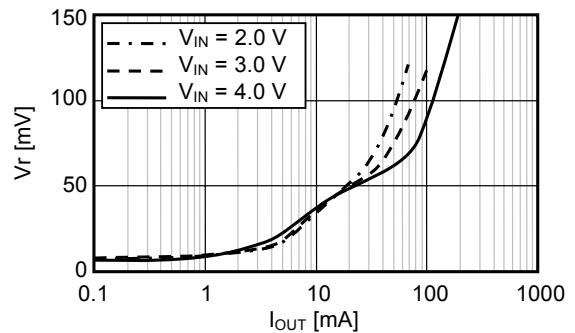
**Condition 10 S-8357B50**



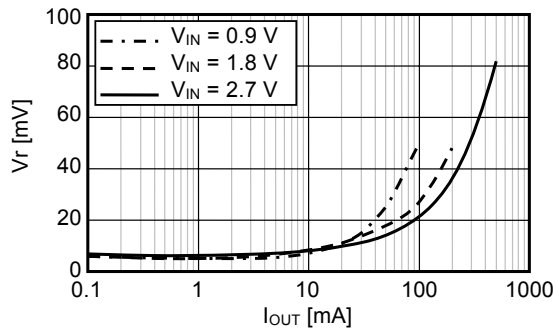
**Condition 11 S-8357F33**



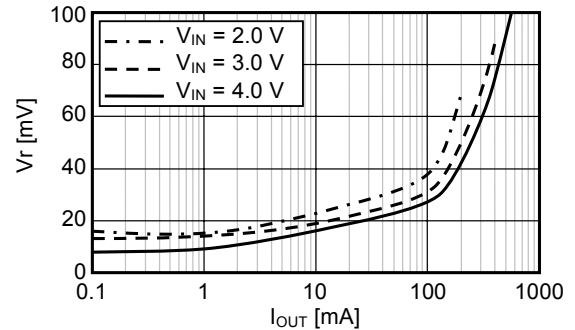
**Condition 12 S-8356M50**



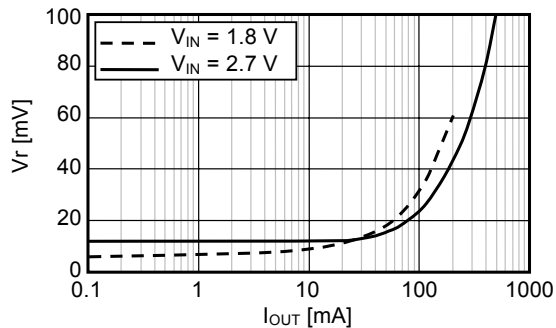
**Condition 13 S-8357N33**



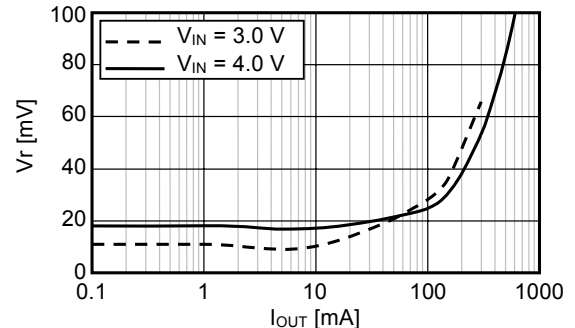
**Condition 14 S-8357N50**

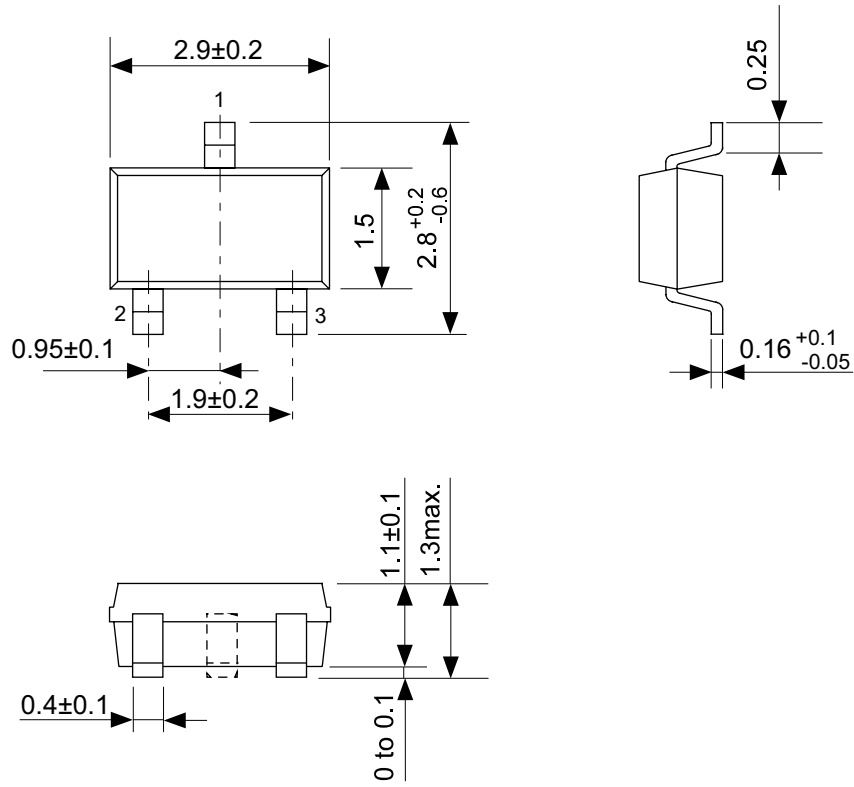


**Condition 15 S-8356Q33**



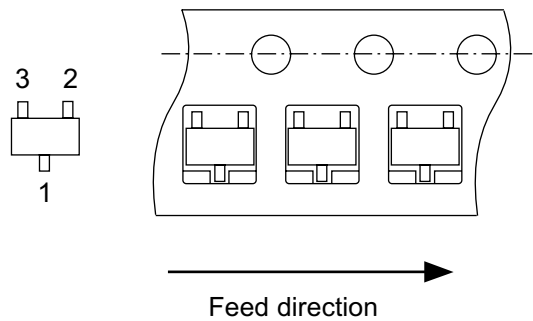
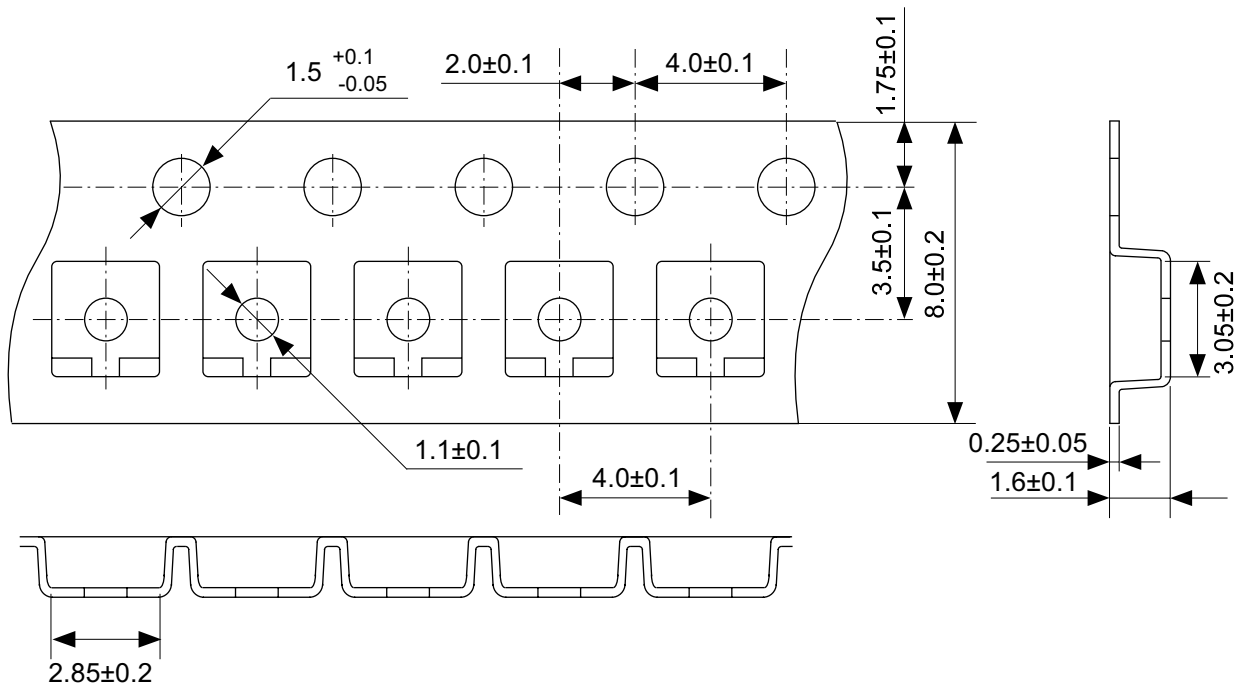
**Condition 16 S-8356Q50**





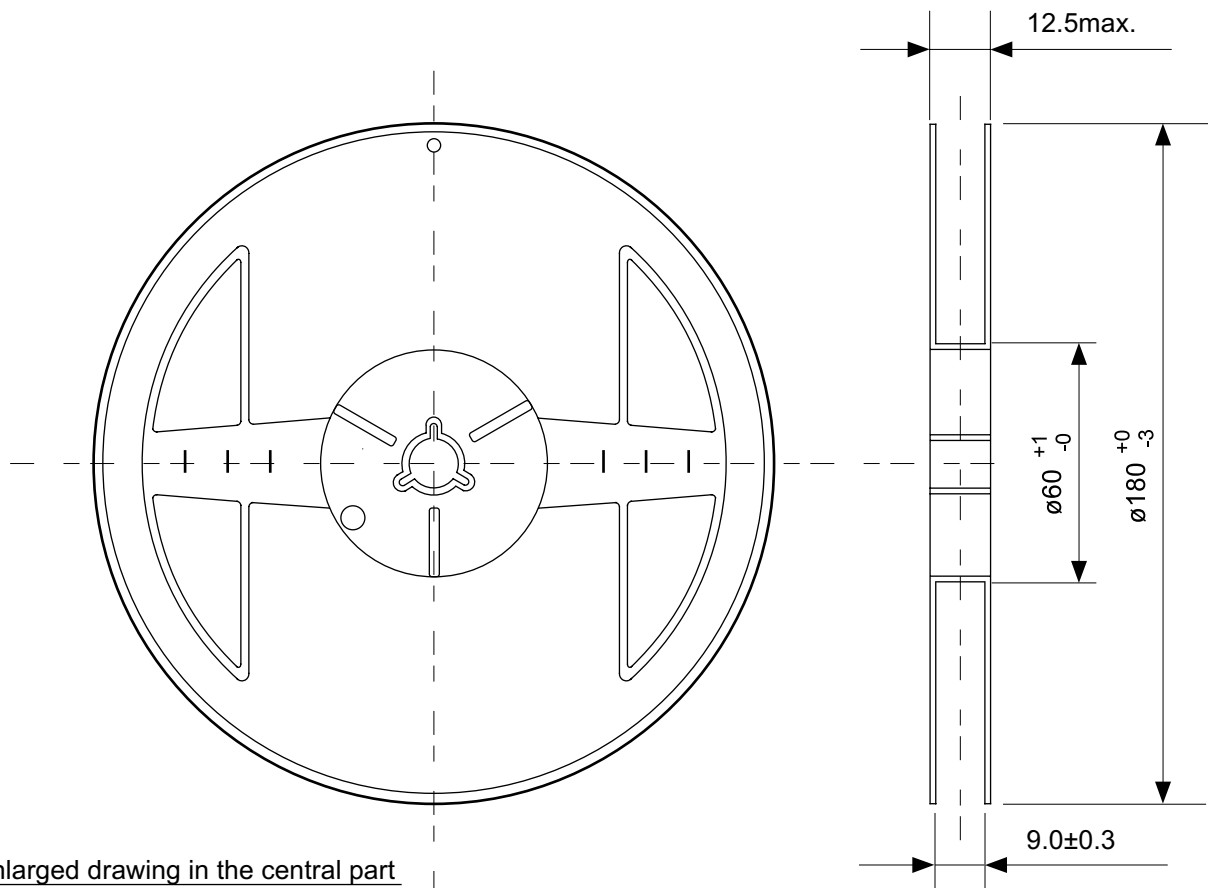
No. MP003-A-P-SD-1.1

TITLE	SOT233-A-PKG Dimensions
No.	MP003-A-P-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	

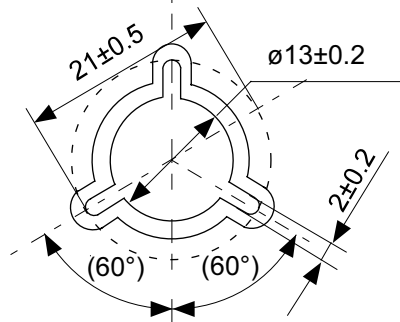


No. MP003-A-C-SD-1.1

TITLE	SOT233-A-Carrier Tape
No.	MP003-A-C-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	

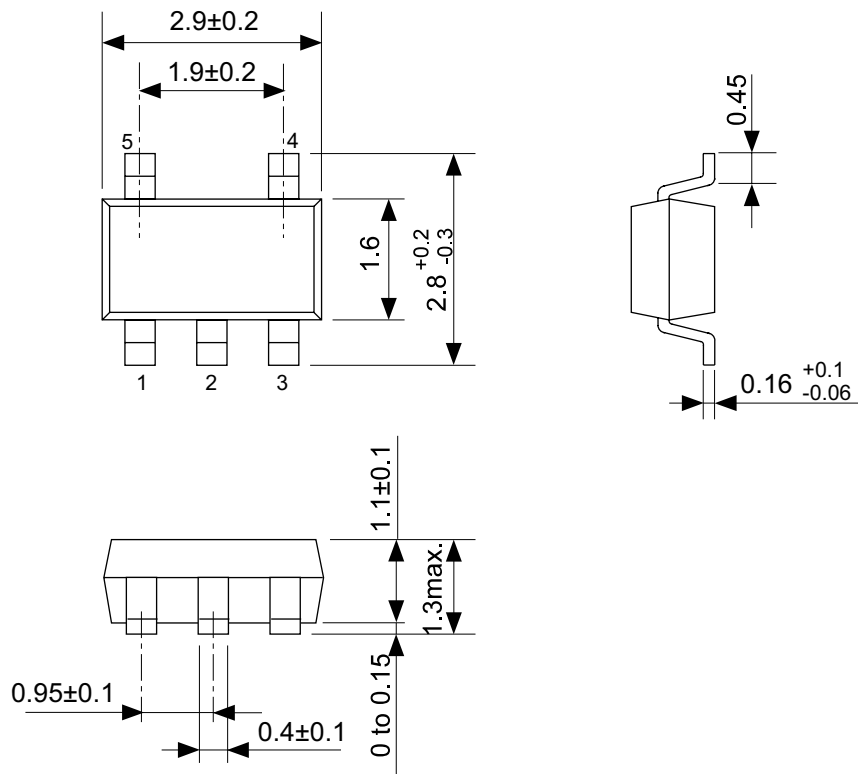


Enlarged drawing in the central part



No. MP003-A-R-SD-1.1

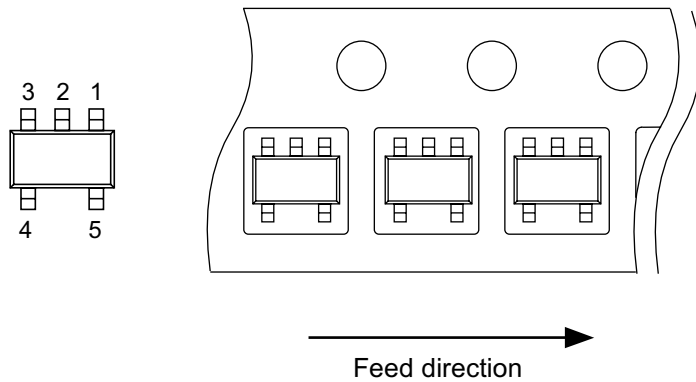
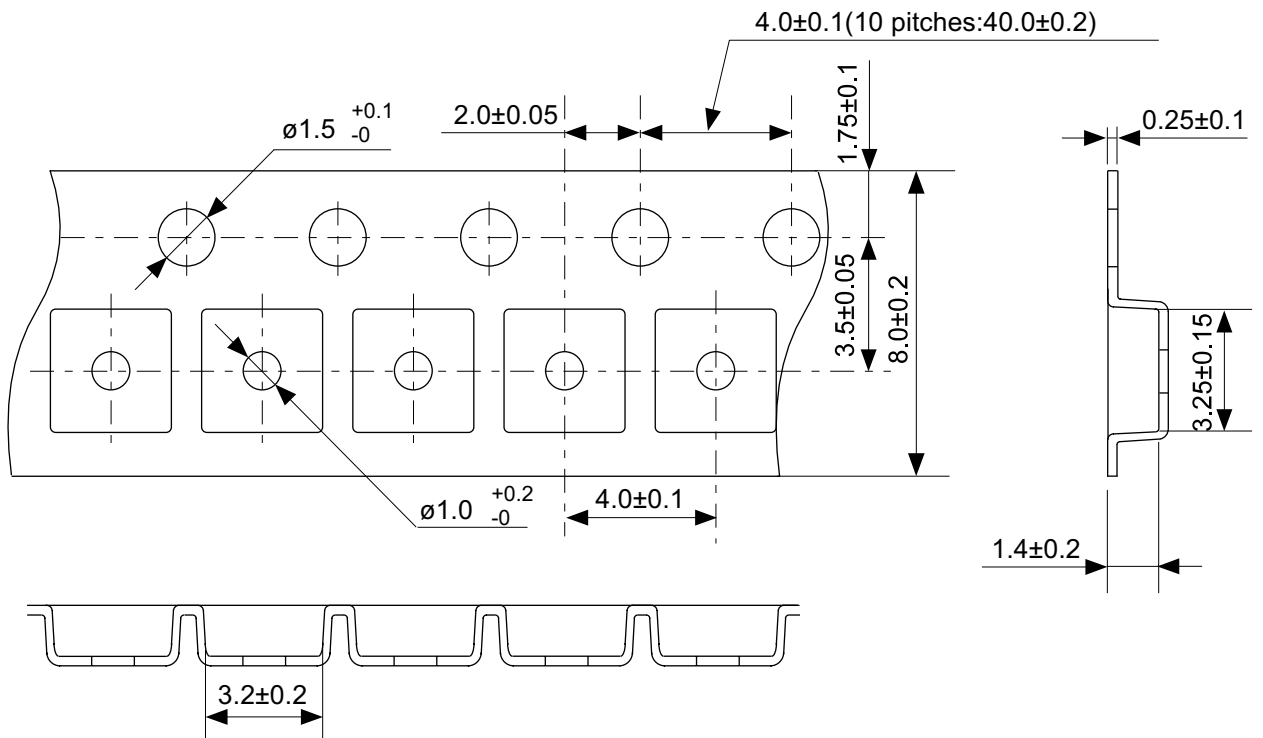
TITLE	SOT233-A-Reel		
No.	MP003-A-R-SD-1.1		
SCALE		QTY.	3,000
UNIT	mm		
Seiko Instruments Inc.			



No. MP005-A-P-SD-1.2

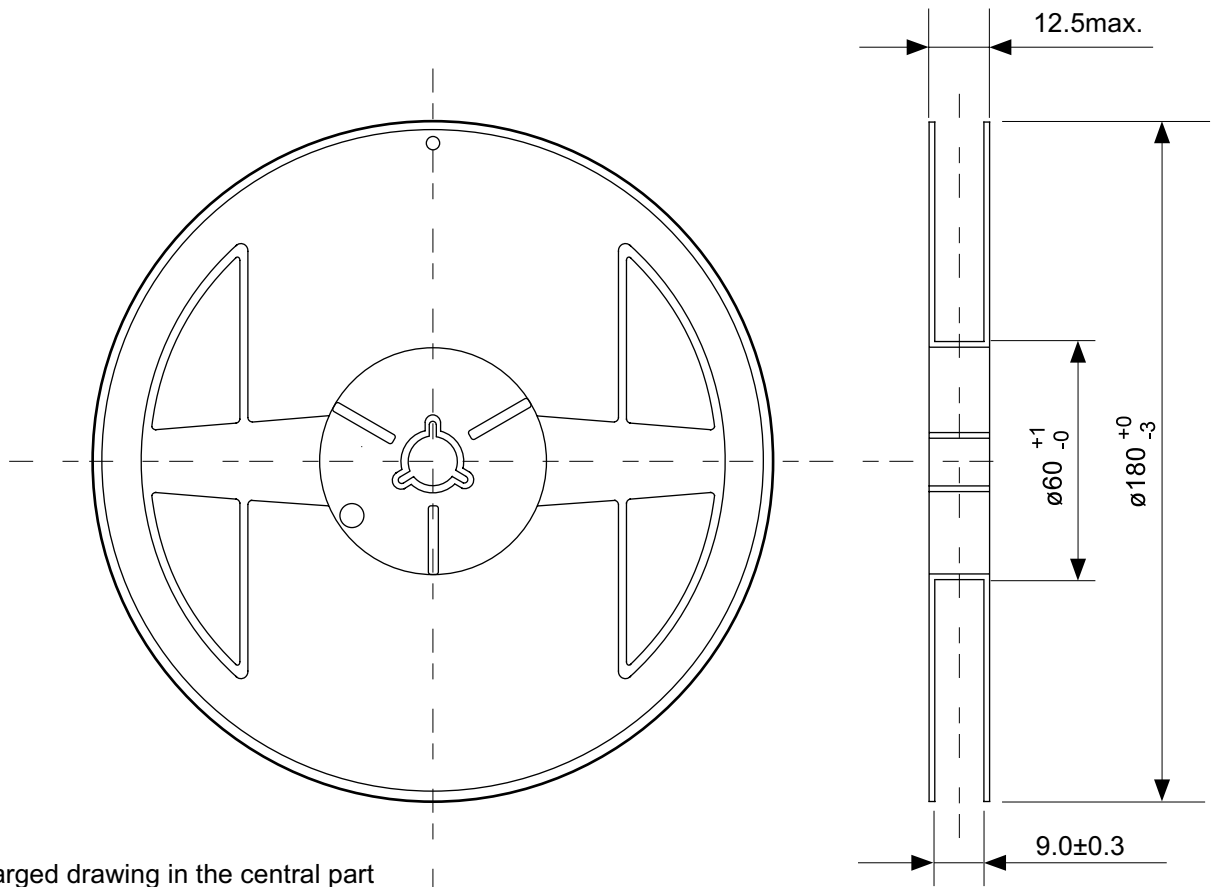
TITLE	SOT235-A-PKG Dimensions
No.	MP005-A-P-SD-1.2
SCALE	
UNIT	mm
Seiko Instruments Inc.	



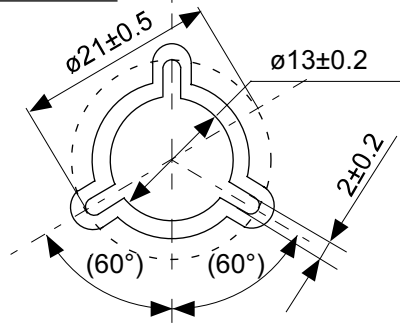


No. MP005-A-C-SD-2.1

TITLE	SOT235-A-Carrier Tape
No.	MP005-A-C-SD-2.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	

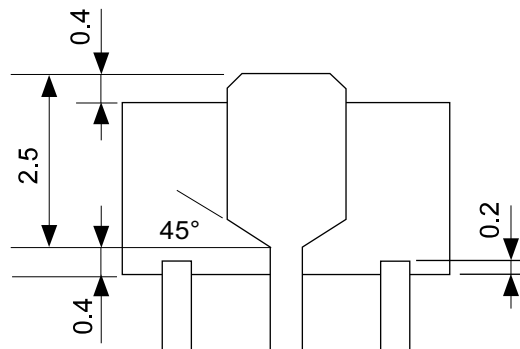
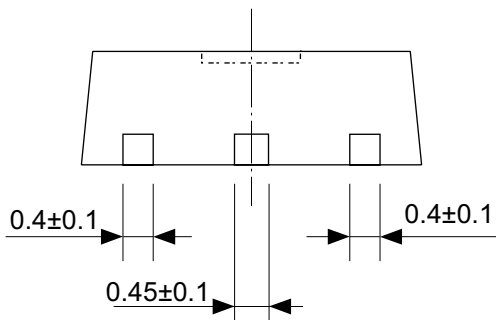
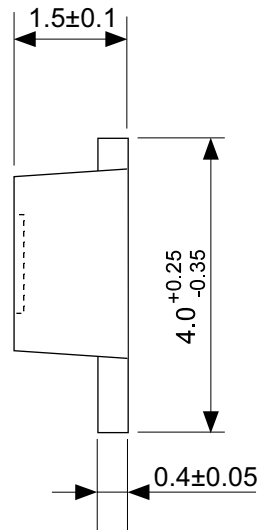
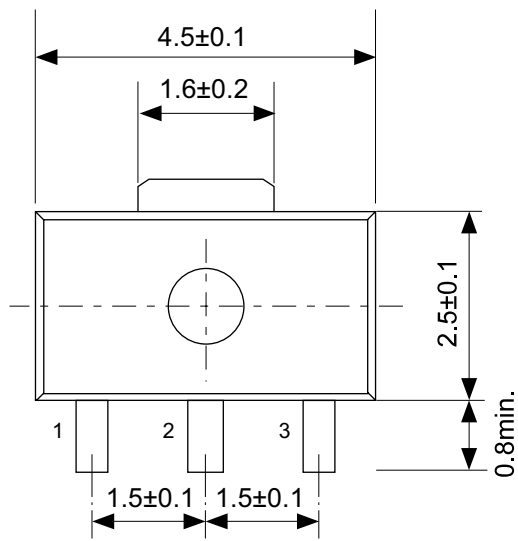


Enlarged drawing in the central part



No. MP005-A-R-SD-1.1

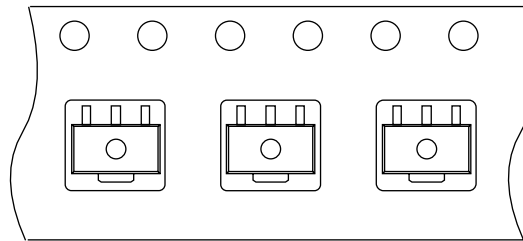
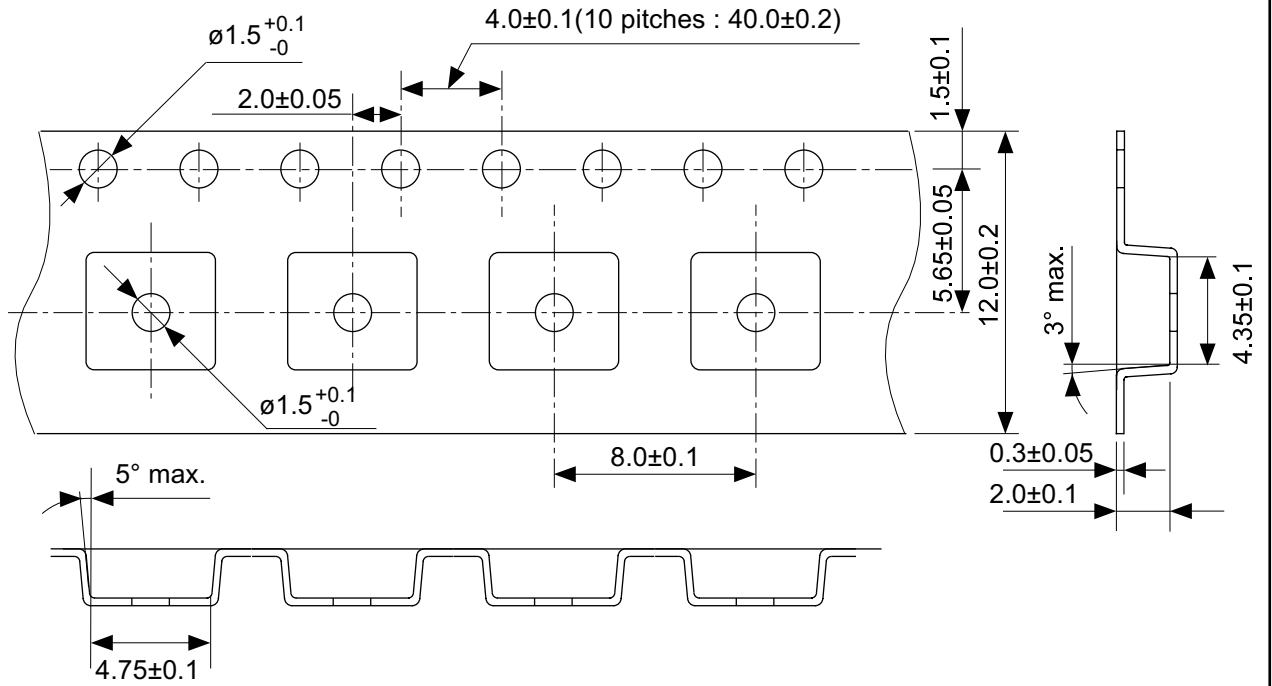
TITLE	SOT235-A-Reel		
No.	MP005-A-R-SD-1.1		
SCALE		QTY.	3,000
UNIT	mm		
Seiko Instruments Inc.			



No. UP003-A-P-SD-1.1

TITLE	SOT893-A-PKG Dimensions
No.	UP003-A-P-SD-1.1
SCALE	
UNIT	mm

Seiko Instruments Inc.

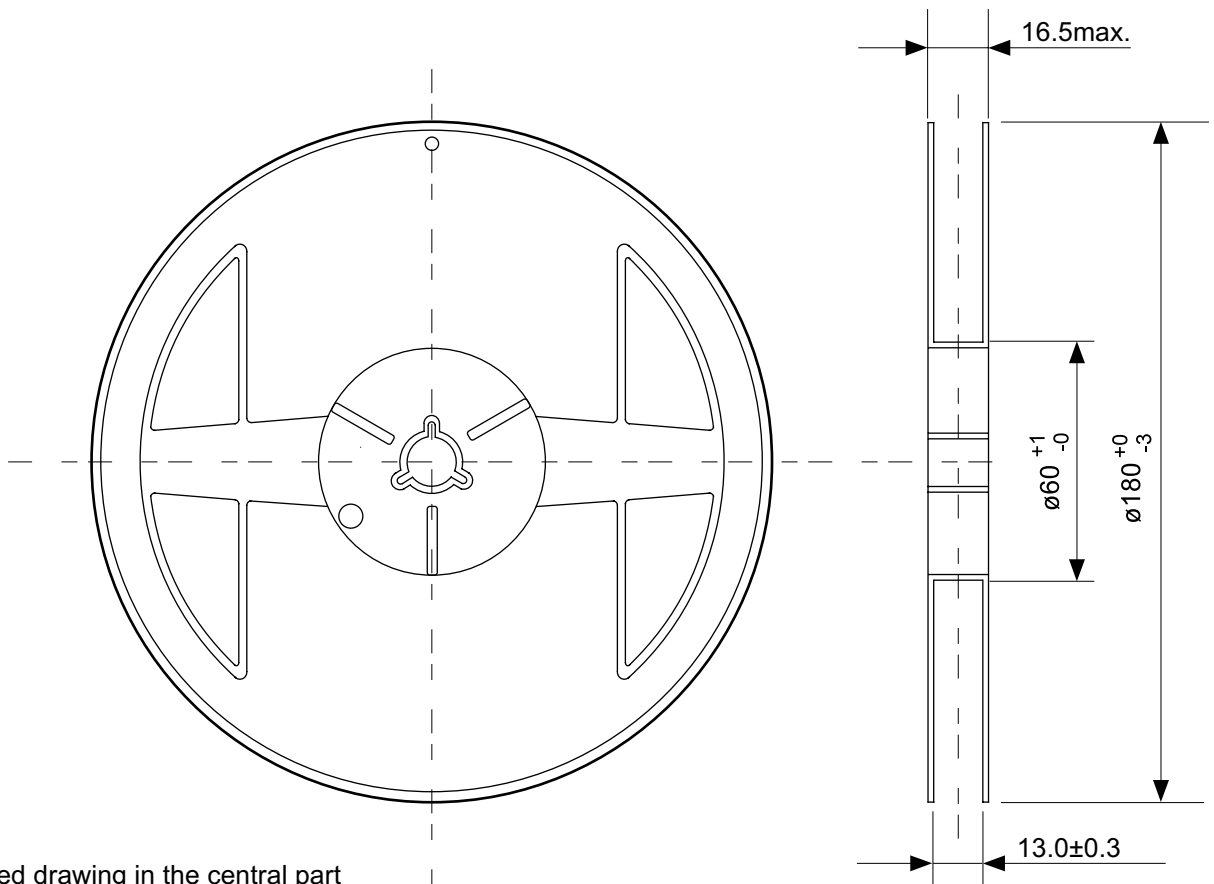


→  
Feed direction

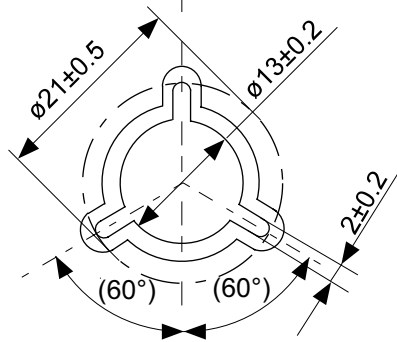
No. UP003-A-C-SD-1.1

TITLE	SOT893-A-Carrier Tape
No.	UP003-A-C-SD-1.1
SCALE	
UNIT	mm

Seiko Instruments Inc.



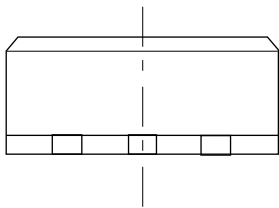
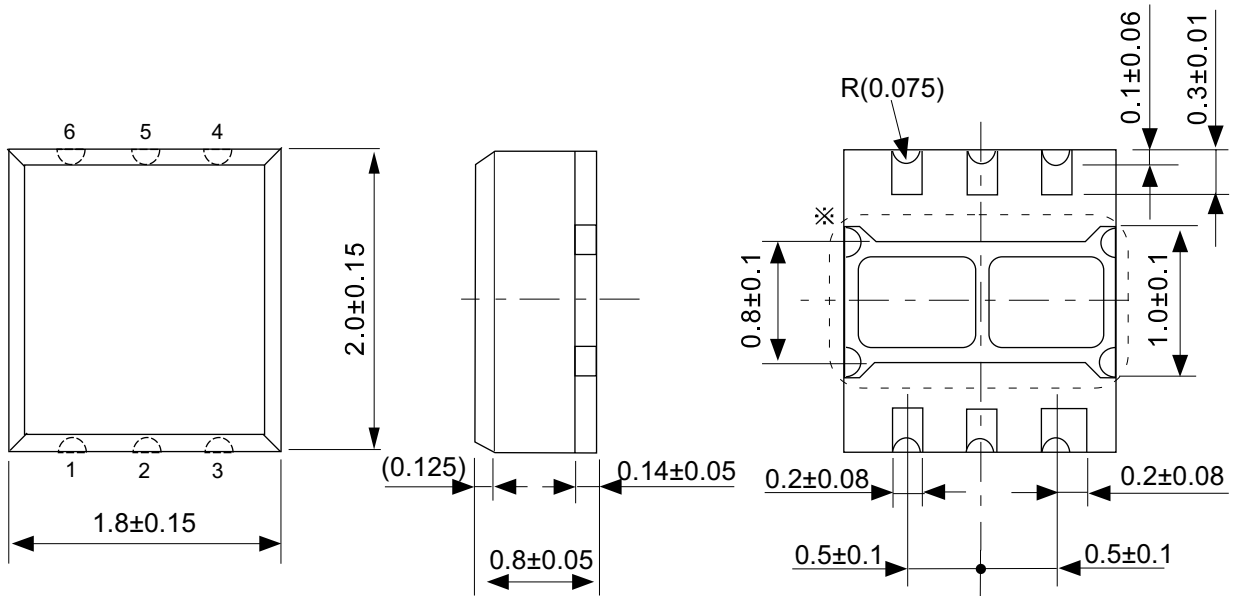
Enlarged drawing in the central part



No. UP003-A-R-SD-1.1

TITLE	SOT893-A-Reel		
No.	UP003-A-R-SD-1.1		
SCALE		QTY.	1,000
UNIT	mm		

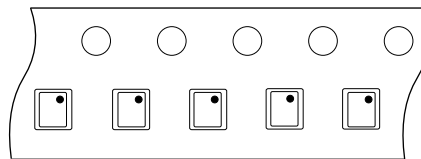
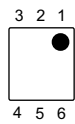
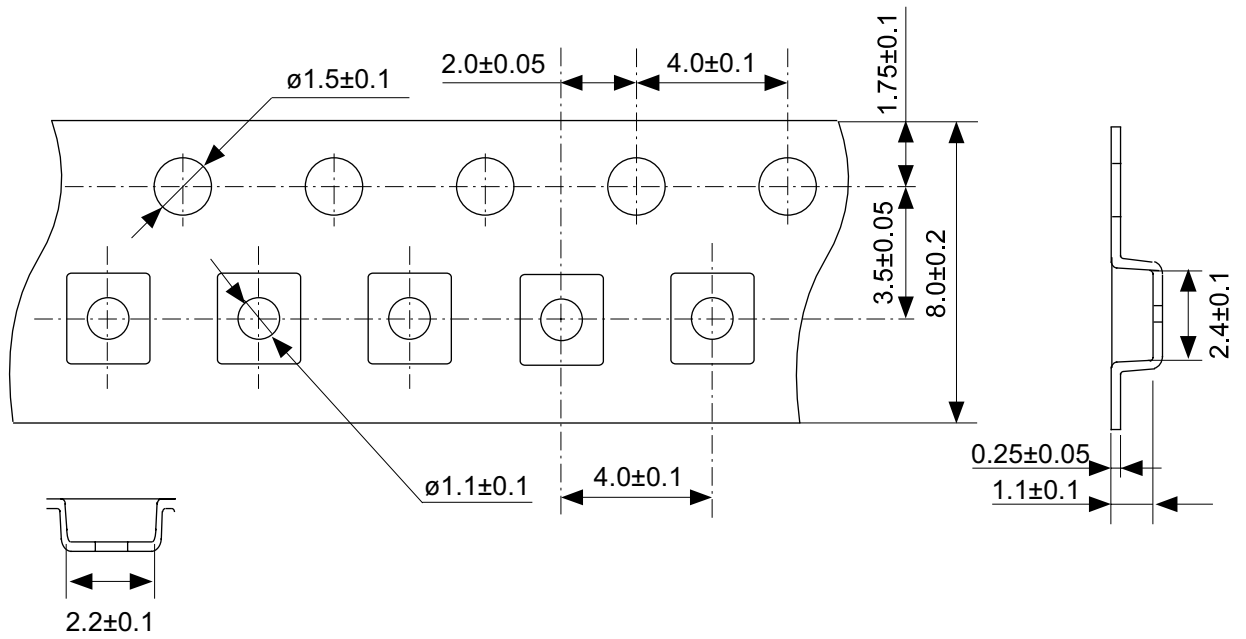
Seiko Instruments Inc.



$\ast$  The heatsink of back side has different electric potential depending on the product. Confirm specifications of each product. Do not use it as the function of electrode.

No. BD006-A-P-SD-3.0

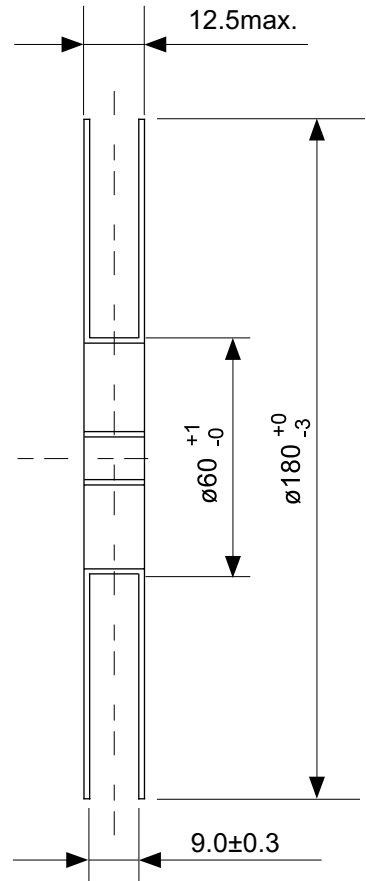
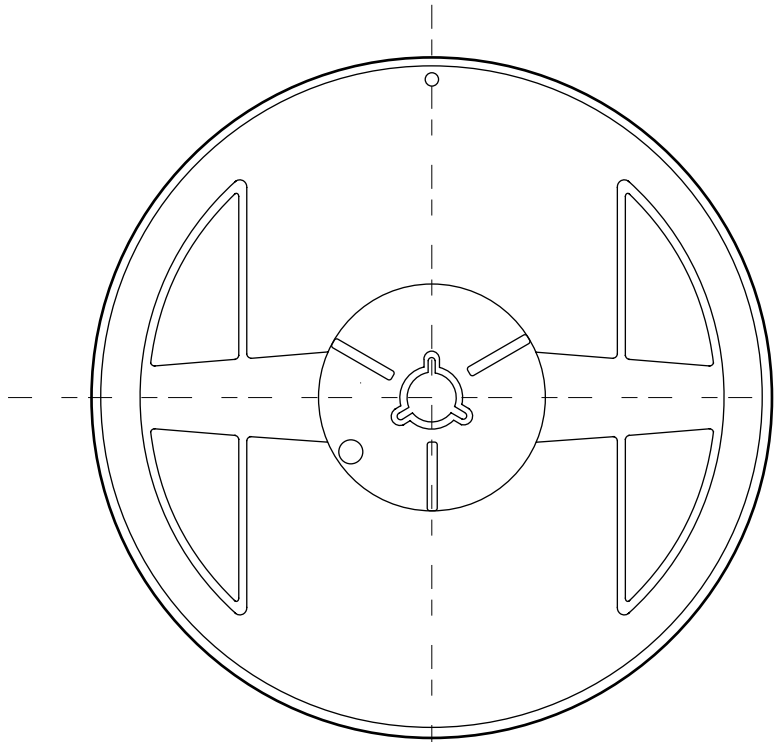
TITLE	SNB6B-A-PKG Dimensions
No.	BD006-A-P-SD-3.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	



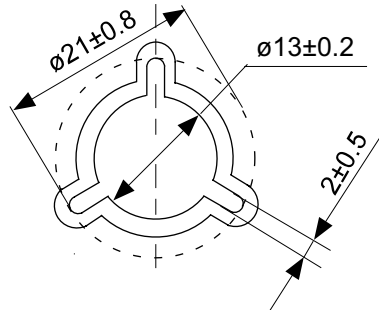
Feed direction →

No. BD006-A-C-SD-2.1

TITLE	SNB6B-A-Carrier Tape
No.	BD006-A-C-SD-2.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	



Enlarged drawing in the central part



No. BD006-A-R-SD-1.1

TITLE	SNB6B-A-Reel		
No.	BD006-A-R-SD-1.1		
SCALE		QTY.	3,000
UNIT	mm		

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